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Data-Driven Pursuit of Electrochemically Stable 2D Materials with Basal Plane Activity toward Oxygen Electrocatalysis

Xiangyu Guo^{a,d,g,h}, Shengli Zhang^{b,*}, Liangzhi Kou^f, Chi Yung Yam^{d,e,j}, Thomas Frauenheim^{d,e,i}, Zhongfang Chen^{c,*}, Shiping Huang^{a,*}

^a State Key Laboratory of Organic–Inorganic Composites, Beijing University of Chemical Technology, Beijing 100029, China

^b MIIT Key Laboratory of Advanced Display Materials and Devices, Ministry of Industry and Information Technology, Institute of Optoelectronics & Nanomaterials, Nanjing University of Science and Technology, Nanjing 210094, China

^c Department of Chemistry, University of Puerto Rico, Rio Piedras, San Juan, Puerto Rico 00931, United States

^d Beijing Computational Science Research Center (CSRC), Beijing 100193, China

^e Shenzhen JL Computational Science and Applied Research Institute, Shenzhen 518110, China

^f School of Mechanical, Medical and Process Engineering, Queensland University of Technology, QLD, 4000, Australia

^g Bremen Center for Computational Materials Science, University of Bremen, Bremen 28359, Germany

^h Institute for Functional Intelligent Materials, National University of Singapore, Singapore, 117544, Singapore

ⁱ School of Science, Constructor University, Bremen 28759, Germany

^j Shenzhen Institute for Advanced Study, University of Electronic Science and Technology of China, Shenzhen, 518000, China

Corresponding E-mails:

E-mail: zhongfangchen@gmail.com

E-mail: zhangslvip@njust.edu.cn

E-mail: huangsp@mail.buct.edu.cn

SUPPORTING INFORMATION

Supplementary Summary

Computational methods		Page S4-S5
Definitions of decomposition energy and exfoliation energy		Page S5
Calculation of the dissolution potential		Page S6-S8
Coverage and kinetic effects		Page S9-S11
Table S1	Details about the 45 experimental synthesized 2D monolayers	Page S12-S13
Table S2	Structural and electronic information of 339 potential electrocatalysts.	Page S14-S23
Table S3	Catalytic activity analysis of 242 four-electron pathway selective sites.	Page S24-S29
Table S4	Adsorption free energy of O* and H ₂ O ₂ * on 25 material surfaces.	Page S30
Table S5	Crystal information of 47 candidate materials.	Page S31-S35
Table S6	Activity analysis on 77 edge structures.	Page S36-S45
Table S7	Electrochemical stability analysis of 47 candidate materials.	Page S46-S37
Table S8	Analysis of minimum pH requirement for 14 ORR and 16 OER catalysts.	Page S48
Table S9	Summary of recent progresses on the design of 2D ORR/OER catalysts	Page S49-S52
Fig. S1	Structure, and band structure of TaS ₂ and Ta ₂ CS ₂ , and the ORR profiles.	Page S53
Fig. S2	Adsorption configurations of H ₂ O ₂ * on 25 materials.	Page S54
Fig. S3	Reaction pathway selectivity of 25 materials.	Page S54
Fig. S4	Activity benchmark of Pt and IrO ₂ .	Page S55
Fig. S5	Kinetic simulation of ORR on the PtTe and NbSe ₂ surfaces	Page S56
Fig. S6	Crystal structure of experimentally synthesized Ni _{0.75} Fe _{0.25} OOH catalysts.	Page S57
Fig. S7	Site activity analysis of OER on Ni _{0.75} Fe _{0.25} OOH catalysts.	Page S57
Fig. S8	Structure snapshots of 47 active materials	Page S58
Fig. S9-S42	Activity analysis of 34 materials for ORR.	Page S59-S92

VAg(PeSe ₃) ₂	MnSbSe ₂ I	CuSeO ₃	Bi ₄ I	CuTeO ₃	Bi ₉ I ₂	NiTe ₂
S59	S60	S61	S62	S63	S64	S65
LiNi(PS ₃) ₂	Ta ₃ Pd ₃ Te ₁₄	PtTe	Ge ₅ (Te ₄ As) ₂	MoTe ₂	Ge ₄ Te ₇ As ₂	NiTe
S66	S67	S68	S69	S70	S71	S72
BiTe	NbTe ₂	Mn(InSe ₂) ₂	Nb ₄ IrSe ₁₀	TaS ₂	BiSe	Fe ₄ S ₅
S73	S74	S75	S76	S77	S78	S79

SUPPORTING INFORMATION

NbSe ₂	TaSe ₂	ZrSiSe	GdBr	CrGeTe ₃	PtPb ₄	CuH ₂ (SeO ₃) ₂
S80	S81	S82	S83	S84	S85	S86
Ag(AuS) ₂	Nb ₉ IrSe ₂₀	AgHO ₂	La ₂ PI ₂	TbGal	Cel ₃	
S87	S88	S89	S90	S91	S92	

Fig. S43-S64 Activity analysis of 22 materials for OER.							Page S93-S114
Sc ₆ C ₂ I ₁₁	Li ₂ Cu ₂ F ₅	Pd ₃ Pb ₂ Te ₂	Zn(InS) ₂	Ta(NiTe) ₂	VTe ₂	Bi ₃ Se ₄	
S93	S94	S95	S96	S97	S98	S99	
TaTe ₂	Nb ₂ Se ₃	Pr ₂ Br ₅	CeZnPO	EuBrO	TbBr	CrGeTe ₃	
S100	S101	S102	S103	S104	S105	S106	
PtPb ₄	CuH ₂ (SeO ₃) ₂	Ag(AuS) ₂	Nb ₉ IrSe ₂₀	AgHO ₂	La ₂ PI ₂	TbGal	
S107	S108	S109	S110	S111	S112	S113	
Cel ₃							
S114							

Fig. S65	Evaluation of the edge sites activity	Page S115
Fig. S66	Work flow for electrochemical stability analysis.	Page S115
Fig. S67	DOS and COHP analyses for the OOH* adsorption	Page S116
Fig. S68	AIMD simulation	Page S117
Fig. S69	Structure snapshots of NiPS ₃ before and after the AIMD simulation	Page S117
Fig. S70	Accuracy of solvation correction on the free energy calculations	Page S118
Fig. S71	Coverage effect and optimize strategies on PtTe and NbSe ₂ monolayers.	Page S118
References		Page S119-S120

SUPPORTING INFORMATION

Data availability

Atomic structures used in this study will be provided at the following GitHub repository:

<https://github.com/ChaunceyGuo?tab=repositories>

Computational methods

Spin-polarized first-principles calculations were carried out using the Perdew–Burke–Ernzerhof (PBE) functional within the generalized gradient approximation (GGA),¹ as implemented in Vienna Ab Initio Simulation Package (VASP).² The valence electrons were expanded as plane wave with a kinetic energy cutoff of 400 eV. The convergence thresholds were set as 1.0×10^{-5} for energy and 2.0×10^{-2} eV Å⁻¹ for atomic force. The Brillouin zone was sampled by Monkhorst–Pack mesh using k -points of $0.04*2\pi$ Å⁻¹ which was achieved by the pre-and post-processing program of VASKIT.³ To eliminate the periodic interactions between the adjacent images, a vacuum space of 15 Å was used in the perpendicular direction of the 2D plane, and a supercell scheme was adopted when a unit cell has a lattice less than 6 Å to minimize the periodic interactions between reaction species. To describe the van der Waals interactions, DFT-D3 method with the standard parameters by Grimme *et al.* was employed.⁴

Electronic transport property of electrical conductivity ($\sigma_{\alpha\beta}$) was calculated by combining ab initio band structures and Boltzmann transport theory within the constant relaxation time approximation. This procedure solves Boltzmann equation by interpolating a band structure and implementing the required integrations, whose accuracy was demonstrated earlier.⁵ Here, the relaxation time was set as $3.0 \cdot 10^{-13}$ s following the previous work.⁶ The K-Spacing Value during this calculation is set to be $0.005*2\pi$ Å⁻¹. The $\sigma_{\alpha\beta}$ a function of temperature (T) and chemical potential (μ) described as:

$$\sigma_{\alpha\beta}(T, \mu) = \frac{1}{\Omega} \int \sigma_{\alpha\beta}(\varepsilon) \left[-\frac{\partial f_\mu(T, \varepsilon)}{\partial \varepsilon} \right] d\varepsilon$$

where Ω represents the volume of the unit cell. f_μ is the Fermi distribution, ε is the band energy which obtained from computed band structure.

The free energy landscapes and reaction pathways along the oxygen electrocatalysis on the basal plane of 2D materials were investigated in conjunction with the computational hydrogen electrode (CHE) model.⁷ The vibrational contributions, including zero-point energy, enthalpy, and entropy, were obtained by the harmonic approximation at a temperature of 298.15 K. Since the current computational framework is difficult

SUPPORTING INFORMATION

to describe low-frequency modes properly, we set up a threshold value of 50 cm^{-1} to reduce these unphysically large entropy contributions.^{8,9} Solvation-induced energy change for the adsorption of reaction species, i.e., OOH^* , O^* and OH^* , were considered according to the previous investigations, which were estimated to be 0.3, 0.0, and 0.3 eV, respectively.¹⁰⁻¹² This correction is based on the fact that each H_2O in the liquid phase can create two donors and one acceptor hydrogen bonds with adjacent molecules, which stabilize the molecules by ~ 0.45 (3×0.15) eV. As OOH^* and OH^* are able to create two hydrogen bonds with H_2O , it will be stabilized by ~ 0.3 eV when solvated. And no clear hydrogen bonds were formed around the O^* sites, hence no correction was applied for O^* adsorption. To verify the effectiveness of this correction, we have also adopted an implicit solvation model¹³ to calculate the adsorption free energy of oxygen containing species using the NbSe_2 as prototype (see Fig. S69). The computational results obtained from these two methods are close to each other, which indicate the current calculations could well capture the reaction profiles and thus estimate the catalytic performance.

To well evaluate the electrochemical stability of 2D materials, we performed grand-canonical density functional theory (GC-DFT) computations to model the electrode–electrolyte interface under the specific electrode potential, as implemented in JDFTx.¹⁴ We employed the PBE exchange correlation functional with GBRV ultrasoft pseudopotentials¹⁵ at a kinetic energy cutoff of 20 Hartrees (*ca.* 544 eV) for wavefunctions and 100 Hartrees for the charge density. The charge-asymmetric nonlocally determined local-electric (CANDLE) solvation model was utilized to describe the effect of liquid water.¹⁶ The ionic screening of net charges caused by the constant electrode potential was realized with 1M (mol L^{-1}) Na^+ and F^- components in the fluid model, which displayed high accuracy in capturing the solvation of highly charged negative and positive solutes.¹⁷ Other numerical parameters, including k -point sampling, cell sizes, convergence criteria, etc. are similar to the VASP calculations.

Decomposition energy and exfoliation energy

The decomposition energy and the exfoliation energy were extracted from 2DMatPedia database. The exfoliation energy (E_{exf}), defined as the average energy per atom required to remove a layer from a layered bulk material, was calculated by $E_{exf} = E_{2D} - E_{bulk}$, where E_{2D} and E_{bulk} are the energies (per atom) of the 2D material and its layered bulk counterpart, respectively. The decomposition energy is defined as the energy required (per atom) to decompose a 2D material into the most stable compound(s) at its chemical composition without consideration of the corresponding layered bulk of the given 2D material.

SUPPORTING INFORMATION

Evaluation of the dissolution potential of materials

Under the reaction conditions with the involvement of electrolyte and external electrode potential, a material could undergo a decomposition or a dissolution depending on its redox characteristic. The dissolution potential (U_{diss}) of different sites in a material can be correlated by their thermodynamically favorable dissolution events that readily occur under acidic conditions (more details are given in Table S7). For instance, we assumed that the tellurium can be dissolved through $\text{Te} \rightarrow \text{Te}^{4+} + 4 \text{e}^-$, the sulfur/selenium atoms can be changed into the sulfurous acid/selenous acid via $\text{S}/\text{Se} + 3 \text{H}_2\text{O} \rightarrow \text{H}_2\text{SO}_3/\text{H}_2\text{SeO}_3 + 4 \text{H}^+ + 4 \text{e}^-$, and most metals can be converted into metal ions through $\text{M(s)} \rightarrow \text{M}^{x+}(\text{aq}) + x \text{e}^-$. This is slightly different from the principle of the Pourbaix diagram. For instance, the thermodynamically favorable dissolution products of the Se and S are identified as the H_2SeO_4 and H_2SO_4 , respectively. Here, the use of H_2SO_3 and H_2SeO_3 instead of H_2SeO_4 and H_2SO_4 was actually considered the possible oxidation process in the early stage. We note that elements might involve continuous oxidation steps to realize the final products. For example, Se and S will be first oxidized into XO_3^{2-} ($\text{X} = \text{S}$, and Se), and then coupled with the other oxygen group to form the XO_4^{2-} . Since the transformation of XO_3^{2-} into XO_4^{2-} is easy to occur due to the metastable nature of XO_3^{2-} . The evaluation of the oxidation process of these elements at their early stage could be more valuable to assess electrochemical stability. Thus, we selected H_2SO_3 and H_2SeO_3 as the important dissolution products of the S and Se, instead of using H_2SeO_4 and H_2SO_4 . A similar oxidation process was also found in the Pt dissolution, where Pt is first oxidized into PtO_4 and then reduced into Pt(OH) .¹⁸

Based on the dissolution process, we evaluated the U_{diss} of different 2D materials. The computational workflow to identify the potential dissolution sites was shown in Fig. S66. In detail, we divided the studied materials into three types according to surface structure: 1) material is terminated by a single element with the same coordination configuration, such as 2H and 1T phases of TMDs. 2) the basal plane is formed by a single element but has different coordination configurations, for example, 1T' phase of TMDs. 3) the basal plane has different elements and shows different coordination characteristics, such as MPX_3 systems (M is metal, X is S, Se or Te). For the type 1 structures, the dissolution potential can be directly computed through the GC-DFT simulation. For example, the chalcogenide sites (such as S, Se and Te) were selected for the evaluation of the electrochemical dissolution of TMDs since they are terminated by the chalcogenide elements. But for the type 2 configurations, we first carried out the simple binding energy analysis to identify

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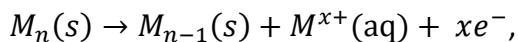
the weak binding sites, then we employed GC-DFT for the following evaluation. For materials with different elements located in the basal plane (i.e., type 3 materials), we initially compared their redox potentials and selected the element that more easily undergo the dissolution/oxidation. Then, detailed analyses including binding energy calculation were performed. In general, the selection is highly associated with the surface configuration, and the redox nature of the elements, and only the most unstable sites were selected for the evaluation to realize the key dissolution process at the early stage of the reaction.

Note that it is difficult for the current DFT framework to well predict the free energy of ions properly. In this work, the free energy of the ions was computed from the electronic energy of elemental atoms in their bulk phase *via* the experimental determined standard reduction potential (U_0 vs SHE). For example, for a metal element, this yields

$$F_{M^{x+}(aq)} = E_{M(s)} - N_e^M \mu + x|e|U_0 + k_B T \ln[M^{x+}]$$

where $F_{M^{x+}(aq)}$ is the grand free energy of $M^{x+}(aq)$ at the concentration of $[M^{x+}]$ mol L⁻¹, N_e^M is the number of valence electrons of metal atom, and μ is electron absolute energy referred to the vacuum level (for the CANDLE solvation model, μ_{SHE} is -4.66 V, which is different from the experimentally measured value of -4.44 V). Here, considering the actual operating condition, the dissolvable $M^{x+}(aq)$ in the electrolyte is typically small, which is in the order of $10^{-3} \sim 10^{-6}$ mol L⁻¹.^{19, 20} A concentration correction was applied, which was set to be 10^{-6} mol L⁻¹.

Assuming that metal dissolution in the 2D material follows the equation



and the corresponding grand free energy change of metal dissolution as a function of electrode potential can be written as

$$\Delta F = F_{M^{x+}(aq)} + x(\mu - \mu_{SHE}) + F_{M_{n-1}(s)} - F_{M_n(s)}$$

where the potential-dependent grand free energies of catalyst before and after metal dissolution (i.e., $F_{M_n(s)}$ and $F_{M_{n-1}(s)}$) were obtained by fitting the relative free energies at electrode potential of 0 and 2.0 V vs SHE following the previous works,^{9, 21, 22} and described as

$$F_{M(s)}(U) = k_x U + F_{M(s)}(0 \text{ V vs. SHE})$$

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It requires $\Delta F < 0$ to suppress the metal dissolution on the 2D materials, and thus the threshold potential of dissolution (U_{diss}) can be readily computed when $\Delta F = 0$. Similar procedures can be used to estimate the U_{diss} of the other active sites (see Table S7).

We note that shifting the concentration of $[M^{x+}]$ from 1.0 mol L^{-1} to $10^{-6} \text{ mol L}^{-1}$ can slightly change the values of U_{diss} . The computational results before and after correction is around 0.1 V in most of the cases, and larger changes occur on the PtPb₄ (0.19 V), VAg(PSe₃)₂ (0.25 V), CrGeTe₃ (0.17 V), AgHO₂ (0.22 V), and Te₂Pd₃Pb₂ (0.16 V). The detailed values of U_{diss} with/without concentration correction are listed in Table S7.

Coverage effect on the catalytic activity of ORR and OER

To study the effect of adsorbate-adsorbate interactions on the catalytic activity of ORR and OER, two adsorption types, including single-side adsorption (only one side of basal plane as the reaction area), and double-side adsorption, were considered on the 2D PtTe and NbSe₂ monolayers. Here, the PtTe and NbSe₂ were selected to study the adsorbate-adsorbate interactions because: 1) both of them have excellent activity for oxygen electrocatalysis as demonstrated by our computations; 2) they display different characteristics for adsorption of oxygen-containing species, in which the PtTe monolayer shows strong binding towards reaction species (*i.e.*, OOH*, O*, and OH*) with OH* → H₂O as the potential limiting step (PDS) for ORR; while the NbSe₂ monolayer exhibits weak binding with OOH*, O*, and OH*, and the O₂ → OOH* step is identified as the PDS of ORR.

According to our computations (Fig. S70a and S70b), when the reaction species coverage increases from low to high, the adsorption free energy of OOH*, O*, and OH* generally becomes more positive in both single- and double-side adsorption types, indicating that the interactions between the 2D materials and reaction intermediates are weakened. In particular, the coverage effect is more pronounced for the adsorption of O* than those of OOH* and OH* due to the strong band hybridization between O* and materials.

However, for the single-side adsorption, the coverage-induced potential difference is relatively small (with *ca.* 0.1 V derivation on the U_L value). The adsorbate-adsorbate interactions may not significantly affect the catalytic activity of the 2D materials in this adsorption mode. In comparison, the effect of the adsorbate-adsorbate interactions highly depends on the binding strength between the adsorbate and the material in the double-side adsorption.

SUPPORTING INFORMATION

Specifically, for the weak binding system of NbSe₂ monolayer, the U_L value of ORR/OER can be changed into 0.36/1.86 V in the double-side mode, and by comparison with the single-side adsorption, it is found that the coverage effect on the OER tends to be small, and the computed U_L values are in the range of 1.86–2.00 V, similar to those in the single-side mode (1.81–2.00 V). Whereas the adsorbate-adsorbate interactions can induce a largest derivation of 0.44 V on the U_L values of ORR, from 0.80 eV in the single-side mode to 0.36 V in the double-side adsorption, leading to a reduced catalytic activity. Such derivation between the two adsorption types is caused by the coverage-induced free energy change for OOH* adsorption, in which the adsorption free energy of OOH* on the NbSe₂ monolayer goes from 4.12 eV at the coverage of 12.5% in the single-side adsorption to 4.55 eV at the coverage of 37.5% in the double-side adsorption.

For the strong binding system of PtTe monolayer, the coverage-induced potential difference on ORR is insignificant due to the neglected free energy change for OOH* adsorption (Fig. S70a). However, for OER, with the change of the O* binding strength along different coverage, the U_L value decreases from *ca.* 2.20 V in the single-side adsorption to 1.76 V in double-side mode, suggesting that double-side adsorption can improve the catalytic performance of OER on the strong binding system.

In general, the above investigations suggest different approaches can be used to improve the catalytic performance, depending on the binding strength between the oxygen-containing species and the catalytic surface. For systems featuring weak binding for O*, OH*, and OOH*, for example, those with O₂↔OOH* step as the PDS of ORR, tuning the adsorption type into single-side adsorption could help maintain their catalytic activity. For instance, by increasing catalytic layer from monolayer to bilayer and forming van der Waals interactions, the reactions in the interlayer can be inhibited, accordingly the coverage effects can be reduced, and the catalytic performance be well kept (see Fig. S70c). In addition, modulating the anchoring configurations of 2D materials on the catalytic substrates could be helpful to maintain/improve the catalytic performance of 2D materials. For example, by contacting the 2D monolayers with catalytic substrates using their basal planes (Fig. S70d), the double-side adsorption type could also be prohibited. Differently, for the strong binding systems (*e.g.*, PtTe), it would be better to use the well separated monolayer as the catalyst and take advantage of the double-side adsorption to further tune/improve catalytic performance.

Reaction kinetics of 2D materials for the oxygen electrocatalysis

The kinetic simulation of oxygen electrocatalysis were performed on the 2D materials using the PtTe and NbSe₂ as the prototypes (see Fig. S5). The climbing image nudged elastic band (CI-NEB) method was used

SUPPORTING INFORMATION

for finding saddle points and minimum energy pathways during the oxygen electrocatalysis by inserting six NEB images between the initial and final states.²³ Explicit H₅O₂⁺ was used as the proton source, positioned above each surface of the materials. A linearized Poisson–Boltzmann implicit solvation model was used to neutralize the nonzero charge in the simulation, as implemented in VASPsol.¹³ Here, we applied a plate-capacitor based approach²⁴ to extrapolate reaction energetics to constant potentials by correcting for the work function change via the following equation:

$$\Delta G = \Delta G_0 + \beta \bar{\Phi} = \Delta G_0 + (q_2 - q_1) \left(\frac{\Phi_1 + \Phi_2}{2} \right)$$

where ΔG_0 is the free energy change of the two states at the potential of zero charge (PZC)), β is the charge transfer coefficient representing the potential dependence of the shift in energy between two given states. It is described by the difference in stored charge (q) between the two states within the capacitor model. Following the previous scheme, we employed Bader charge analysis to estimate β as the difference in the net charge of the catalyst surface from the transition state (TS) to the reaction's final state (FS). Moreover, to compare Φ to a potential experimental scale, the absolute potential reference of the standard hydrogen electrode was applied as $U_{\text{SHE}} = \Phi - 4.60$ V. The detailed reaction profiles of ORR on the PtTe and NbSe₂ were displayed in Fig. S5.

At the 0.0 V vs. SHE (i.e., overpotential $\eta=1.23$ V), the free energy changes along the ORR on these two surfaces are downhill without any kinetic barriers, indicating the reaction can proceed spontaneously. With the upshift of the external electrode potential (U) to the theoretical limiting potential (U_L , 0.83 V for PtTe, and 0.76 V for NbSe₂) and the equilibrium potential (U_{eq} , 1.23 V) of ORR, the kinetic barriers are arisen on both systems but yield different elementary steps.

On the PtTe surface (see Fig. S5a), the reaction is restricted in the step of OOH* protonation into O* (OOH* + H⁺/e⁻ → O* + H₂O), and no distinguishable barriers are available in the other steps within the potential range, including O₂ to OOH*, O* to OH*, and OH* to H₂O. On the basis of the capacitor model, we estimate that the charge transfer coefficient β is about 0.75. The activation free energy (ΔG^\ddagger) as the function of U follows the equation of $\Delta G^\ddagger = -0.36 + 0.75 U$. Simply, we can evaluate that the kinetic barrier of OOH* protonation step is 0.26 eV at the condition of U_L and 0.56 eV at the U_{eq} , respectively.

Similarly, we accessed the kinetic limitations on the NbSe₂ surface (see Fig. S5b), The protonation of O* into OH* (O* + H⁺/e⁻ → OH*) is identified as the rate-limiting step. The β is estimated by 0.34, and the corresponding kinetic barriers at the potential of U_L and U_{eq} are 0.18 eV and 0.34 eV, respectively. Such kinetic

SUPPORTING INFORMATION

barriers are in the same order as that on the Pt(111) (cat. 0.18 eV at the potential of U_L), and can be overcome at room temperature.

Generally, both previous studies and our own computations indicate that the kinetic contribution to oxygen electrocatalysis is insignificant, which might not dramatically change the activity trends obtained from the thermodynamic evaluation. Thus, the computational results presented in this manuscript could be credible and help to discover the potential catalysts and identify the active sites. Yet, based on catalytic activity analysis and electrochemical stability evaluation, we can conclude that simply predicting the catalytic activity and selectivity of catalysts could be insufficient to describe their overall performance; the stability issue of materials represents another central issue that should be carefully considered to preserve the active sites under the operating conditions. Therefore, to achieve a rational framework to identify candidate materials for experimental validation, *establishing effective methods to assess both catalytic activity and electrochemical stability* is very important, which is the focus of this study.

SUPPORTING INFORMATION

Table S1 Details about the 45 experimental synthesized 2D monolayers, including their formula, space group, decomposition energy, exfoliation energy, ID in Materials Project database, and reference of reported work.

Formula	Space group	Decomposition energy (meV/atom)	Exfoliation energy (meV/atom)	Obtained from	Reference
C	P6/mmm	2.1	67.0	mp-48	Science 2014, 306, 666–9
BN	P6 ₃ /mmc	0.1	0.1	mp-7991	Nat. Mater. 2010, 9, 430–435
P	Pmna	42.5	109.4	mp-157	ACS Nano 2014, 8, 4033–4041
NbS ₂	P-6m2	3.9	92.5	mp-10033	Nanoscale, 2017, 9, 16607–16611
NbSe ₂	P-6m2	5.1	5.1	mp-7597	Nat. Commun. 2017, 8, 394
NbTe ₂	P-3m1	47.7	106.3	mp-1018150	Adv. Funct. Mater. 2019, 29, 1806611
VTe ₂	P-3m1	22.6	98.2	mp-1008626	
TaTe ₂	C2/m	17.6	114.0	mp-1967	
WTe ₂	P2_1/m	0	84.6	mp-22693	2D Mater. 2017, 4 021008 Nano Lett. 2017, 17, 2, 878–885 Nanoscale, 2016, 8, 2309–2316
MoSe ₂	P-6m2	1.9	78.3	mp-1634	ChemPhysChem, 2014, 15, 1592– 1598
WSe ₂	P-6m2	1.7	77.7	mp-1821	
MoTe ₂	P-6m2	3.8	89.1	mp-602	Nano Lett. 2014, 14, 6231–6236
WS ₂	P-6m2	1.6	56.4	mp-224	Nano Lett. 2013, 13, 3447–3454
C ₃ N ₄	P-6m2	86.5	82.2	mp-971684	Carbon 2014, 80, 213–221
MoS ₂	P-6m2	2.1	76.3	mp-2815	Sci. Rep. 2013, 3, 1866
ZrS ₂	P-3m1	0	89.4	mp-1186	J. Am. Chem. Soc. 2015, 137, 7051–7054
ZrSe ₂	P-3m1	0	95.4	mp-2076	Appl. Sci. 2016, 6 264
HfS ₂	P-3m1	0	86.4	mp-985829	Adv. Mater. 2015, 27 7881–7
TaS ₂	P-1	16.6	90.4	none	Chem. Mater. 2016, 28 7613–8
TaSe ₂	P-6m2	3.8	69.3	mp-500	Nano Lett. 2018, 8 689–94
VSe ₂	P-3m1	0	86.0	mp-694	Chem. Commun. 2016, 52 9228–31
VS ₂	P-6m2	0	78.7	mp-1013525	Adv. Funct. Mater. 2020, 30, 2000240
PtSe ₂	P-3m1	0	88.7	mp-1115	Nano Lett. 2015, 15 4013–8
PtS ₂	P-3m1	0	97.7	mp-762	Adv. Mater. 2016, 28 2399–407

SUPPORTING INFORMATION

TiS₂	P-3m1	2.0	88.4	mp-2156	Nat. Mater. 2015, 14, 622–627
TiSe₂	P-3m1	0	92.3	mp-2194	Adv. Mater. 2018, 30, 1704382
ReS₂	P-1	0	71.5	mp-572758	Nat. Commun. 2014, 5, 3252
PdSe₂	P2_1/c	8.0	166.7	mp-2418	J. Am. Chem. Soc. 2017, 139, 14090–14097
InSe	P-6m2	1.9	63.7	mp-22691	2D Mater. 2018, 5, 025019
GaTe	P-6m2	8.3	58.5	mp-10009	2D Mater. 2018, 2, 035010
GaSe	P-6m2	2.1	43.6	mp-1943	2D Mater. 2018, 2, 035010
TiS₃	Pmmn	0	54.2	mp-9920	Adv. Mater. 2015, 27, 2595–2601
HfTe₃	Pmmn	25.5	88.9	mp-1025459	Adv. Electron. Mater. 2016, 2, 1600324
CrI₃	P-31m	0	89.2	none	Nature 2017, 546, 270–273
Bil₃	P-31m	9.2	95.7	mp-22849	ACS Appl. Mater. Interfaces 2021, 13, 25918–25925
FeSe	P4/nmm	0	85.5	mp-20311	Phys. Rev. B 2011, 84, 020503
MoO₃	P2_1/m	32.9	38.9	mp-510584	Nano Lett. 2017, 17, 3854–3861
Bi₂Se₃	P-3m1	0	67.7	mp-541837	Nano Lett. 2015, 15, 2645–2651
Bi₂Te₃	P-3m1	0	77.9	mp-34202	ACS Nano 2016, 10, 11442–11448
SnS₂	P-3m1	3.7	81.7	mp-1170	ACS Nano 2019, 13, 8265–8274
GaS	P-6m2	1.3	39.3	mp-2507	Nano Lett. 2013, 13, 1649–1654
ReS₂	P-1	0	71.5	mp-572758	Adv. Mater. 2020, 32, 2001890
ReSe₂	P-1	0	74.5	mp-541582	Nano Res. 2018, 11, 1787–1797
PtTe₂	P-3m1	0	145.7	mp-399	Nat. Commun. 2017, 8, 257
CrTe₂	P2_1/m	28.3	28.3	none	Nat. Commun. 2021, 12, 2492

SUPPORTING INFORMATION

Table S2. Structural and electronic information of 339 candidate materials which screened from the band structure analysis, including space group, band gap, decomposition energy, exfoliation energy, Electrical conductivity, and Identity number in materials project database. Note that the ground state of the layered materials might be changed due to the update of database, which would slightly change the values of the decomposition and exfoliation energies.

Formula	Space group	Band gap (meV)	Is gap direct?	Decomposition compound(s)	Decomposition energy (meV/atom)	Exfoliation energy (meV/atom)	Electrical conductivity ($\Omega^{-1} \text{ m}^{-1} \text{ s}^{-1}$)	Identity number in MP
Eu(ReO₄)₂	P-3	314	No	\	0	68	4.19E-10	mp-754760
HfFeCl₆	P312	94	No	FeCl ₃ + Fe + HfCl ₄	18	70	3.07E-03	mp-28220
Gd₂CCl₂	P-3m1	493	No	Gd ₅ C ₂ Cl ₉ + Gd ₄ C ₂ Cl ₃ + C	0	41	2.19E+00	mp-29394
PdSeO₃	C2/m	452	Yes	PdSeO ₃	22	67	8.31E+00	mp-546684
Gd₂Br₃	C2/m	149	No	GdBr ₃ + Gd	9	100	2.35E+01	mp-618813
VCuO₄	Pmma	290	No	Cu ₂ O ₃ + V ₂ O ₅	71	111	3.57E+01	mp-510733
CuBrO₂	P2/m	0	No	Br ₂ O ₃ + Cu ₂ O ₃ + Br	27	143	2.04E+02	mp-996993
CuBrO₂	P222_1	458	Yes	Br ₂ O ₃ + Cu ₂ O ₃ + Br	36	56	2.04E+02	mp-997011
CuSbS₂	Pmc2_1	373	Yes	\	0	144	3.39E+02	mp-4468
CeP₃H₈O₇	P-1	311	No	H ₂ O + CePO ₄ + H ₂ + P	49	42	3.44E+02	mp-505610
ZrI₂	P2_1/m	432	No	\	0	77	6.06E+02	mp-570506
K₂As₂Pd	Pmma	423	Yes	\	0	156	7.35E+02	mp-8147
ZrSe₂	P-3m1	458	No	\	0	95	9.32E+02	mp-2076
FeCl₂	P-3m1	0	No	\	0	64	9.76E+02	mp-23229
TiGeTe₆	P2_1/m	412	No	\	0	101	9.93E+02	mp-574169
Nb₂GeTe₄	Pbam	430	No	\	0	80	1.20E+03	mp-29073
In₂Se₃	P-3m1	492	No	In ₂ Se ₃	48	51	1.34E+03	mp-1017565
K₂P₂Pd	Pmma	401	No	\	0	172	2.53E+03	mp-7505
z-Feb	P-3m1	0	No	\	0	73	3.45E+03	mp-22880
TiS₃	Pmmn	275	Yes	\	0	54	3.66E+03	mp-9920
Ge₄Te₇As₂	P-3m1	422	No	Te ₃ As ₂ + GeTe	19	33	7.93E+03	mp-568730
ZrSe₃	Pmmn	448	No	\	0	54	8.45E+03	mp-1683
La₂GeI₂	P-3m1	402	No	\	0	48	1.05E+04	mp-570597
FeI₂	P-3m1	0	No	\	0	81	1.08E+04	mp-571122
NbS₃	P2_1/m	406	No	NbS ₃	0	46	1.36E+04	mp-562100
Cel₃	Pmmn	30	No	\	0	98	1.56E+04	mp-1025426
TaSe₂	P-3	159	No	TaSe ₂	7	92	3.10E+04	mp-542495
Ge₅(Te₄As)₂	P-3m1	322	No	Te ₃ As ₂ + GeTe	19	25	4.04E+04	mp-28487

SUPPORTING INFORMATION

CuSeO₃	P2_1/c	134	No	Cu ₄ Se ₃ O ₁₀ + CuSe ₂ O ₅	36	36	5.70E+04	mp-22688
CuSbSe₂	Pmc2_1	152	Yes	\	0	152	5.86E+04	mp-20331
MoCl₃	C2/m	126	Yes	MoCl ₅ + MoCl ₂	60	70	7.41E+04	mp-22853
C	P6/mmm	0	Yes	C	2	67	7.55E+04	mp-48
Li₂NbP₄O₁₃	P-1	262	No	Nb ₂ (PO ₄) ₃ + LiPO ₃ + P ₂ O ₅ + P	70	36	7.79E+04	mp-673156
Rb₂O	P31m	316	No	Rb ₂ O	10	51	1.29E+05	mp-776922
HfSe₃	Pmmn	360	No	\	0	47	1.43E+05	mp-15622
Y₂Gel₂	P-3m1	157	No	\	0	45	1.88E+05	mp-676315
Sc₆C₂I₁₁	P-1	386	No	\	0	78	3.31E+05	mp-541102
TiIN	Pmmn	31	Yes	\	0	44	5.04E+05	mp-27848
CeBrO	P4/nmm	0	No	\	0	63	5.82E+05	mp-754112
CeBrO	P-3m1	0	No	CeBrO	19	38	5.82E+05	mp-755464
Ge₃(BiTe₃)₂	P3m1	0	No	Bi ₂ Te ₃ + GeTe	38	37	5.94E+05	mp-540687
AgSb₂F₁₂	P-1	454	No	\	0	29	7.49E+05	mp-14653
CrP₂S₇	C2	36	No	P ₂ S ₅ + P ₂ S ₇ + Cr ₅ S ₈	32	56	7.87E+05	mp-768680
CuTeO₃	P2_1/c	1	Yes	CuO + TeO ₂	69	148	7.91E+05	mp-558696
Li₂CrP₄O₁₃	P-1	343	Yes	LiCrP ₂ O ₇ + LiPO ₃ + Cr(PO ₃) ₃ + O ₂	60	36	8.17E+05	mp-705053
CuH₂SeO₅	P-1	0	No	CuSeO ₄ + H ₂ O	44	120	8.37E+05	mp-23955
MnPSe₃	P-31m	450	Yes	\	0	73	8.94E+05	mp-8695
CuHClO	P2_1/c	19	No	H ₂ O + CuO + CuCl ₂	75	82	9.63E+05	mp-643743
V₂P₄S₁₃	P-1	129	No	P ₄ S ₉ + VS ₂	12	69	9.94E+05	mp-620190
Li₂Cu₂F₇	P-1	150	No	LiCu ₂ F ₆ + LiF	68	53	1.16E+06	mp-753090
SrSbSe₂F	P4/nmm	58	Yes	SrSe + Sb ₂ Se ₃ + SrF ₂	29	58	1.16E+06	mp-556194
BiTe	P-3m1	0	No	Bi ₄ Te ₃ + Bi ₂ Te ₃	6	33	1.17E+06	mp-23224
Li₂Cr₃(CO₃)₆	P-1	0	No	CrO ₂ + LiCr(CO ₃) ₂ + CO ₂	71	70	1.18E+06	mp-763398
Mn₂F₇	P2/c	215	Yes	MnF ₃ + MnF ₄	52	41	1.24E+06	mp-765923
CrTe₃	Pmna	279	No	CrTe ₂ + Te	21	97	1.30E+06	mp-540922
NbTe₄Ir	P2_1/m	28	No	\	0	103	1.34E+06	mp-505164
AgIrF₇	Pmc2_1	0	No	\	0	85	1.36E+06	mp-662534
Nb₃Cl₈	P3m1	236	No	\	0	72	1.37E+06	mp-29950
CuMoO₄	P1	430	No	MoO ₃ + CuO	52	134	1.45E+06	mp-619545
La₂Br₅	P2_1/m	412	No	LaBr ₂ + LaBr ₃	6	101	1.46E+06	mp-28571
Bi₂Te₅Pb₂	P-3m1	0	No	TePb + Bi ₂ Te ₄ Pb	64	48	1.51E+06	mp-569044

SUPPORTING INFORMATION

Cu(IO₃)₂	P2_1/m	426	No	Cu(IO ₃) ₂	20	68	1.53E+06	mp-556582
CuSeO₃	P-1	0	No	Cu ₄ Se ₃ O ₁₀ + CuSe ₂ O ₅	20	54	1.60E+06	mp-560049
LiWCl₆	P3	74	No	WCl ₄ + WCl ₆ + LiCl	17	75	1.64E+06	mp-570512
ZrTe₅	Pmmn	22	Yes	\	0	90	1.65E+06	mp-605
Zn(InS₂)₂	P3m1	0	No	Zn(InS ₂) ₂	76	59	1.66E+06	mp-22253
MnSbSe₂I	P2/m	73	No	Mn(SbSe ₂) ₂ + MnI ₂	72	189	1.67E+06	mp-570268
Nb₃I₈	P3m1	293	No	\	0	99	1.69E+06	mp-27772
VAg(PS₃)₂	P2/c	0	No	P ₄ S ₇ + VS ₂ + P ₄ S ₃ + Ag ₃ PS ₄	29	67	1.70E+06	mp-6462
CeZnPO	P-3m1	0	No	\	0	142	1.74E+06	mp-13207
Nb₃SiTe₆	Pmc2_1	0	No	NbTe ₂ + Nb ₂ SiTe ₄	10	94	1.79E+06	mp-505137
AgBi₂F₁₂	P-1	363	No	\	0	31	1.89E+06	mp-28965
Ta₂PtSe₇	P2_1/m	14	No	Ta ₂ Pt ₃ Se ₈ + TaSe ₃ + PtSe ₂	3	80	1.91E+06	mp-14474
TaTe₄Ir	P2_1/m	24	No	\	0	98	1.92E+06	mp-17287
Nb₃GeTe₆	Pmc2_1	0	No	NbTe ₂ + Nb ₂ GeTe ₄	12	94	1.93E+06	mp-28754
CrS₂	P-3m1	0	No	\	0	53	1.99E+06	mp-755263
CuAgO₂	P2/m	0	No	CuAgO ₂	73	193	2.03E+06	mp-7237
Ta₃SiTe₆	Pmc2_1	0	No	\	0	92	2.06E+06	mp-505206
Cu₂H₂CO₅	P2_1/c	0	No	CuO + H ₂ O + CO ₂	60	100	2.10E+06	mp-504588
CuH₂SO₅	P-1	233	No	\	0	113	2.17E+06	mp-24522
CrPO₅	P-1	377	No	CrPO ₄ + O ₂	44	26	2.18E+06	mp-773520
₃-Feb	P-31m	40	No	\	0	81	2.22E+06	mp-23232
FeCl₃	P-31m	395	No	\	0	69	2.23E+06	mp-583463
VCl₃	P-31m	1	Yes	VCl ₂ + VCl ₄	0	73	2.23E+06	mp-28117
TiAgF₆	P-1	208	No	AgF ₂ + TiF ₄	54	119	2.23E+06	mp-10810
Sc₇Cl₁₀	C2/m	0	No	\	0	69	2.37E+06	mp-27513
Ta₂Te₅Pd₃	Pmn2_1	0	No	\	0	85	2.42E+06	mp-28934
Li₂FeP₄O₁₃	P-1	47	No	LiFeP ₂ O ₇ + LiFe(PO ₃) ₄ + LiPO ₃ + O ₂	74	40	2.43E+06	mp-763647
ZrBr	P-3m1	0	No	\	0	55	2.54E+06	mp-504594
Te₂OsCl₁₂	P-1	0	No	\	24	44	2.59E+06	mp-28866
La₂I₅	P2_1/m	254	No	\	0	92	2.61E+06	mp-30282
HfTe₅	Pmmn	0	No	\	0	89	2.65E+06	mp-1168
Cu₃OF₅	P2_1	0	No	CuF ₂ + Cu ₂ O ₃ + O ₂	58	76	2.71E+06	mp-755255

SUPPORTING INFORMATION

Ce₄C₂Br₅	Pmmm	0	No	Ce ₂ C ₃ + Ce ₅ C ₂ Br ₉ + Ce	7	105	2.72E+06	mp-574262
Li₂Cu₂F₅	P2_1/m	101	No	CuF ₂ + LiF + Cu	60	54	2.83E+06	mp-762270
MnSbSe₂Br	Pmc2_1	115	No	Mn(SbSe ₂) ₂ + MnBr ₂	80	195	2.84E+06	mp-567478
Er(ReO₄)₂	P-3	0	No	Er(ReO ₄) ₃ + ReO ₃ + Er ₂ O ₃	26	86	2.85E+06	mp-755194
BiSe	P-3m1	0	No	Bi ₂ Se ₃ + Bi	8	26	2.87E+06	mp-27902
CuMoF₆	P-1	0	No	MoF ₆ + CuF ₂ + MoF ₃	73	108	2.91E+06	mp-611706
H₄W	P4/nmm	23	No	W + H ₂	16	25	2.95E+06	mp-1078595
RuCl₃	P-31m	3	Yes	RuCl ₃	33	74	2.98E+06	mp-570997
TaCoTe₂	P2_1/c	9	Yes	Ta(CoTe) ₂ + TaTe ₂	12	75	3.24E+06	mp-28846
Er₆I₇	C2/m	0	No	Er + ErI ₃	59	69	3.24E+06	mp-571258
CuH₂(SeO₃)₂	P2_1/c	72	Yes	\	0	93	3.35E+06	mp-24164
Pr₂Br₅	P2_1/m	349	No	\	0	93	3.44E+06	mp-23169
Ta₄Co₂PdSe₁₂	C2/m	6	No	\	0	82	3.48E+06	mp-505133
TbCl	P-3m1	0	No	Tb ₂ Cl ₃ + Tb	53	53	3.52E+06	mp-27923
CuTeO₄	P2/m	0	No	CuTeO ₄	25	125	3.56E+06	mp-755455
K₂RuBr₆	Pmn2_1	0	No	\	0	none	3.62E+06	mp-1097045
VAg(PSe₃)₂	C2	95	No	Ag ₂ PSe ₃ + V ₂ Se ₉ + VSe ₂ + PSe	12	72	3.63E+06	mp-6543
KFe₂S₃	Pmma	0	No	\	0	138	3.66E+06	mp-22035
MnF₄	P2_1/c	32	Yes	\	0	48	3.74E+06	mp-765921
Nb₂Se₃	P2_1/m	11	No	Nb ₃ Se ₄ + NbSe ₂	48	137	3.76E+06	mp-2330
Pr(ReO₄)₂	P-3	0	No	\	0	92	3.84E+06	mp-754632
Ta₂NiS₅	Pmmn	0	No	\	0	72	3.96E+06	mp-28308
CrGeTe₃	P-31m	484	No	GeTe + Cr ₅ Te ₈ + Te	0	89	4.01E+06	mp-541449
Nb₉IrSe₂₀	P-1	0	No	IrSe ₂ + NbSe ₂	45	68	4.03E+06	mp-675290
Ta₂NiSe₅	Pmmn	0	No	\	0	73	4.03E+06	mp-541070
TiS₂	P-3m1	26	No	\	0	88	4.05E+06	mp-2156
NiPS₃	P-31m	47	No	P ₄ S ₇ + NiPS + Ni ₃ S ₄	64	61	4.05E+06	mp-676040
TbBr	P-3m1	0	No	TbBr ₃ + Tb	16	47	4.06E+06	mp-27924
TiCl₃	C2/m	0	No	TiCl ₃	5	61	4.15E+06	mp-569756
AgRuF₇	P2_1/c	0	No	\	0	31	4.28E+06	mp-17588
LiNi(PS₃)₂	P312	31	No	P ₄ S ₉ + Li ₃ PS ₄ + P ₄ S ₇ + Ni ₃ S ₄	36	63	4.30E+06	mp-557500
TiBr₃	C2/m	0	No	\	2	79	4.31E+06	mp-28214
Fe₄S₅	P4/n	0	No	FeS + FeS ₂	59	2	4.35E+06	mp-850083
TaSe₃	P2_1/m	0	No	\	0	65	4.39E+06	mp-29652

SUPPORTING INFORMATION

Sc₅Cl₈	P2/m	0	No	\	1	79	4.45E+06	mp-542449
Pr₂I₅	P2_1/m	155	No	\	0	88	4.53E+06	mp-22854
Nb₄IrSe₁₀	P-1	0	No	IrSe ₂ + NbSe ₂	38	86	4.54E+06	mp-675326
CrCuO₄	Pmma	116	No	Cr ₅ O ₁₂ + Cu ₂ O ₃ + O ₂	69	127	4.58E+06	mp-504927
KFe₂Se₃	Pmma	0	No	FeSe + KFeSe ₂	68	129	4.69E+06	mp-1095516
ZrCl	P-3m1	0	No	\	0	52	4.71E+06	mp-27440
La₂(BiO₂)₇	P1	0	No	La ₂ Bi ₂ O ₇ + La ₁₀ Bi ₈ O ₂₇ + Bi ₂ O ₃	77	37	4.83E+06	mp-753524
NbCoTe₂	P2_1/c	0	No	NbCoTe ₂	7	78	5.25E+06	mp-571471
Tb₅Br₈	P2/m	0	No	TbBr ₃ + Tb	33	103	5.28E+06	mp-31007
YCl	C2/m	0	No	\	0	37	5.33E+06	mp-23062
YCl	P-3m1	0	No	Y ₂ Cl ₃ + Y	51	54	5.33E+06	mp-540884
Tl₂Cu₃(SeO₃)₆	P-1	162	No	\	0	56	5.44E+06	mp-558944
Nb₃IrSe₈	C2	0	No	IrSe ₂ + NbSe ₂	11	88	5.45E+06	mp-675066
Cu₃Te₂(BrO₃)₂	C2/m	0	No	CuBr ₂ + CuO + TeO ₂	17	41	5.48E+06	mp-572313
Ag(TeMo)₆	C2/m	0	No	\	0	76	5.53E+06	mp-29607
NbCrSe₅	P2_1/m	0	No	Nb ₂ Se ₉ + Cr ₂ Se ₃ + NbSe ₂	2	77	5.55E+06	mp-28019
CrI₂	C2/m	253	No	CrI ₃ + Cr	0	84	5.58E+06	mp-27215
Fe(CO₃)₂	P-3	0	No	CO ₂ + Fe ₂ O ₃ + O ₂	59	36	5.84E+06	mp-769642
CuF₂	P2_1/c	461	No	\	0	127	5.88E+06	mp-1229
LiCu(PO₃)₃	P-1	401	No	LiCu(PO ₃) ₃	71	79	6.04E+06	mp-758797
Ta₂Se₃	P2_1/m	0	No	Ta ₂ Se + TaSe ₂	30	123	6.05E+06	mp-9983
TbGal	P-3m1	0	No	\	0	45	6.23E+06	mp-1025099
Te₂W	P2_1/m	73	No	\	0	84	6.25E+06	mp-22693
AgClO₂	P2_1/m	186	No	AgClO ₄ + AgCl	0	54	6.27E+06	mp-997017
Cu₃OF₅	P-1	0	No	CuF ₂ + Cu ₂ O ₃ + O ₂	60	72	6.27E+06	mp-755349
Mn₂Ga₂S₅	P-3m1	0	No	Mn(GaS ₂) ₂ + MnS	50	26	6.28E+06	mp-1078896
ScHCl	P-3m1	0	No	\	0	35	6.96E+06	mp-24081
CrBr₂	C2/m	447	No	CrBr ₃ + Cr	73	74	7.01E+06	mp-567624
Cu₃Se₂(ClO₃)₂	C2/m	0	No	CuSe ₂ O ₅ + Cu ₄ Se ₃ O ₁₀ + CuCl ₂	3	42	7.18E+06	mp-557136
Cu₃Se₂(ClO₃)₂	P-1	58	No	CuSe ₂ O ₅ + Cu ₄ Se ₃ O ₁₀ + CuCl ₂	14	49	7.18E+06	mp-557946
VT₂	C2/m	0	No	\	0	115	7.18E+06	mp-11687
Sc₅CCl₈	P2/m	0	No	\	0	102	7.20E+06	mp-31024

SUPPORTING INFORMATION

CrSe₂	P-3m1	0	No	Cr ₂ Se ₃ + Se	11	113	7.22E+06	mp-1009581
Ag₂IO₆	P-31m	0	No	Ag ₃ O ₄ + AgI ₃ O ₈ + O ₂	45	9	7.25E+06	mp-1079032
Sr₂CoClO₃	P4/nmm	0	No	Sr ₃ (CoO ₃) ₂ + Sr ₂ Co ₂ O ₅ + Sr ₄ Cl ₆ O	36	35	7.25E+06	mp-505678
YGaI	P-3m1	0	No	\	0	39	7.39E+06	mp-571210
TaTe₂	C2/m	0	No	\	17	114	7.43E+06	mp-1967
NiPSe₃	P-31m	0	No	NiSe ₂ + NiP ₂ + Se	64	74	7.45E+06	mp-1079754
AgF₂	P2_1/c	0	No	\	0	150	7.52E+06	mp-7715
Y₇C₃I₆O	Pmma	0	No	\	0	31	7.72E+06	mp-554027
AgHO₂	Cm	0	No	\	0	126	7.75E+06	mp-996958
TaFeTe₃	P2_1/m	0	No	Ta ₄ FeTe ₄ + FeTe ₂ + TaTe ₂	24	82	7.80E+06	mp-8848
Ta₂PdSe₆	C2/m	79	No	\	0	89	7.91E+06	mp-8436
Mn₃CuO₈	P-3m1	6	No	Cu ₂ O ₃ + MnO ₂ + O ₂	61	60	7.99E+06	mp-771841
Cr(GaS₂)₂	P-3m1	0	No	GaS + Cr ₃ GaS ₆ + Ga ₂ S ₃	62	36	8.54E+06	mp-985304
ZrCl₃	C2/m	173	No	ZrCl ₃	51	73	8.67E+06	mp-1100795
Sr₃Co₂Cl₂O₅	P4/mmm	0	No	Sr ₂ Co ₂ O ₅ + Sr ₅ (CoO ₃) ₄ + Co ₃ O ₄ + Sr ₄ Cl ₆ O	53	8	8.69E+06	mp-24846
NbFeTe₂	Pmna	0	No	NbTe ₂ + Fe	25	82	8.69E+06	mp-616481
Cr₃Te₄	P-3m1	0	No	Cr ₅ Te ₈ + Cr	67	51	8.79E+06	mp-570122
NbTe₂	C2/m	0	No	\	0	121	8.81E+06	mp-11675
V₆O₁₃	Pmma	0	No	VO ₂ + V ₂ O ₅	63	67	9.07E+06	mp-715617
Tl₂CuF₄	P4/mmm	0	No	\	0	66	9.14E+06	mp-1025338
Ta₂PdS₆	C2/m	162	No	\	0	83	9.39E+06	mp-8435
Sc₅NCl₈	P2/m	0	No	Sc ₅ Cl ₈ + Sc ₄ NCl ₆ + ScCl ₃	28	98	9.49E+06	mp-31025
LuHCl	P-3m1	0	No	\	0	36	9.49E+06	mp-23896
ErHCl	P-3m1	0	No	\	0	36	9.64E+06	mp-24051
KV₄O₁₀	Amm2	0	No	VO ₂ + KV ₃ O ₈	50	61	9.69E+06	mp-767780
Bi₄I	P2/m	0	No	BiI ₃ + Bi	76	102	9.72E+06	mp-583234
CoCl₂	P-3m1	109	No	CoCl ₂	0	67	9.82E+06	mp-23240
MoTe₂	P2_1/m	0	No	MoTe ₂	21	87	9.88E+06	mp-7459
ScCl	P-3m1	0	No	Sc ₇ Cl ₁₀ + Sc	23	50	9.99E+06	mp-27507
Ta₃Te₁₄Pd₃	Pm	0	No	\	0	104	1.02E+07	mp-505132
LiCu₂(CO₃)₂	P1	0	No	Cu ₂ O + Li ₂ CO ₃ + CuO + CO ₂	70	53	1.03E+07	mp-760546
Bi₉I₂	P2_1/m	0	No	BiI ₃ + Bi	70	97	1.03E+07	mp-28149
Y₄Cl₅	Pmmm	0	No	\	0	80	1.04E+07	mp-23382

SUPPORTING INFORMATION

TaNi₂Te₃	P2_1/m	0	No	\	0	79	1.05E+07	mp-9391
La₄C₂Br₅	Pmmm	0	No	\	0	107	1.09E+07	mp-569873
CrSBr	Pmmn	292	Yes	\	0	51	1.09E+07	mp-22998
RbV₄O₁₀	Cmmm	0	No	RbV ₃ O ₈ + VO ₂	45	61	1.09E+07	mp-764947
Sc₇(CCl₅)₂	C2/m	0	No	\	0	81	1.11E+07	mp-29315
Nb₂Te₃	P2_1/m	0	No	NbTe ₂ + Nb ₃ Te ₄	38	102	1.13E+07	mp-570451
CuSi₂P₃	Pm	0	No	Cu ₄ SiP ₈ + Cu ₁₅ Si ₄ + SiP	64	24	1.14E+07	mp-674984
Y₆C₂I₇	C2/m	0	No	\	0	55	1.14E+07	mp-23440
NbSe₃	P2_1/m	0	No	\	0	57	1.19E+07	mp-525
Na₂ZrN₂	P-3m1	0	No	Zr ₃ N ₄ + NaN ₃ + Na	78	43	1.22E+07	mp-1029316
TaTe₂	C2/m	0	No	TaTe ₂	20	113	1.23E+07	mp-601823
Bi₂Rh₃S₂	C2/m	0	No	\	0	150	1.25E+07	mp-977592
CoBr₂	P-3m1	43	No	\	0	75	1.26E+07	mp-30033
Mn(InSe₂)₂	P3m1	0	No	MnSe + In ₂ Se ₃	39	51	1.27E+07	mp-1078140
Nb₂PdS₆	C2/m	0	No	\	0	86	1.29E+07	mp-1080466
AgClO₂	P2_1/m	13	No	AgClO ₄ + AgCl	0	59	1.32E+07	mp-997013
Ta₂Te₃	C2/m	0	No	\	0	78	1.32E+07	mp-542634
LiCu₃F₁₀	Pc	0	No	\	0	41	1.32E+07	mp-760825
NbNiTe₂	Pmna	0	No	\	0	81	1.32E+07	mp-20506
Nb₃IrS₈	C2	0	No	NbS ₂ + IrS ₂	28	89	1.33E+07	mp-675367
TaS₃	P2_1/m	0	No	\	0	55	1.36E+07	mp-30527
RbMnAs	P4/nmm	0	No	RbAs + Mn	73	-11	1.37E+07	mp-20242
Pr₄C₂Cl₅	Pmmm	0	No	\	0	123	1.39E+07	mp-570498
Na₂HfN₂	P-3m1	0	No	Hf ₃ N ₄ + NaN ₃ + Na	76	43	1.45E+07	mp-1029309
Ga₂NiS₄	P-3m1	0	No	Ni ₉ S ₈ + Ni ₃ S ₄ + Ga ₂ S ₃	54	29	1.45E+07	mp-6959
MnS₂	P-3m1	0	No	\	0	59	1.46E+07	mvc-14047
HfTe₂	P-3m1	0	No	\	0	103	1.48E+07	mp-32887
TiSe₂	P-3m1	0	No	\	0	92	1.48E+07	mp-2194
NaFeAs	P4/nmm	0	No	\	0	105	1.50E+07	mp-22152
TaNiTe₂	Pmna	0	No	\	0	82	1.59E+07	mp-19810
CoI₂	P-3m1	0	No	Co + I	19	88	1.66E+07	mp-569610
VBr₂O	Pmmm	408	Yes	VBrO + Br	13	64	1.81E+07	mp-32450
CuAuO₂	P2/m	0	No	\	0	182	1.82E+07	mp-996978
Sr₂Cu(IO)₂	P4/mmm	0	No	\	0	41	1.87E+07	mp-549487
VS₂	P-6m2	27	No	\	0	78	1.89E+07	mp-1013525
AlPd₅I₂	P4/mmm	0	No	\	0	50	1.90E+07	mp-27393
CeS₁	P-3m1	0	No	\	0	43	1.92E+07	mp-29535
AuSe	C2/m	0	No	AuSe	10	74	1.92E+07	mp-570325
Ta₂Se	P4/nmm	0	No	\	0	59	1.93E+07	mp-8732

SUPPORTING INFORMATION

LaI₂	P4/mmm	0	No	\	0	85	1.96E+07	mp-23194
Ag(AuS)₂	Pc	0	No	Ag ₃ AuS ₂ + AgAuS ₂ + Au ₂ S	64	98	1.97E+07	mp-35835
EuBrO	P4/nmm	0	No	\	0	59	2.08E+07	mp-504727
CuBr₂	C2/m	0	No	\	0	93	2.12E+07	mp-23219
Sr₂Co(ClO)₂	P4/mmm	225	No	Sr ₂ Co(ClO) ₂	23	54	2.12E+07	mp-560610
RbMnP	P4/nmm	0	No	\	0	46	2.13E+07	mp-21413
ZrTiTe₄	P2/m	0	No	TiTe ₂ + ZrTe ₂	25	113	2.13E+07	mp-8677
Ca(TiS₂)₈	P-3m1	0	No	\	0	40	2.13E+07	mvc-16026
Sr₂Cu(BrO)₂	P4/mmm	0	No	\	0	48	2.13E+07	mp-546898
FeSe	P4/nmm	0	No	\	0	85	2.15E+07	mp-20311
NbSe₂	P-6m2	0	No	NbSe ₂	5	93	2.18E+07	mp-7597
VTe₂	P-3m1	0	No	VTe ₂	22	98	2.19E+07	mp-1008626
NaMnAs	P4/nmm	0	No	Mn ₂₃ As ₁₆ + Na ₃ As + Mn	73	93	2.20E+07	mp-20612
ZrHCl	P-3m1	0	No	ZrCl ₂ + ZrH ₂	73	33	2.23E+07	mp-1024958
Ca₂Cu(BrO)₂	P4/mmm	0	No	\	0	42	2.26E+07	mp-545481
Nil₂	P-3m1	142	No	\	0	79	2.28E+07	mp-27638
TaSe₂	P-6m2	0	No	TaSe ₂	3	69	2.29E+07	mp-500
KMnP	P4/nmm	0	No	\	0	48	2.30E+07	mp-20422
Sr₂Cu(ClO)₂	P4/mmm	0	No	\	0	74	2.31E+07	mp-23102
Ca₂Cu(ClO)₂	P4/mmm	0	No	Ca ₄ Cl ₆ O + CaCu ₃ O ₄ + CaO	20	63	2.34E+07	mp-23143
Na₃(TiS₂)₁₀	Cm	0	No	\	0	43	2.36E+07	mp-675056
LiFeP	P4/nmm	0	No	\	0	163	2.36E+07	mp-20049
FeS	P4/nmm	0	No	\	0	83	2.41E+07	mp-505531
CoTe₂	P-3m1	0	No	\	0	165	2.42E+07	mp-1009641
NbS₂	P-6m2	0	No	\	0	92	2.43E+07	mp-10033
NdI₂	P4/mmm	0	No	\	0	94	2.57E+07	mp-28753
TaS₂	P-6m2	0	No	\	0	88	2.61E+07	mp-1984
Ta₄AgS₈	P2_1/m	0	No	Ta ₄ AgS ₈	0	43	2.66E+07	mp-677597
NbNiTe₅	Pmma	0	No	\	0	78	2.76E+07	mp-8999
MnSe	P4/nmm	0	No	MnSe	32	82	2.80E+07	mp-604910
GdBr	P-3m1	0	No	GdBr ₃ + Gd	70	57	2.84E+07	mp-1064427
Zr₂HBr₂	P2_1/m	0	No	ZrBr + ZrH ₂ + ZrBr ₃	24	41	2.94E+07	mp-642803
VSe₂	P-3m1	0	No	\	0	86	2.95E+07	mp-694
La₂Pl₂	P-3m1	0	No	\	0	54	3.00E+07	mp-571647
TaTe₅Pt	Pmma	0	No	\	0	70	3.01E+07	mp-14815
AgO₂F	P2_1/m	0	No	\	0	78	3.02E+07	mp-997101
TaNiTe₅	Pmma	0	No	\	0	73	3.03E+07	mp-8998
CoSe	P4/nmm	0	No	Co ₃ Se ₄ + Co ₉ Se ₈	16	104	3.04E+07	mp-604908

SUPPORTING INFORMATION

Sr₂MnClO₃	P4/nmm	0	No	\	0	33	3.05E+07	mp-561903
TiBrO	Pmmn	0	No	Ti ₂ O ₃ + TiBr ₃	17	40	3.05E+07	mp-23002
La₂PBr₂	P-3m1	0	No	\	0	51	3.20E+07	mp-570988
TaNi₂TeSe	Pmma	0	No	\	0	51	3.24E+07	mp-622009
NbTe₅Pd	Pmc2_1	0	No	NbTe ₄ + Te ₂ Pd + NbTe ₂	1	83	3.27E+07	mp-28616
Sr₂Cu(BiO₃)₂	Pmna	0	No	SrCuO ₂ + Sr(BiO ₂) ₂	70	37	3.32E+07	mp-555827
TiTe₂	P-3m1	0	No	\	0	110	3.34E+07	mp-1907
Te₂Pd₃Pb₂	Pmmn	0	No	\	0	135	3.34E+07	mp-605028
Ti₂Te₂P	P-3m1	0	No	\	0	57	3.40E+07	mp-12527
Hf₃Te₂	P4/mmm	0	No	\	0	78	3.43E+07	mp-28919
TiNbS₄	P2/m	0	No	TiS ₂ + NbS ₂	23	93	3.44E+07	mp-34289
NbTe₂	P-3m1	0	No	NbTe ₂	47	106	3.47E+07	mp-1018150
TiBr₂	P-3m1	0	No	Ti ₇ Br ₁₆ + Ti	38	61	3.50E+07	mp-27785
TiClO	Pmmn	0	No	Ti ₂ O ₃ + TiCl ₃	15	37	3.55E+07	mp-22992
Ta(NiTe)₂	Pmma	0	No	\	0	54	3.56E+07	mp-28667
Sr₄Mn₃(ClO₄)₂	P4/mmm	0	No	\	0	26	3.59E+07	mp-25033
TiCl₂	P-3m1	0	No	Ti ₇ Cl ₁₆ + Ti	55	90	3.63E+07	mp-28116
EuIO	P4/nmm	0	No	\	0	51	3.73E+07	mp-600622
CeBiS₂O	P4/nmm	0	No	Ce ₄ S ₃ O ₄ + Bi ₂ S ₃ + Bi	62	71	3.74E+07	mp-610469
LiCoAs	P4/nmm	0	No	\	0	157	3.74E+07	mp-20698
TiSCl	Pmmn	0	No	\	0	60	3.99E+07	mp-1013900
Ca₃Cu₂(ClO₂)₂	P4/mmm	0	No	Ca ₄ Cl ₆ O + CaCu ₃ O ₄ + CaO	7	41	4.09E+07	mp-23095
In₃Te₄	P-3m1	0	No	In ₄ Te ₃ + In ₇ Te ₁₀	36	51	4.11E+07	mp-541885
Ca₃Cu₂(BrO₂)₂	P4/mmm	0	No	\	0	26	4.16E+07	mp-545706
Bi₃Se₄	P-3m1	0	No	Bi ₂ Se ₃ + Bi	55	53	4.17E+07	mp-542615
TiOF	Pmmn	0	No	Ti ₂ O ₃ + TiF ₃	71	47	4.27E+07	mp-753059
TmI₂	P-3m1	0	No	TmI ₃ + Tm	50	90	4.34E+07	mp-29671
CuSe	P4/nmm	0	No	CuSe	71	117	4.36E+07	mp-580226
Sc₂NCl₂	P-3m1	0	No	\	0	41	4.39E+07	mp-28480
NiTe	P-3m1	0	No	Ni ₃ Te ₂ + NiTe ₂	43	125	4.56E+07	mp-10264
PtPb₄	P4/nbm	0	No	\	0	185	4.58E+07	mp-21296
Zr₂Te₂P	P-3m1	0	No	\	0	66	4.67E+07	mp-16765
NiTe₂	P-3m1	0	No	\	0	171	4.68E+07	mp-2578
Li₂H₂Pd	P4/mmm	0	No	\	0	109	4.72E+07	mp-644389
PtTe	P-3m1	0	No	\	0	145	4.86E+07	mp-11693
SrCu	P6/mmm	0	No	\	0	180	4.91E+07	mp-1025402
Nb₂CS₂	P-3m1	186	No	Nb ₃ S ₄ + Nb ₆ C ₅ + C	22	54	4.96E+07	mp-4384
ZrSiTe	P4/nmm	0	No	\	0	64	5.12E+07	mp-19917

SUPPORTING INFORMATION

ZrSiSe	P4/nmm	0	No	\	0	84	5.34E+07	mp-4628
OsCl ₂ O	Pmmm	0	No	\	0	67	5.45E+07	mp-29133
HfSiSe	P4/nmm	0	No	\	0	78	5.50E+07	mp-13962
ZrGeTe	P4/nmm	0	No	\	0	71	5.51E+07	mp-3208
RuCl ₂ O	Pmmm	0	No	\	0	64	5.54E+07	mp-29132
Li ₂ H ₂ Pt	P4/mmm	0	No	\	0	108	5.56E+07	mp-644136
YCBr	C2/m	0	No	\	0	34	5.58E+07	mp-643367
SiTe ₂	P-3m1	0	No	Te + Si	53	91	5.63E+07	mp-2755
TbCBr	C2/m	0	No	\	0	39	5.67E+07	mp-1025023
HfSiTe	P4/nmm	0	No	\	0	63	5.69E+07	mp-13963
Ta ₂ CS ₂	P-3m1	22	No	\	0	42	5.94E+07	mp-7814
CeTe ₃	P4/nmm	0	No	\	0	62	6.11E+07	mp-571571
ZrTe ₃	Pmmn	0	No	\	0	95	6.22E+07	mp-2089
LiC ₁₂	P6/mmm	0	No	\	0	38	6.31E+07	mp-1021323
HfTe ₃	Pmmn	0	No	HfTe ₅ + HfTe ₂	25	88	6.54E+07	mp-1025459
CuTe	Pmmn	0	No	\	0	79	9.05E+07	mp-20826
CuAgTe ₂	Pmm2	0	No	Ag ₂ Te + CuTe + Te	70	93	1.16E+08	mp-2977
LaTe ₃	P4/nmm	0	No	\	0	57	1.47E+08	mp-1078612
Nd ₂ Te ₅	P4/nmm	0	No	\	0	29	1.60E+08	mp-1119
PrTe ₃	P4/nmm	0	No	\	0	56	1.60E+08	mp-12351
NdTe ₃	P4/nmm	0	No	\	0	55	1.60E+08	mp-740
SmTe ₃	P4/nmm	0	No	\	0	57	1.64E+08	mp-9399
TbTe ₃	P4/nmm	0	No	\	0	57	1.73E+08	mp-1084847
LuTe ₃	P4/nmm	0	No	Lu ₂ Te ₃ + Te	9	58	1.73E+08	mp-1080689
ErTe ₃	P4/nmm	0	No	\	0	57	1.74E+08	mp-1078991
TmTe ₃	P4/nmm	0	No	\	0	57	1.74E+08	mp-1087512
HoTe ₃	P4/nmm	0	No	\	0	57	1.75E+08	mp-1078508
DyTe ₃	P4/nmm	0	No	\	0	57	1.76E+08	mp-1086673
YTe ₃	P4/nmm	0	No	\	0	61	1.78E+08	mp-945077
PrTe ₂ Se	P4/nmm	0	No	\	0	52	1.87E+08	mp-30125
NdTe ₂ Se	P4/nmm	0	No	\	0	51	1.91E+08	mp-4437
LaTe ₂ Se	P4/nmm	0	No	\	0	44	2.09E+08	mp-4034

SUPPORTING INFORMATION

Table S3. Computed free energy of reaction species (with consideration of the effect of solvation), including $\Delta G(\text{OOH}^*)$, $\Delta G(\text{O}^*)$, and $\Delta G(\text{OH}^*)$, theoretical limiting potential (U_L) and potential limiting step (PDS) for the ORR and OER on the 242 possible sites in the 199 candidate materials which screened from catalytic selectivity analysis.

Formula	$\Delta G(\text{OOH}^*)$	$\Delta G(\text{O}^*)$	$\Delta G(\text{OH}^*)$	PDS-ORR	$U_L(\text{ORR})$	PDS-OER	$U_L(\text{OER})$
NbTe₂	3.95	2.00	0.66	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.66	$\text{OOH}^* \leftrightarrow \text{O}^*$	1.96
HfSiSe	3.94	1.34	0.48	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.48	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.60
HfTe₅_1	4.59	1.47	1.40	$\text{O}^* \leftrightarrow \text{OH}^*$	0.06	$\text{OOH}^* \leftrightarrow \text{O}^*$	3.12
HfTe₅_2	4.87	1.86	1.60	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.05	$\text{OOH}^* \leftrightarrow \text{O}^*$	3.02
Nb₂PdS₆_1	4.49	1.86	1.17	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.43	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.64
Nb₂PdS₆_2	4.61	1.97	1.64	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.31	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.65
TiTe₂	4.66	1.47	1.35	$\text{O}^* \leftrightarrow \text{OH}^*$	0.13	$\text{OOH}^* \leftrightarrow \text{O}^*$	3.19
TiSe₂	4.64	1.81	1.55	$\text{O}^* \leftrightarrow \text{OH}^*$	0.26	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.83
Ta₂NiS₅	4.73	2003	1.60	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.19	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.70
Ta₂Te₃	4.67	1.69	1.62	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.08	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.97
TaSe₃	4.44	2.08	1.26	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.48	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.36
NbNiTe₅	4.39	1.73	1.39	$\text{O}^* \leftrightarrow \text{OH}^*$	0.34	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.66
ZrSiSe	4.12	1.58	0.71	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.71	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.54
TaNiTe₅	4.49	1.58	1.33	$\text{O}^* \leftrightarrow \text{OH}^*$	0.26	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.91
Ta₂NiSe₅	4.85	2.02	1.58	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.07	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.83
TaS₃	4.63	2.07	1.83	$\text{O}^* \leftrightarrow \text{OH}^*$	0.24	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.56
ZrGeTe	4.02	1.18	0.59	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.59	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.84
FeSe	4.17	1.65	0.49	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.49	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.52
FeS	4.67	1.53	1.43	$\text{O}^* \leftrightarrow \text{OH}^*$	0.11	$\text{OOH}^* \leftrightarrow \text{O}^*$	3.14
NbCrSe₅	4.38	1.75	0.76	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.54	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.63
TaS₂	4.12	1.65	0.70	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.70	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.48
NbS₂	3.95	1.55	0.57	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.57	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.40
NbCoTe₂	4.28	1.64	1.13	$\text{O}^* \leftrightarrow \text{OH}^*$	0.51	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.64
Nb₃IrSe₈	4.25	1.74	1.22	$\text{O}^* \leftrightarrow \text{OH}^*$	0.51	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.51
VTe₂	3.85	1.93	0.57	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.57	$\text{OOH}^* \leftrightarrow \text{O}^*$	1.92
Te₂Pd₃Pb₂	3.70	1.97	0.50	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.50	$\text{OOH}^* \leftrightarrow \text{O}^*$	1.73
CoSe	4.38	1.93	1.23	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.54	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.45
TaTe₂	3.55	1.77	0.29	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.29	$\text{OOH}^* \leftrightarrow \text{O}^*$	1.79
Te₂Mo	4.09	1.95	0.82	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.82	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.13
VTe₂	3.09	1.07	-0.10	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	-0.10	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.02
ScCl	5.09	1.63	2.42	$\text{O}^* \leftrightarrow \text{OH}^*$	-0.78	$\text{OOH}^* \leftrightarrow \text{O}^*$	3.46
TiNbS₄	4.54	1.74	1.34	$\text{O}_2 \leftrightarrow \text{OOH}^*$	0.38	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.80
TaFeTe₃	4.07	1.34	0.76	$\text{OH}^* \leftrightarrow \text{H}_2\text{O}$	0.58	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.73
Nb₃IrS₈_1	4.44	1.50	1.09	$\text{O}^* \leftrightarrow \text{OH}^*$	0.42	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.94
Nb₃IrS₈_2	4.53	1.60	1.50	$\text{O}^* \leftrightarrow \text{OH}^*$	0.10	$\text{OOH}^* \leftrightarrow \text{O}^*$	2.93
MnSe	4.70	1.54	1.58	$\text{O}^* \leftrightarrow \text{OH}^*$	-0.04	$\text{OOH}^* \leftrightarrow \text{O}^*$	3.16

SUPPORTING INFORMATION

Mn(InSe₂)₂_1	3.34	0.45	0.63	O*↔OH*	-0.18	OOH*↔O*	2.89
Mn(InSe₂)₂_2	4.27	1.84	1.12	O ₂ ↔OOH*	0.65	OOH*↔O*	2.43
TePt	4.02	1.83	0.80	OH*↔H ₂ O	0.80	OOH*↔O*	2.20
NiTe	4.09	2.00	0.88	O ₂ ↔OOH*	0.83	OOH*↔O*	2.09
Mn₂Ga₂S₅	4.84	1.94	2.58	O*↔OH*	-0.64	OOH*↔O*	2.90
SiTe₂	4.46	1.99	1.20	O ₂ ↔OOH*	0.46	OOH*↔O*	2.47
PtPb₄_1	3.68	1.28	0.47	OH*↔H ₂ O	0.47	OOH*↔O*	2.40
PtPb₄_2	3.65	1.83	0.65	OH*↔H ₂ O	0.65	OOH*↔O*	1.82
NiTe₂	4.01	1.60	0.76	OH*↔H ₂ O	0.76	OOH*↔O*	2.41
Fe₄S₅	3.93	1.83	0.70	OH*↔H ₂ O	0.70	OOH*↔O*	2.10
CoTe₂	3.49	1.02	0.04	OH*↔H ₂ O	0.04	OOH*↔O*	2.47
CeBiS₂O	3.20	0.98	-0.13	OH*↔H ₂ O	-0.13	OOH*↔O*	2.21
Cr(GaS₂)₂	3.53	1.15	0.12	OH*↔H ₂ O	0.12	OOH*↔O*	2.39
KFe₂Se₃	3.86	0.90	0.64	O*↔OH*	0.25	OOH*↔O*	2.96
Bi₉I₂_1	3.87	1.22	0.69	O*↔OH*	0.53	OOH*↔O*	2.65
Bi₉I₂_2	3.79	1.83	0.62	OH*↔H ₂ O	0.62	OOH*↔O*	1.96
LiCu₂(CO₃)₂	2.59	1.57	-0.53	OH*↔H ₂ O	-0.53	O ₂ ↔OOH*	2.33
CuAgTe₂_1	3.73	1.44	0.35	OH*↔H ₂ O	0.35	OOH*↔O*	2.29
CuAgTe₂_2	3.70	1.50	0.37	OH*↔H ₂ O	0.37	OOH*↔O*	2.19
CuSe	4.42	1.98	1.23	O ₂ ↔OOH*	0.50	OOH*↔O*	2.44
Na₂HfN₂	2.00	1.42	-1.20	OH*↔H ₂ O	-1.20	O ₂ ↔OOH*	2.92
Bi₄I_1	3.84	1.83	0.67	OH*↔H ₂ O	0.67	OOH*↔O*	2.01
Bi₄I_2	3.95	1.92	0.82	OH*↔H ₂ O	0.82	OOH*↔O*	2.02
VCl₃	4.81	2.10	3.03	O*↔OH*	-0.94	OOH*↔O*	2.72
TaCoTe₂	4.38	1.58	1.25	O*↔OH*	0.33	OOH*↔O*	2.80
ZrTe₅_1	4.55	1.60	1.40	O*↔OH*	0.20	OOH*↔O*	2.95
ZrTe₅_2	4.86	1.86	1.68	O ₂ ↔OOH*	0.06	OOH*↔O*	3.00
TaTe₄Ir	4.36	1.91	1.16	O ₂ ↔OOH*	0.56	OOH*↔O*	2.44
TiS₂	4.71	1.90	1.36	O ₂ ↔OOH*	0.21	OOH*↔O*	2.80
VS₂	4.37	1.65	0.91	O ₂ ↔OOH*	0.55	OOH*↔O*	2.72
NbTe₄Ir	4.41	1.98	1.21	O ₂ ↔OOH*	0.51	OOH*↔O*	2.43
LiNi(PS₃)₂	4.31	1.72	0.99	O ₂ ↔OOH*	0.61	OOH*↔O*	2.60
SrSbSe₂F	4.24	1.60	1.04	O*↔OH*	0.57	OOH*↔O*	2.63
Te₂W	4.33	1.97	0.93	O ₂ ↔OOH*	0.59	OOH*↔O*	2.36
VAg(PSe₃)₂	3.92	1.34	0.60	OH*↔H ₂ O	0.60	OOH*↔O*	2.58
Ta₂PdS₆	4.76	1.99	1.42	O ₂ ↔OOH*	0.16	OOH*↔O*	2.76
TiS₃	4.72	1.80	1.83	O*↔OH*	-0.03	OOH*↔O*	2.91
Ge₅(Te₄As)₂	4.24	1.73	1.04	O ₂ ↔OOH*	0.68	OOH*↔O*	2.50
Pr₂Br₅_1	2.66	0.57	-0.89	OH*↔H ₂ O	-0.89	O ₂ ↔OOH*	2.26
Pr₂Br₅_2	3.29	1.28	-0.28	OH*↔H ₂ O	-0.28	OOH*↔O*	2.01
Pr₂Br₅_3	3.66	1.87	0.22	OH*↔H ₂ O	0.22	OOH*↔O*	1.79
Pr₂Br₅_4	3.73	1.06	-0.16	OH*↔H ₂ O	-0.16	OOH*↔O*	2.67
HfSe₃	4.76	1.69	1.63	O*↔OH*	0.05	OOH*↔O*	3.07

SUPPORTING INFORMATION

NbS₃	4.70	2.04	1.52	O ₂ ↔OOH*	0.22	OOH*↔O*	2.65
Ge₄Te₇As₂	4.32	1.83	1.17	O ₂ ↔OOH*	0.60	OOH*↔O*	2.49
ZrSe₃	4.78	1.75	1.21	O ₂ ↔OOH*	0.14	OOH*↔O*	3.03
ZrSe₂	4.76	1.75	1.34	O ₂ ↔OOH*	0.16	OOH*↔O*	3.01
CuBrO₂	4.30	1.69	1.79	O*↔OH*	-0.09	OOH*↔O*	2.61
In₂Se₃	4.35	1.51	1.09	O*↔OH*	0.42	OOH*↔O*	2.83
Ti₂Te₂P	4.67	1.82	1.35	O ₂ ↔OOH*	0.25	OOH*↔O*	2.85
Zr₂Te₂P	4.77	1.74	1.55	O ₂ ↔OOH*	0.15	OOH*↔O*	3.02
Ta₂Te₅Pd₃_1	4.20	1.64	1.05	O*↔OH*	0.59	OOH*↔O*	2.55
Ta₂Te₅Pd₃_2	4.70	2.44	1.36	O ₂ ↔OOH*	0.22	OOH*↔O*	2.25
Ta₄AgS₈	4.48	1.94	1.14	O ₂ ↔OOH*	0.44	OOH*↔O*	2.54
Ag(TeMo)₆	4.40	1.62	1.20	O*↔OH*	0.42	OOH*↔O*	2.78
Ta₃SiTe₆	4.61	1.57	1.42	O*↔OH*	0.15	OOH*↔O*	3.04
NbSe₂	4.12	2.13	0.83	O ₂ ↔OOH*	0.80	OOH*↔O*	1.99
BiTe	4.28	1.78	1.09	O ₂ ↔OOH*	0.64	OOH*↔O*	2.50
Ta₃Te₁₄Pd₃_1	4.26	1.78	1.10	O ₂ ↔OOH*	0.66	OOH*↔O*	2.48
Ta₃Te₁₄Pd₃_2	4.16	1.81	1.15	O ₂ ↔OOH*	0.76	OOH*↔O*	2.35
Ta₃Te₁₄Pd₃_3	4.28	1.93	1.06	O ₂ ↔OOH*	0.64	OOH*↔O*	2.35
Nb₃SiTe₆	4.58	1.85	1.40	O ₂ ↔OOH*	0.34	OOH*↔O*	2.73
Nb₃GeTe₆	4.51	1.27	1.24	O*↔OH*	0.03	OOH*↔O*	3.24
Bi₂Rh₃S₂	3.76	1.73	0.53	OH*↔H ₂ O	0.53	OOH*↔O*	2.03
Ge₃(BiTe₃)₂	4.64	1.34	1.45	O*↔OH*	-0.11	OOH*↔O*	3.30
Nb₄IrSe₁₀_1	4.29	1.21	1.61	O*↔OH*	-0.40	OOH*↔O*	3.08
Nb₄IrSe₁₀_2	4.26	2.26	1.43	O ₂ ↔OOH*	0.66	OOH*↔O*	2.00
Nb₄IrSe₁₀_3	4.85	2.55	1.45	O ₂ ↔OOH*	0.07	OOH*↔O*	2.60
KFe₂S₃	3.96	0.97	0.88	O*↔OH*	0.09	OOH*↔O*	2.98
Nb₉IrSe₂₀_1	4.55	2.02	1.40	O ₂ ↔OOH*	0.37	OOH*↔O*	2.53
Nb₉IrSe₂₀_2	4.80	2.31	1.85	O ₂ ↔OOH*	0.12	OOH*↔O*	2.48
Nb₉IrSe₂₀_3	4.19	2.27	0.93	O ₂ ↔OOH*	0.73	OOH*↔O*	1.91
CeZnPO	3.12	1.22	0.04	OH*↔H ₂ O	0.04	OOH*↔O*	1.90
Bi₃Se₄	3.61	1.70	0.32	OH*↔H ₂ O	0.32	OOH*↔O*	1.91
Bi₂Te₅Pb₂	4.59	1.78	1.24	O ₂ ↔OOH*	0.33	OOH*↔O*	2.80
Na₂ZrN₂	1.97	1.30	-1.19	OH*↔H ₂ O	-1.19	O ₂ ↔OOH*	2.95
CuTeO₃	4.17	2.06	0.94	O*↔OH*	0.75	OOH*↔O*	2.11
TiFeTe₆_1	4.85	1.70	1.63	O*↔OH*	0.07	OOH*↔O*	3.14
TiFeTe₆_2	4.67	1.82	1.57	O*↔OH*	0.24	OOH*↔O*	2.86
TiFeTe₆_3	4.53	1.96	1.28	O ₂ ↔OOH*	0.39	OOH*↔O*	2.57
TiFeTe₆_4	4.39	2.10	1.07	O ₂ ↔OOH*	0.53	OOH*↔O*	2.29
TbTe₃	4.77	2.61	2.09	O ₂ ↔OOH*	0.15	OOH*↔O*	2.16
PrTe₃	4.81	2.52	1.98	O ₂ ↔OOH*	0.11	OOH*↔O*	2.29
Nd₂Te₅	4.79	2.47	1.66	O ₂ ↔OOH*	0.13	OOH*↔O*	2.32
TbGal	4.24	2.71	0.85	O ₂ ↔OOH*	0.68	O*↔OH*	1.85
HfSiTe	4.19	0.70	0.79	O*↔OH*	-0.09	OOH*↔O*	3.48

SUPPORTING INFORMATION

HoTe₃	4.70	2.62	1.66	O ₂ ↔OOH*	0.22	OOH*↔O*	2.08
LiC₁₂	4.53	2.14	1.18	O ₂ ↔OOH*	0.39	OOH*↔O*	2.39
TaNiTe₂	4.63	2.24	1.29	O ₂ ↔OOH*	0.29	OOH*↔O*	2.39
ZrCl	4.77	2.34	1.62	O ₂ ↔OOH*	0.15	OOH*↔O*	2.43
ZrSiTe	4.28	0.96	0.93	O*↔OH*	0.03	OOH*↔O*	3.32
CuTe	4.43	2.21	1.31	O ₂ ↔OOH*	0.49	OOH*↔O*	2.22
NdI₂	3.76	0.11	0.29	OH*↔H ₂ O	-0.18	OOH*↔O*	3.65
Ta₂Se	3.54	0.94	0.35	OH*↔H ₂ O	0.35	OOH*↔O*	2.60
NdTe₃	4.49	2.55	2.01	O ₂ ↔OOH*	0.13	OOH*↔O*	2.24
NbSe₃	4.73	2.55	1.78	O ₂ ↔OOH*	0.19	OOH*↔O*	2.17
TaNi₂TeSe	4.73	2.64	1.29	O ₂ ↔OOH*	0.19	OOH*↔O*	2.09
SmTe₃	4.79	2.59	2.07	O ₂ ↔OOH*	0.13	OOH*↔O*	2.20
HfTe₂	4.81	0.24	1.05	O*↔OH*	-0.81	OOH*↔O*	4.57
La₂Pl₂	4.28	2.37	0.87	O ₂ ↔OOH*	0.64	OOH*↔O*	1.91
NdTe₂Se	4.75	2.46	1.44	O ₂ ↔OOH*	0.17	OOH*↔O*	2.29
Ca(TiS₂)₈	4.72	2.16	1.38	O ₂ ↔OOH*	0.20	OOH*↔O*	2.56
VSe₂	4.86	2.25	0.94	O ₂ ↔OOH*	0.06	OOH*↔O*	2.61
PrTe₂Se	4.76	2.44	1.42	O ₂ ↔OOH*	0.16	OOH*↔O*	2.32
CrS₂	2.58	0.09	-0.66	OH*↔H ₂ O	-0.66	OOH*↔O*	2.49
YTe₃	4.76	2.60	1.64	O ₂ ↔OOH*	0.16	OOH*↔O*	2.15
EuBrO	3.74	1.92	1.88	O*↔OH*	0.04	OH*↔H ₂ O	1.88
TaNi₂Te₃	4.58	1.17	1.48	O*↔OH*	-0.31	OOH*↔O*	3.41
Ta(NiTe)₂	4.62	2.71	1.46	O ₂ ↔OOH*	0.30	OOH*↔O*	1.91
ErTe₃	4.75	2.61	1.50	O ₂ ↔OOH*	0.17	OOH*↔O*	2.13
TaTe₅Pt_1	4.48	2.24	1.23	O ₂ ↔OOH*	0.44	OOH*↔O*	2.23
TaTe₅Pt_2	4.81	2.28	1.48	O ₂ ↔OOH*	0.11	OOH*↔O*	2.53
LaTe₃	4.61	2.47	1.88	O ₂ ↔OOH*	0.31	OOH*↔O*	2.14
LaTe₂Se	4.56	2.39	1.30	O ₂ ↔OOH*	0.36	OOH*↔O*	2.17
CeTe₃	4.96	2.65	1.45	O ₂ ↔OOH*	-0.04	OOH*↔O*	2.30
NbTe₅Pd_1	4.47	2.15	1.14	O ₂ ↔OOH*	0.45	OOH*↔O*	2.32
NbTe₅Pd_2	4.44	2.22	1.53	O ₂ ↔OOH*	0.48	OOH*↔O*	2.22
TiBr₃	4.04	0.27	0.81	O*↔OH*	-0.53	OOH*↔O*	3.76
TaSe₂	4.18	2.17	0.90	O ₂ ↔OOH*	0.74	OOH*↔O*	2.01
TiCl₃	4.94	0.20	0.30	O*↔OH*	-0.10	OOH*↔O*	4.74
ZrTe₃	4.64	1.27	1.17	O*↔OH*	0.10	OOH*↔O*	3.37
AuSe	4.80	2.57	1.81	O ₂ ↔OOH*	0.12	OOH*↔O*	2.23
TbBr	4.03	2.18	0.56	OH*↔H ₂ O	0.56	OOH*↔O*	1.85
TaTe₂	3.79	0.49	0.57	O*↔OH*	-0.09	OOH*↔O*	3.30
CoI₂	3.48	0.67	0.49	O*↔OH*	0.18	OOH*↔O*	2.81
CuSeO₃	4.84	2.60	1.58	O ₂ ↔OOH*	0.08	OOH*↔O*	2.23
VTe₂	3.09	1.07	-0.10	OH*↔H ₂ O	-0.10	OOH*↔O*	2.02
HfTe₃	4.54	1.02	0.86	O*↔OH*	0.16	OOH*↔O*	3.52
ZrTiTe₄	4.67	0.34	1.36	O*↔OH*	-1.02	OOH*↔O*	4.33

SUPPORTING INFORMATION

NbFeTe₂	3.64	0.68	0.35	O*↔OH*	0.33	OOH*↔O*	2.96
Li₂H₂Pt	2.12	0.27	-0.80	OH*↔H ₂ O	-0.80	O ₂ ↔OOH*	2.80
VAg(PS₃)₂	4.27	0.89	0.74	O*↔OH*	0.15	OOH*↔O*	3.38
Nb₂Te₃_1	3.23	0.17	0.04	OH*↔H ₂ O	0.04	OOH*↔O*	3.06
Nb₂Te₃_2	4.77	2.34	1.67	O ₂ ↔OOH*	0.15	OOH*↔O*	2.43
AgHO₂	3.70	2.38	1.21	O*↔OH*	1.17	OOH*↔O*	1.32
NbTe₂	2.19	0.32	-0.39	OH*↔H ₂ O	-0.39	O ₂ ↔OOH*	2.73
KV₄O₁₀	2.90	1.25	-0.26	OH*↔H ₂ O	-0.26	O ₂ ↔OOH*	2.02
TmI₂	2.84	0.60	-0.58	OH*↔H ₂ O	-0.58	OOH*↔O*	2.24
Ga₂NiS₄	4.75	2.43	2.17	O ₂ ↔OOH*	0.17	OOH*↔O*	2.32
LiCoAs	2.63	0.04	-0.63	OH*↔H ₂ O	-0.63	OOH*↔O*	2.59
V₆O₁₃	3.71	0.72	0.38	O*↔OH*	0.34	OOH*↔O*	2.99
NiPSe₃	3.61	0.21	0.32	O*↔OH*	-0.11	OOH*↔O*	3.40
Ag(AuS)₂_1	4.13	0.91	0.30	OH*↔H ₂ O	0.30	OOH*↔O*	3.21
Ag(AuS)₂_2	4.16	2.34	.01	O ₂ ↔OOH*	0.76	OOH*↔O*	1.82
CuSi₂P₃_1	3.13	0.25	-0.25	OH*↔H ₂ O	-0.25	OOH*↔O*	2.88
CuSi₂P₃_2	4.44	0.66	0.88	O*↔OH*	-0.21	OOH*↔O*	3.78
Cr₃Te₄	4.64	0.96	1.34	O*↔OH*	-0.39	OOH*↔O*	3.68
Nb₂Se₃_1	3.02	0.11	-0.11	OH*↔H ₂ O	-0.11	OOH*↔O*	2.91
Nb₂Se₃_2	4.59	2.71	1.45	O ₂ ↔OOH*	0.33	OOH*↔O*	1.88
Ta₂PtSe₇_1	4.75	2.05	2.13	O*↔OH*	-0.08	OOH*↔O*	2.70
Ta₂PtSe₇_2	4.58	2.42	1.49	O ₂ ↔OOH*	0.34	OOH*↔O*	2.17
Ta₂PtSe₇_3	4.90	2.12	1.64	O ₂ ↔OOH*	0.02	OOH*↔O*	2.78
Ta₂CS₂	4.81	2.28	1.88	O ₂ ↔OOH*	0.11	OOH*↔O*	2.53
Cel₃_1	3.26	0.53	0.07	OH*↔H ₂ O	0.07	OOH*↔O*	2.73
Cel₃_2	3.29	1.44	0.79	O*↔OH*	0.65	OOH*↔O*	1.85
TiIN	4.73	2.33	2.70	O*↔OH*	-0.37	OH*↔H ₂ O	2.70
CrP₂S₇	4.29	0.85	0.54	O*↔OH*	0.31	OOH*↔O*	3.44
FeBr₃	4.80	2.63	1.80	O ₂ ↔OOH*	0.12	OOH*↔O*	2.16
CoBr₂	4.87	2.55	2.35	O ₂ ↔OOH*	0.05	OH*↔H ₂ O	2.35
NiPS₃	3.86	0.99	0.55	OH*↔H ₂ O	0.44	OOH*↔O*	2.87
MnSbSe₂I	4.06	1.25	0.63	O*↔OH*	0.62	OOH*↔O*	2.81
Ta₂PdSe₆_1	4.67	2.51	1.43	O ₂ ↔OOH*	0.25	OOH*↔O*	2.16
Ta₂PdSe₆_2	4.86	2.58	1.77	O ₂ ↔OOH*	0.06	OOH*↔O*	2.28
HfFeCl₆	2.40	2.18	0.24	OH*↔H ₂ O	0.24	OOH*↔O*	2.22
MnSbSe₂Br	3.50	0.36	-0.19	OH*↔H ₂ O	-0.19	OOH*↔O*	3.13
MoCl₃	3.99	0.77	1.75	O*↔OH*	-0.98	OOH*↔O*	3.22
CuSeSe₂	3.70	0.71	0.07	OH*↔H ₂ O	0.07	OOH*↔O*	2.99
TaSe₂	4.74	2.14	1.61	O ₂ ↔OOH*	0.17	OOH*↔O*	2.61
Crl₂	4.79	1.32	1.94	O*↔OH*	-0.62	OOH*↔O*	3.47
CrTe₃_1	4.40	1.68	2.74	O*↔OH*	-1.06	OH*↔H ₂ O	2.74
CrTe₃_2	4.34	2.35	1.20	O ₂ ↔OOH*	0.58	OOH*↔O*	1.99
Rb₂O	2.84	2.60	-0.17	OH*↔H ₂ O	-0.17	OOH*↔O*	2.77

SUPPORTING INFORMATION

CuSbS₂	3.80	0.85	0.12	OH* \leftrightarrow H ₂ O	0.12	OOH* \leftrightarrow O*	2.95
CrPO₅	4.67	2.74	2.78	O* \leftrightarrow OH*	-0.04	OH* \leftrightarrow H ₂ O	2.78
Sc₆C₂I₁₁	3.01	1.18	-0.44	OH* \leftrightarrow H ₂ O	-0.44	O ₂ \leftrightarrow OOH*	1.91
K₂As₂Pd	3.05	0.94	-0.07	OH* \leftrightarrow H ₂ O	-0.07	OOH* \leftrightarrow O*	2.11
Nb₂GeTe₄	4.87	2.74	1.67	O ₂ \leftrightarrow OOH*	0.05	OOH* \leftrightarrow O*	2.13
ZrI₂	4.74	0.34	2.27	O ₂ \leftrightarrow OOH*	-1.93	OOH* \leftrightarrow O*	4.40
MnPSe₃	3.86	1.24	0.58	OH* \leftrightarrow H ₂ O	0.58	OOH* \leftrightarrow O*	2.62
PdSeO₃	4.90	2.76	1.31	O ₂ \leftrightarrow OOH*	0.02	OOH* \leftrightarrow O*	2.13
CrGeTe₃	4.10	2.45	0.86	O ₂ \leftrightarrow OOH*	0.82	OOH* \leftrightarrow O*	1.64
DyTe₃	4.72	2.6	1.65	O ₂ \leftrightarrow OOH*	0.20	OOH* \leftrightarrow O*	2.11
LuTe₃	4.70	2.59	1.57	O ₂ \leftrightarrow OOH*	0.22	OOH* \leftrightarrow O*	2.11
Na₃(TiS₂)₁₀	4.75	2.17	1.39	O ₂ \leftrightarrow OOH*	0.17	OOH* \leftrightarrow O*	2.58
BiSe	3.96	2.70	0.68	OH* \leftrightarrow H ₂ O	0.68	O* \leftrightarrow OH*	2.02
Ta₂Se₃	2.84	0.87	0.47	O* \leftrightarrow OH*	0.39	O ₂ \leftrightarrow OOH*	2.08
In₃Te₄	4.59	2.52	1.28	O ₂ \leftrightarrow OOH*	0.33	OOH* \leftrightarrow O*	2.07
GdBr	4.19	1.91	0.61	OH* \leftrightarrow H ₂ O	0.61	OOH* \leftrightarrow O*	2.29
Li₂Cr₃(CO₃)₆_1	4.46	2.68	1.98	O ₂ \leftrightarrow OOH*	0.46	OH* \leftrightarrow H ₂ O	1.98
Li₂Cr₃(CO₃)₆_2	4.47	2.68	3.03	O* \leftrightarrow OH*	-0.35	OH* \leftrightarrow H ₂ O	3.03
Zn(InS₂)₂_1	4.36	2.22	0.67	O ₂ \leftrightarrow OOH*	0.56	OOH* \leftrightarrow O*	2.15
Zn(InS₂)₂_2	4.41	2.54	1.10	O ₂ \leftrightarrow OOH*	0.51	OOH* \leftrightarrow O*	1.87
Ta₄Co₂PdSe₁₂_1	4.83	2.28	1.81	O ₂ \leftrightarrow OOH*	0.09	OOH* \leftrightarrow O*	2.54
Ta₄Co₂PdSe₁₂_2	4.85	2.28	2.04	O ₂ \leftrightarrow OOH*	0.07	OOH* \leftrightarrow O*	2.57
Ta₄Co₂PdSe₁₂_3	4.69	2.71	1.80	O ₂ \leftrightarrow OOH*	0.23	OOH* \leftrightarrow O*	1.98
CuH₂(SeO₃)₂	4.20	2.50	1.77	O ₂ \leftrightarrow OOH*	0.72	OH* \leftrightarrow H ₂ O	1.77
Li₂Cu₂F₅_1	4.33	2.18	0.31	OH* \leftrightarrow H ₂ O	0.31	OOH* \leftrightarrow O*	2.14
Li₂Cu₂F₅_2	4.11	2.38	0.53	OH* \leftrightarrow H ₂ O	0.53	OOH* \leftrightarrow O*	1.73
V₂P₄S₁₃_1	3.45	0.56	-0.11	OH* \leftrightarrow H ₂ O	-0.11	OOH* \leftrightarrow O*	2.90
V₂P₄S₁₃_2	4.87	0.91	1.78	O* \leftrightarrow OH*	-0.87	OOH* \leftrightarrow O*	3.96
V₂P₄S₁₃_3	4.23	0.77	0.99	O* \leftrightarrow OH*	-0.2	OOH* \leftrightarrow O*	3.45
V₂P₄S₁₃_4	4.88	0.91	1.68	O* \leftrightarrow OH*	-0.77	OOH* \leftrightarrow O*	3.96
V₂P₄S₁₃_5	4.88	0.68	1.57	O* \leftrightarrow OH*	-0.89	OOH* \leftrightarrow O*	4.20
V₂P₄S₁₃_6	3.46	0.56	-0.10	OH* \leftrightarrow H ₂ O	-0.10	OOH* \leftrightarrow O*	2.90
CuSeO₃	4.13	2.12	1.13	O ₂ \leftrightarrow OOH*	0.79	OOH* \leftrightarrow O*	2.01
Nb₃I₈	4.75	2.03	1.92	O* \leftrightarrow OH*	0.11	OOH* \leftrightarrow O*	2.72

SUPPORTING INFORMATION

Table S4. Computed adsorption free energy of O* and H₂O₂* on the 25 candidate material surfaces. A solvation correction of -0.27 eV was included into H₂O₂ adsorption according to the previous study.²⁸

Material	ΔG (O*, eV)	ΔG (H ₂ O ₂ *, eV)
ZrSiSe	1.58	3.52
TaSe ₂	2.17	3.80
NbSe ₂	2.13	3.79
Fe ₄ S ₅	1.83	3.85
BiSe	2.70	3.66
TaS ₂	1.65	3.77
Nb ₉ IrSe ₂₀	2.02	3.77
Nb ₄ IrSe ₁₀	2.26	3.53
Mn(InSe ₂) ₂	1.84	3.75
NbTe ₂	2.00	3.68
BiTe	1.78	3.72
NiTe	2.00	3.77
Ge ₄ Te ₇ As ₂	1.83	3.51
MoTe ₂	1.95	3.66
Ge ₅ (Te ₄ As) ₂	1.73	3.31
PtTe	1.83	3.79
LiNi(PS ₃) ₂	1.72	3.60
Bi ₉ I ₂	1.83	3.47
CuH ₂ (SeO ₃) ₂	2.50	3.36
AgHO ₂	2.38	2.46
CuTeO ₃	2.06	3.04
Bi ₄ I	1.92	3.61
PtPb ₄	1.83	3.63
CuSeO ₃	2.12	3.11
TaTe ₂	1.77	3.36

SUPPORTING INFORMATION

Table S5. The space group (SG), the lattice constants (a, and b in Å, α, β, and γ in °), and the MP material-id (mp-id) for all 47 materials which exhibit the basal plane activity for oxygen electrocatalysis from the screening. The Publications related to the experimental available compounds are also given.

Formula	mp-id	Crystal System	Space Group	a	b	α	β	γ	Reference for material synthesis
VAg(PSe ₃) ₂	mp-6543	monoclinic	C2	6.35	6.36	90.00	90.00	60.05	Materials Research Bulletin 1988, 23 1199-1209
MnSbSe ₂ I	mp-570268	monoclinic	C2/m	3.90	10.53	90.00	90.00	90.00	Solid State Sciences 2006, 8, 652-699
CuSeO ₃	mp-22688	orthorhombic	Pbca	4.59	10.27	90.00	90.00	92.51	Crystalline Materials, 1986, 175, 61-72
Bi ₄ I	mp-583234	monoclinic	C2/m	4.43	13.25	90.00	90.00	90.00	Eur. J. Inorg. Chem., 2008: 5196-5202.
CuTeO ₃	mp-558696	monoclinic	P21/c	7.33	8.64	90.00	90.42	90.00	Journal of Solid State Chemistry, 1987, 291-295
Bi ₉ I ₂	mp-28149	monoclinic	P21/m	4.44	13.28	90.00	90.00	90.00	Doklady Akademii Nauk SSSR 1990, 310, 117-120
NiTe ₂	mp-2578	trigonal	P3m1	3.71	3.71	90.00	90.00	120.00	Bull. Soc. Chim. Belges, 1971, 80, 107-116.
LiNi(PS ₃) ₂	mp-557500	monoclinic	C2	5.82	5.84	90.00	90.00	60.14	Solid State Ionics 1984, 14, 45-49
Ta ₃ Te ₁₄ Pd ₃	mp-505132	monoclinic	P21/m	3.74	21.80	90.00	90.00	90.00	Journal of Solid State Chemistry 1989, 78, 7-16

SUPPORTING INFORMATION

PtTe	mp-11693	trigonal	R-3m	3.92	3.92	90.00	90.00	60.00	Journal of the Less Common Metals 1969, 19, 121-140; Nano Res. 2021, 14, 1663–1667
Ge₅(Te₄As)₂	mp-28487	trigonal	P3m1	4.16	4.16	90.00	90.00	120.00	Acta Cryst. 1987, 43, 2268-2270
MoTe₂	mp-7459	monoclinic	P21/m	3.40	6.35	90.00	90.00	90.00	Acta Cryst. 1966, 20, 268-274
Ge₄Te₇As₂	mp- 568730	trigonal	R3m	4.15	4.15	90.00	90.00	60.00	Journal of Solid State Chemistry 1988, 74, 277-286
NiTe	mp-10264	trigonal	R-3m	3.78	3.78	90.00	90.00	60.00	Sov. Phys. Crystallogr 1964, 8, 448-451
BiTe	mp-23224	trigonal	P3m1	4.43	4.43	90.00	90.00	120.00	Acta Cryst. 1979, 35, 147-149
NbTe₂	mp-11675	monoclinic	C2/m	3.43	9.79	90.00	90.00	79.90	Sci. Rep. 2018, 8, 16984
Mn(InSe₂)₂	mp- 1078140	trigonal	R3m	4.10	4.10	90.00	90.00	60.00	Phys. Stat. Sol. A, 1991, 126, 237-244
Nb₄IrSe₁₀	mp- 675326	triclinic	P1	6.01	9.12	90.00	90.00	72.31	N/A
TaS₂	mp-1984	hexagonal	P63/mmc	3.33	3.33	90.00	90.00	120.00	Acta Cryst. 1990, 46, 1598-1599
BiSe	mp-27902	trigonal	P3m1	4.22	4.22	90.00	90.00	120.00	Journal of Structural Chemistry 1967, 8, 584–589

SUPPORTING INFORMATION

Fe₄S₅	mp-850083	tetragonal	P4	7.88	7.88	90.00	90.00	90.00	N/A
NbSe₂	mp-7597	trigonal	R3m	3.45	3.45	90.00	90.00	60.00	Journal of Solid State Chemistry 1972, 4, 425-429
TaSe₂	mp-542495	triclinic	P1	3.46	3.46	90.00	90.00	120.00	Physica B+C 1980, 99, 51-55
ZrSiSe	mp-4628	tetragonal	P4/nmm	3.52	3.52	90.00	90.00	90.00	Recl. Trav. Chim. Pays-Bas 1964, 83, 776-783
GdBr	mp-1064427	trigonal	P3m1	3.78	3.78	90.00	90.00	120.00	N/A
Sc₆C₂I₁₁	mp-541102	triclinic	P1	9.05	16.16	90.00	90.00	83.11	N/A
Li₂Cu₂F₅	mp-762270	orthorhombic	Pnma	2.81	7.36	90.00	90.00	90.00	N/A
Pd₃Pb₂Te₂	mp-605028	orthorhombic	Pmmn	5.83	8.62	90.00	90.00	90.00	Canadian Mineralogist 2009, 47, 53–62.
Zn(InS₂)₂	mp-22253	trigonal	P3m1	3.89	3.89	90.00	90.00	120.00	J. Am. Chem. Soc. 2017, 139, 22, 7586–7594
Ta(NiTe)₂	mp-28667	orthorhombic	Pnma	3.51	6.44	90.00	90.00	90.00	Angew. Chem. Int. Ed. 1992, 31: 217–220
VTe₂	mp-11687	monoclinic	C2/m	3.36	9.44	90.00	90.00	79.75	Journal of Solid State Chemistry 1984, 53, 415-421

SUPPORTING INFORMATION

Bi₃Se₄	mp-542615	trigonal	R-3m	4.30	4.30	90.00	90.00	60.00	Dokl. AN SSSR, 1955, 100, 1079-1082; Nanotechnology 2018, 29, 085401
TaTe₂	mp-601823	monoclinic	C2/m	3.53	9.72	90.00	90.00	79.60	J. Phys.: Condens. Matter 1998, 10, 761
Nb₂Se₃	mp-2330	monoclinic	P21/m	3.38	9.81	90.00	90.00	90.00	Acta Cryst. 1968, 24, 1102-1106
Pr₂Br₅	mp-23169	monoclinic	P21/m	4.11	15.75	90.00	90.00	90.00	Journal of Solid State Chemistry 1991, 95, 1-13
CeZnPO	mp-13207	trigonal	R-3m	3.93	3.93	90.00	90.00	60.00	Z. Anorg. Allg. Chem., 2008, 634, 1339-1348.
EuBrO	mp-504727	tetragonal	P4/nmm	3.77	3.77	90.00	90.00	90.00	Z. Anorg. Allg. Chem. 1965, 338: 250-265
TbBr	mp-27924	trigonal	R-3m	3.79	3.79	90.00	90.00	60.00	Z. Anorg. Allg. Chem. 1980, 466, 7-22
CrGeTe₃	mp-541449	trigonal	R3	6.85	6.85	90.00	90.00	60.00	J. Am. Chem. Soc. 2020, 142, 9, 4438-4444
PtPb₄	mp-21296	tetragonal	P4/nbm	6.79	6.79	90.00	90.00	90.00	Phys. Rev. B 2021, 104, 125127
CuH₂(SeO₃)₂	mp-24164	monoclinic	P21/c	7.03	8.62	90.00	90.00	90.00	Zeitschrift für Kristallographie -

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									Crystalline Materials. 2001, 216, 99-104
Ag(AuS)₂	mp-35835	monoclinic	Pc	4.29	7.16	90.00	90.00	90.00	N/A
Nb₉IrSe₂₀	mp- 675290	triclinic	P-1	6.91	15.10	90.00	90.00	83.51	N/A
AgHO₂	mp- 996958	monoclinic	Cm	5.42	5.48	90.00	90.00	80.84	N/A
La₂PI₂	mp- 571647	trigonal	P-3m1	4.30	4.30	90.00	90.00	120.00	Zeitschrift für Naturforschung B, 2007, 62, 11, 2007, 1377-1382
TbGal	mp- 1025099	trigonal	P-3m1	4.18	4.18	90.00	90.00	120.00	N/A
Cel₃	mp- 1025426	orthorhombic	Cmcm	4.33	10.10	90.00	90.00	90.00	N/A

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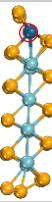
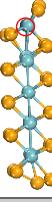
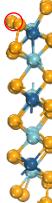
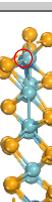
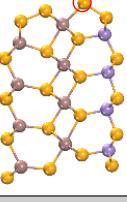
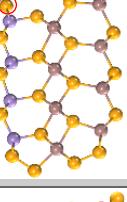
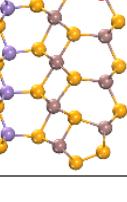
Table S6. Adsorption free energies (ΔG) of the OOH^* , O^* , and OH^* species, and the corresponding limiting potentials (U_L) for the ORR and OER on 77 built edges. The unit for adsorption energy and limiting potential are eV, and V, respectively. The major adsorption site is highlighted by red cycle.

Material	edge configuration	ΔG (OOH^*)	ΔG (O^*)	ΔG (OH^*)	U_L (ORR)	PDS of ORR	U_L (OER)	PDS of OER	Active?
ZrSiSe		-4.23	-2.29	-2.29	-2.29	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	9.15	$\text{OOH}^*\leftrightarrow\text{O}_2$	No
TaSe ₂		4.55	2.29	1.33	0.37	$\text{O}_2\leftrightarrow\text{OOH}^*$	2.26	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.64	0.92	0.42	0.42	$\text{OH}^*\leftrightarrow\text{H}_2\text{O(l)}$	2.72	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.81	0.40	0.52	-0.11	$\text{O}_2\leftrightarrow\text{OOH}^*$	3.41	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
NbSe ₂		4.40	1.86	1.20	0.52	$\text{O}_2\leftrightarrow\text{OOH}^*$	2.54	$\text{O}\leftrightarrow\text{OOH}$	No
		5.26	1.81	0.69	-0.34	$\text{O}_2\leftrightarrow\text{OOH}^*$	3.46	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		4.03	0.56	0.53	0.03	$\text{O}^*\leftrightarrow\text{OH}^*$	3.47	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
Fe ₄ S ₅		3.72	1.53	0.82	0.71	$\text{O}^*\leftrightarrow\text{OH}^*$	2.19	$\text{O}^*\leftrightarrow\text{OOH}^*$	ORR

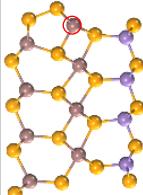
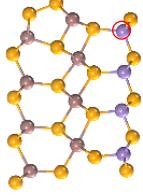
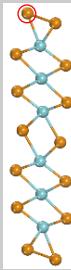
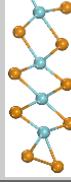
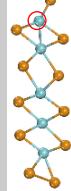
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		3.35	1.82	0.02	0.02	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	1.80	$\text{OH}^*\leftrightarrow\text{O}^*$	No
BiSe		3.38	0.46	0.05	0.05	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.92	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.31	2.50	0.78	0.78	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	1.72	$\text{OH}^*\leftrightarrow\text{O}^*$	ORR&OER
		3.44	2.29	0.08	0.08	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.21	$\text{OH}^*\leftrightarrow\text{O}^*$	No
		3.63	2.20	0.27	0.27	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	1.94	$\text{OH}^*\leftrightarrow\text{O}^*$	No
		4.30	2.46	1.16	0.62	$\text{O}_2\leftrightarrow\text{OOH}^*$	1.84	$\text{O}^*\leftrightarrow\text{OOH}^*$	ORR&OER
TaS ₂		4.74	0.57	0.79	-0.22	$\text{O}^*\leftrightarrow\text{OH}^*$	4.16	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.28	0.01	-0.90	-0.90	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.27	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.92	0.78	0.72	0.06	$\text{O}^*\leftrightarrow\text{OH}^*$	3.14	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
Nb ₉ IrSe ₂₀		4.02	0.68	0.88	-0.20	$\text{O}^*\leftrightarrow\text{OH}^*$	3.34	$\text{O}^*\leftrightarrow\text{OOH}^*$	No

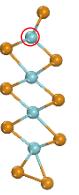
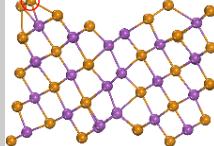
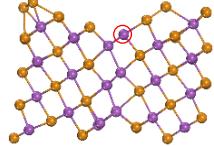
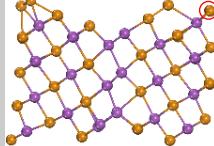
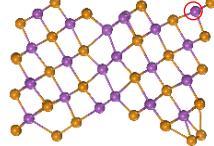
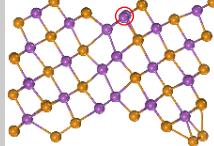
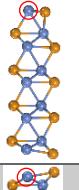
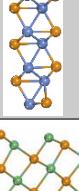
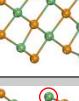
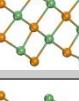
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		3.51	1.86	0.40	0.40	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	1.65	$\text{O}^*\leftrightarrow\text{OOH}^*$	OER
		2.91	-0.63	-0.76	-0.76	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.55	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
$\text{Nb}_4\text{IrSe}_{10}$		3.60	0.89	0.32	0.32	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.71	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.27	0.01	-0.25	-0.25	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.26	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		4.04	2.57	1.14	0.88	$\text{O}_2\leftrightarrow\text{OOH}^*$	1.48	$\text{O}^*\leftrightarrow\text{OOH}^*$	ORR&OER
$\text{Mn}(\text{InSe}_2)_2$		4.05	1.54	1.18	0.37	$\text{O}^*\leftrightarrow\text{OH}^*$	2.51	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		2.89	0.68	-0.45	-0.45	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.21	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.54	0.39	0.72	-0.33	$\text{O}^*\leftrightarrow\text{OH}^*$	3.15	$\text{O}^*\leftrightarrow\text{OOH}^*$	No

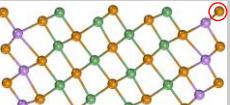
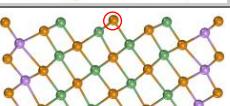
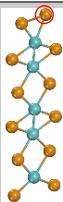
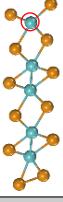
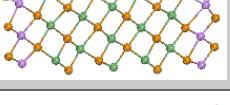
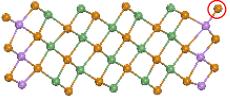
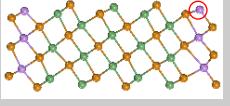
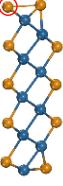
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		2.50	0.61	-0.73	-0.73	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.42	$\text{OOH}^*\leftrightarrow\text{O}_2$	No
		4.18	1.90	-0.41	-0.41	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.43	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
NbTe_2		3.78	1.46	0.35	0.35	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.33	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.21	0.57	-0.01	-0.01	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.64	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.44	0.21	0.37	-0.16	$\text{O}^*\leftrightarrow\text{OH}^*$	3.23	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.44	0.36	0.01	0.01	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.08	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.18	0.24	-0.14	-0.14	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.94	$\text{O}^*\leftrightarrow\text{OOH}^*$	No

SUPPORTING INFORMATION

		3.07	-0.15	-0.37	-0.37	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.22	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
BiTe		3.91	1.69	0.49	0.49	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.22	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.12	1.16	-0.13	-0.13	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	1.96	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.79	1.41	0.54	0.54	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.38	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.83	1.38	0.59	0.59	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.46	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.27	1.28	-0.01	-0.01	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.00	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
NiTe		3.11	1.11	-0.62	-0.62	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.00	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		1.06	-0.15	-1.39	-1.39	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	4.16	$\text{O}^*+\text{OH}^*\leftrightarrow\text{O}_2$	No
Ge ₄ Te ₇ As ₂		3.25	-0.06	-0.05	-0.05	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.31	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.50	-0.34	-0.48	-0.48	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	3.84	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.51	1.62	0.06	0.06	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	1.89	$\text{O}^*\leftrightarrow\text{OOH}^*$	No

SUPPORTING INFORMATION

		4.61	1.12	1.29	-0.16	$O^*\leftrightarrow OH^*$	3.48	$O^*\leftrightarrow OOH^*$	No
		3.83	1.51	0.66	0.66	$OH^*\leftrightarrow H_2O$	2.32	$O^*\leftrightarrow OOH^*$	ORR
MoTe ₂		3.68	1.16	0.31	0.31	$OH^*\leftrightarrow H_2O$	2.52	$O^*\leftrightarrow OOH^*$	No
		4.01	0.96	0.85	0.11	$O^*\leftrightarrow OH^*$	3.05	$O^*\leftrightarrow OOH^*$	No
		2.93	0.50	-0.32	-0.32	$OH^*\leftrightarrow H_2O$	2.43	$O^*\leftrightarrow OOH^*$	No
		3.21	-0.42	0.52	-0.93	$O^*\leftrightarrow OH^*$	3.63	$O^*\leftrightarrow OOH^*$	No
		3.51	-0.14	-0.19	-0.19	$OH^*\leftrightarrow H_2O$	3.65	$O^*\leftrightarrow OOH^*$	2.16
Ge ₅ (Te ₄ As) ₂		3.68	1.52	0.87	0.65	$O^*\leftrightarrow OH^*$	2.16	$O^*\leftrightarrow OOH^*$	ORR
		3.20	0.04	-0.17	-0.17	$OH^*\leftrightarrow H_2O$	3.16	$O^*\leftrightarrow OOH^*$	No
PtTe		3.52	1.46	0.19	0.19	$OH^*\leftrightarrow H_2O$	2.06	$O^*>OOH^*$	No

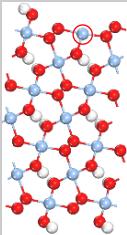
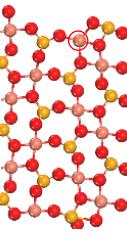
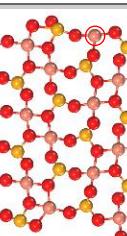
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		3.47	1.40	0.63	0.63	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.07	$\text{O}^*\leftrightarrow\text{OOH}^*$	ORR
LiNi(PS ₃) ₂		3.86	1.19	0.38	0.38	$\text{OH}^*\leftrightarrow\text{H}_2$	2.66	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.64	2.54	0.42	0.42	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.12	$\text{OH}^*\leftrightarrow\text{O}^*$	No
		3.97	1.36	1.00	0.37	$\text{O}^*\leftrightarrow\text{OH}^*$	2.60	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		4.15	3.10	1.46	0.77	$\text{O}_2\leftrightarrow\text{OOH}^*$	1.64	$\text{OH}^*\leftrightarrow\text{O}^*$	ORR&OER
Bi ₉ I ₂		3.72	1.31	0.43	0.43	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.42	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.37	0.74	0.09	0.09	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.63	$\text{O}^*\leftrightarrow\text{OOH}^*$	No

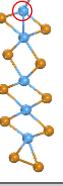
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		3.90	3.54	1.19	0.36	$\text{OOH}^*\leftrightarrow\text{O}^*$	2.64	$\text{OH}^*\leftrightarrow\text{O}^*$	No
		4.08	3.16	0.96	0.84	$\text{O}_2\leftrightarrow\text{OOH}^*$	2.20	$\text{OH}^*\leftrightarrow\text{O}^*$	ORR
CuTeO ₃		3.01	0.76	-0.39	-0.39	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.25	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.63	0.86	-1.09	-1.09	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.77	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
Bi ₄ I		3.84	1.19	0.66	0.53	$\text{O}^*\leftrightarrow\text{OH}^*$	2.65	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.57	1.11	0.52	0.52	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.46	$\text{O}^*\leftrightarrow\text{OOH}^*$	No

SUPPORTING INFORMATION

		3.29	0.55	-0.29	-0.29	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.74	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
PtPb ₄		3.59	1.53	0.38	0.38	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.06	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
		3.27	0.65	0.07	0.07	$\text{OH}^*\leftrightarrow\text{H}_2\text{O}$	2.62	$\text{O}^*\leftrightarrow\text{OOH}^*$	No
AgHO ₂		3.87	3.67	1.00	0.21	$\text{OOH}^*\leftrightarrow\text{O}^*$	2.67	$\text{OH}^*\leftrightarrow\text{O}^*$	No
CuSeO ₃		3.83	3.77	1.18	0.05	$\text{OOH}^*\leftrightarrow\text{O}^*$	2.59	$\text{OH}^*\leftrightarrow\text{O}^*$	No
		3.93	3.17	0.89	0.76	$\text{OOH}^*\leftrightarrow\text{O}^*$	2.28	$\text{OH}^*\leftrightarrow\text{O}^*$	ORR

SUPPORTING INFORMATION

TaTe ₂		3.72	1.01	0.29	0.29	OH*↔H ₂ O	2.71	O*↔OOH*	No
		3.53	0.67	0.27	0.27	OH*↔H ₂ O	2.85	O*↔OOH*	No
		3.68	0.27	0.41	-0.13	O*↔OH*	3.41	O*↔OOH*	No
		3.21	0.05	-0.22	-0.22	OH*↔H ₂ O	3.17	O*↔OOH*	No
		2.82	0.16	-0.39	-0.39	OH*↔H ₂ O	2.66	O*↔OOH*	No
		2.81	-0.29	-0.65	-0.65	OH*↔H ₂ O	3.10	O*↔OOH*	No

SUPPORTING INFORMATION

Table S7. Summary of dissolution sites, dissolution processes, standard reduction potentials (U^0 , V vs SHE), and dissolution potentials (U_{diss} , V vs SHE) of 40 candidate materials screened out from activity analysis. U^0 values of different materials were obtained from ref. 24-26. For the materials whose dissolution process involves the protons, the function between the U_{diss} and pH was evaluated by Nernst equation. For example, U_{diss} on La₂PI₂ is calculated as $U_{diss}(\text{pH}) = U_{diss}(\text{pH} = 0) - 0.0591/10 * \log 1/[H^+]^{12} = U_{diss}(\text{pH} = 0) - 0.0709 \text{ pH}$ according to the dissolution process of I₂ + 6H₂O → 2IO₃⁻ + 12H⁺ + 10 e⁻. More explanations can be in the website: <https://www.doitpoms.ac.uk/tplib/pourbaix/printall.php>.

Formula	Dissolution site	Dissolution Process	U^0	U_{diss} at pH = 0 without concentration correction	U_{diss} at pH = 0 with correction	Is the dissolution pH-dependent?	U_{diss} at different pH level
VAg(PSe ₃) ₂	P	P + 2H ₂ O → H ₃ PO ₂ + H ⁺ + e ⁻	-0.51	-0.47	-0.72	Yes	-0.72 – 0.0591 pH
MnSbSe ₂ I	Sb	2Sb + 3H ₂ O → Sb ₂ O ₃ + 6H ⁺ + 6e ⁻	0.15	-0.19	-0.24	Yes	-0.24 – 0.0591 pH
CuSeO ₃	Cu	Cu → Cu ²⁺ + 2e ⁻	0.34	0.10	-0.01	No	0.10
Bi ₄ I	Bi	Bi → Bi ³⁺ + 3e ⁻	0.31	0.43	0.32	No	0.43
CuTeO ₃	Cu	Cu → Cu ²⁺ + 2e ⁻	0.34	0.47	0.33	No	0.47
Bi ₉ I ₂	Bi	Bi → Bi ³⁺ + 3e ⁻	0.31	0.61	0.50	No	0.61
NiTe ₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.76	0.67	No	0.76
LiNi(PS ₃) ₂	S	S + 3H ₂ O → H ₂ SO ₃ + 4H ⁺ + 4e ⁻	0.45	0.63	0.55	Yes	0.55 – 0.0591 pH
Ta ₃ Te ₁₄ Pd ₃	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.82	0.73	No	0.73
PtTe	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.92	0.83	No	0.83
Ge ₅ (Te ₄ As) ₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.84	0.75	No	0.75
MoTe ₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.99	0.90	No	0.90
Ge ₄ Te ₇ As ₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.84	0.75	No	0.75
NiTe	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	1.13	1.04	No	1.04
BiTe	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.97	0.87	No	0.87
NbTe ₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	1.05	0.95	No	0.95
Mn(InSe ₂) ₂	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.04	0.96	Yes	0.96 – 0.0591 pH
Nb ₄ IrSe ₁₀	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.13	1.04	Yes	1.04 – 0.0591 pH
TaS ₂	S	S + 3H ₂ O → H ₂ SO ₃ + 4H ⁺ + 4e ⁻	0.45	1.28	1.18	Yes	1.18 – 0.0591 pH
BiSe	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.26	1.17	Yes	1.17 – 0.0591 pH

SUPPORTING INFORMATION

Fe₄S₅	S	S + 3H ₂ O → H ₂ SO ₃ + 4H ⁺ + 4e ⁻	0.45	1.34	1.26	Yes	1.26 – 0.0591 pH
NbSe₂	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.50	1.40	Yes	1.40 – 0.0591 pH
TaSe₂	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.50	1.40	Yes	1.40 – 0.0591 pH
ZrSiSe	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.65	1.56	Yes	1.56 – 0.0591 pH
GdBr	\	\	\	\	\	\	\
Sc₆C₂I₁₁	Sc	Sc → Sc ³⁺ + 3e ⁻	-2.09	-0.90	-1.00	No	-1.00
Li₂Cu₂F₅	Cu	Cu → Cu ²⁺ + 2e ⁻	0.34	-0.01	-0.02	No	-0.02
Pd₃Pb₂Te₂	Pb	Pb → Pb ³⁺ + 3e ⁻	-0.13	0.45	0.29	No	0.29
Zn(InS₂)₂	S	S + 3H ₂ O → H ₂ SO ₃ + 4H ⁺ + 4e ⁻	0.45	0.69	0.60	Yes	0.60
Ta(NiTe)₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.85	0.76	No	0.76
VT₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	0.98	0.89	No	0.89
Bi₃Se₄	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.13	1.04	Yes	1.04 – 0.0591 pH
TaTe₂	Te	Te → Te ⁴⁺ + 4e ⁻	0.57	1.05	0.96	No	0.96
Nb₂Se₃	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.54	1.45	Yes	1.45 – 0.0591 pH
Pr₂Br₅	\	\	\	\	\	\	\
CeZnPO	\	\	\	\	\	\	\
EuBrO	\	\	\	\	\	\	\
TbBr	\	\	\	\	\	\	\
CrGeTe₃	Ge	Ge → Ge ²⁺ + 2e ⁻	0.1	0.07	-0.10	No	-0.10
PtPb₄	Pb	Pb → Pb ³⁺ + 3e ⁻	-0.13	0.26	0.07	No	0.07
CuH₂(SeO₃)₂	Cu	Cu → Cu ²⁺ + 2e ⁻	0.34	0.53	0.41	No	0.41
Ag(AuS)₂	S	S + 3H ₂ O → H ₂ SO ₃ + 4H ⁺ + 4e ⁻	0.45	0.71	0.63	Yes	0.63 – 0.0591 pH
Nb₉IrSe₂₀	Se	Se + 3H ₂ O → H ₂ SeO ₃ + 4H ⁺ + 4e ⁻	0.74	1.25	1.15	Yes	1.15 – 0.0591 pH
AgHO₂	Ag	Ag → Ag ⁺ + e ⁻	0.80	0.77	0.55	No	0.55
La₂PI₂	I	I ₂ + 6H ₂ O → 2IO ₃ ⁻ + 12H ⁺ + 10 e ⁻	1.20	1.80	1.72	Yes	1.72 – 0.0709 pH
TbGal	\	\	\	\	\	\	\
Cel₃	\	\	\	\	\	\	\

SUPPORTING INFORMATION

Table S8 Calculated potential difference between U_{diss} and U_L ($U_{diss} - U_L$) as a function of pH, and the minimum pH requirement (pH_{mini}) of 14 ORR catalysts and 16 OER catalysts that excluded from the electrochemical stability analysis at pH = 0. For materials that the value of $U_{diss} - U_L$ remains constant at full pH level, the pH_{mini} is marked as “none”. Unstable materials at full pH range were highlighted by red color.

Category	Formula	$U_{diss} - U_L$ as function of pH	pH_{mini}
ORR catalysts	LiNi(PS ₃) ₂	-0.06 + 0.0591 pH	2
	VAg(PSe ₃) ₂	-1.32	none
	Ta ₃ Te ₁₄ Pd ₃	-0.02	none
	MnSbSe ₂ I	-0.86	none
	CrGeTe ₃	-0.93 + 0.0591 pH	>14
	CuSeO ₃	-0.81 + 0.0591 pH	14
	AgHO ₂	-0.61 + 0.0591 pH	11
	PtPb ₄	-0.57 + 0.0591 pH	10
	Bi ₄ I	-0.50 + 0.0591 pH	9
	CuTeO ₃	-0.42 + 0.0591 pH	8
	CuH ₂ (SeO ₃) ₂	-0.31 + 0.0591 pH	6
	Ag(AuS) ₂	-0.13	none
	Bi ₉ I ₂	-0.12 + 0.0591 pH	3
	NiTe ₂	-0.09	none
OER catalysts	Sc ₆ C ₂ I ₁₁	-2.91 + 0.0591 pH	>14
	Li ₂ Cu ₂ F ₅	-1.75 + 0.0591 pH	>14
	CrGeTe ₃	-1.75 + 0.0591 pH	>14
	PtPb ₄	-1.75 + 0.0591 pH	>14
	Pd ₃ Pb ₂ Te ₂	-1.28 + 0.0591 pH	>14
	CuH ₂ (SeO ₃) ₂	-1.36 + 0.0591 pH	>14
	Zn(InS ₂) ₂	-1.26	none
	Ag(AuS) ₂	-1.20	none
	Ta(NiTe) ₂	-1.15 + 0.0591 pH	>14
	VT ₂	-1.03 + 0.0591 pH	>14
	Bi ₃ Se ₄	-0.87	none
	TaTe ₂	-0.83 + 0.0591 pH	14
	Nb ₉ IrSe ₂₀	-0.76	none
	AgHO ₂	-0.77 + 0.0591 pH	13
	Nb ₂ Se ₃	-0.43	none
	La ₂ PI ₂	-0.19 – 0.1182 pH	none

SUPPORTING INFORMATION

Table S9 Summary of theoretical and experimental progresses on the design of 2D materials for the oxygen electrocatalysis.

	Material	Overpotential	Active site	Theory or Exp?	Stability of the original structure	Reference
ORR catalysts	Pd ₃ Pb	330 mV in 0.1 M KOH	Pt sites	Theory & Exp.	Activity remains 77% after 5000 cycles	Small Methods 2018, 1700331
	MX ₂ (M= V, Nb, Mo, Ta, and W; X= S, Se and Te)	>=950 mV in aprotic media	Edge sites of VSe ₂	Theory & Exp.	N/A	Adv. Mater. 2019, 31, 1804453
	CoS ₂	580 mV	Co metal site within the Co oxide surface	Theory & Exp.	Unstable	ACS Appl. Energy Mater. 2019, 2, 8605–8614
	SnS, and SnS ₂	>1000 mV on SnS ₂ in 50 mM phosphate buffered saline	N/A	Exp.	Unstable	J. Phys. Chem. C 2016, 120, 24098–24111
	InS, InSe and InTe	>1000 mV in 1.0 M KOH solution	N/A	Exp.	Unstable	ChemCatChem 2019, 11, 2634 – 2642
	FeNiS ₂	450 mV in 0.1 M phosphate buffer solution	N/A	Exp.	Stable	Nano Energy 27 (2016) 526–534
	Ni ₃ S ₂ /MoS ₂ heterostructure	280 mV in 0.1 M KOH electrolyte	Mo edges/Mo–Ni–S sites in the heterointerfaces	Exp.	2.7 h test with activity loss of 12.0%	J. Mater. Chem. A, 2019, 7, 8785–8789
	Nb/Ta doped MoS ₂ and WS ₂	>=450 mV on undoped MoS ₂ in 0.1 M KOH solution	N/A	Exp.	N/A	ACS Catal. 2016, 6, 5724–5734
	P doped MoS ₂	270 mV	N/A	Exp.	Over 2.7 h with activity loss of 18.8%	Chem. Commun., 2015, 51, 7903--7906
	MX ₂ (M = Nb, Ta, Mo, W; X = S, Se, Te)	540 mV	S/Te sites in the basal plane of NbS ₂ /TaSe ₂	Theory	N/A	Nano Research volume 12, pages 925–930 (2019)
OER catalysts	iT'-TaTe ₂	510 mV	Te sites in the basal plane	Theory	1, 2	Green Energy & Environment, https://doi.org/10.1016/j.gee.2020.11.003
	PtTe	370 mV	Te sites in the basal plane	Theory	1, 2	J. Am. Chem. Soc. 2018, 140, 12732–12735

SUPPORTING INFORMATION

	NiTe	450 mV	Te sites in the basal plane	Theory	1, 2, 4	J. Phys. Chem. C 2021, 125, 19164–19170
	M ₂ S ₂ (M= Sc, Ti, V, Cr, Mn, Co, Ni, Zr, Nb, Mo, Ru, Rh, Pd, Hf, Ta, W, and Ir)	>=380 mV	S sites in the basal plane of Ti ₂ S ₂	Theory	N/A	Energy Fuels 2020, 34, 5006–5015
	²⁰⁶ MS ₂ contain ₂ H, ₁ T, and ₁ T' phase	>=240 mV	Te sites in the basal plane of VTe ₂	Theory	1, 2, 3	J. Phys. Chem. Lett. 2022, 13, 58–65
	Pt ₅ Se ₄	700 mV	Pt sites in the basal plane	Theory	1, 2, 4	ACS Appl. Mater. Interfaces 2020, 12, 12, 13896–13903
	RuN ₂	240 mV	Ru sites in the basal plane	Theory	1, 2, 3	ACS Appl. Mater. Interfaces 2020, 12, 49, 54517–54523
	IrN ₂	470 mV	Ir sites in the basal plane	Theory	1,2,3	Journal of Colloid and Interface Science (2021), doi: https://doi.org/10.1016/j.jcis.2021.05.028
	MN ₄ C ₁₂ H ₄ (M=Cr, Mn, Fe, Co, Ni, Cu, Ru, Rh, Ir, Pt, Pd, and Ag)	>=330 mV	Fe sites in the basal plane of FeN ₄ C ₁₂ H ₄	Theory	1,3	Journal of Catalysis 370 (2019) 378–384
	M ₂ C ₁₂ N ₁₂ H ₁₂ (M= V, Cr, Mn, Fe, Co, Ni, Cu, Ru, Rh, Pd)	>=520 mV	Fe sites in the basal plane of Fe ₂ C ₁₂ N ₁₂ H ₁₂	Theory	N/A	Journal of Catalysis 352 (2017) 579–585
	MC ₂ (M= Ti, V, Nb, Ta, and Mo)	>=370mV	C sites in the basal plane of TaC ₂	Theory	1, 2	Adv. Funct. Mater. 2020, 30, 2000570
	GeS, GeSe, and SnSe	>=520 mV	Ge sites in the basal plane of GeS	Theory	1, 3	J. Mater. Chem. A, 2017, 5, 1734–1741
	Nb ₂ SbTe ₂	330 mV	Te sites in the basal plane	Theory	1, 2	Inorg. Chem. 2022, 61, 4, 2284–2291
	Ni ₂ SbTe ₂ , NiSb, NiTe ₂ , NiSe ₂ , Co ₂ SbTe, and Ni ₂ SbSe ₂	>=710 mV	(014) surface of Ni ₂ SbTe ₂	Theory	1, 2	J. Phys. Chem. C 2020, 124, 3671–3680
	MA ₂ Z ₄ (M = Ti, Zr, Hf, V, Nb, Ta, Cr, Mo, W; A = Si or Ge; Z = N,	>=490 mV	As sites in the basal plane of CrGe ₂ As ₄	Theory	1, 2	J. Phys. Chem. C 2021, 125, 22581–22590

SUPPORTING INFORMATION

	P, or As)					
	N-/P-doped TMD (MoS ₂ , MoSe ₂ , WS ₂ , and WSe ₂)	>=310 mV	N sites in the N-doped WS ₂ monolayer	Theory	1	ChemElectroChem 2018, 5, 4029 –4035
	Pt doped MoSe ₂	480 mV	Se sites in the basal plane	Theory	N/A	J. Mater. Chem. C, 2021, 9, 11331–11342
OER catalysts	Fe ₂ S ₆ C ₆	372 mV at 20°C in 1.0 M N ₂ -saturated KOH electrolyte	Fe, and S sites in the basal plane	Theory & Exp.	50 h with activity loss of 6 mV.	ACS Energy Lett. 2022, 7, 343–348
	PtSe ₂	663 mV	Defective sites in the basal plane	Theory & Exp.	Over 10 h in 1 M KOH	Adv. Energy Mater. 2022, 12, 2102359
	MoS ₂ , and TaS ₂ with 1T and 2H phases	420 mV in 0.5 M H ₂ SO ₄	Edge sites of the 1T-MoS ₂	Theory & Exp.	Stable	Adv. Mater. Interfaces 2016, 3, 1500669
	MX ₂ (M= V, Nb, Mo, Ta, and W; X= S, Se and Te)	>=800mV in aprotic media	Edge sites of VSe ₂	Theory & Exp.	N/A	Adv. Mater. 2019, 31, 1804453
	NiPS ₃ /Ni ₂ P heterostructure	260 mV in 1.0 M KOH	In-situ formed nickel hydroxides and/or oxyhydroxides	Theory & Exp.	Unstable	ACS Nano 2019, 13, 7, 7975–7984
	Ni ₃ S ₂ nanosheet arrays on nickel foam	260 mV in basic media	In situ grown (2̄10) high-index facet	Theory & Exp.	Retains the activity for over 200 h	J. Am. Chem. Soc. 2015, 137, 44, 14023–14026
	CoSe ₂	294.2 mV in 1 M NaOH	Co vacancies in in-situ formed metal hydroxides	Theory & Exp.	Unstable	Nat Commun 11, 1664 (2020).
	PtTe ₂	368 mV	Newly formed Pt sites	Exp.	Unstable	Nanotechnology, 2020, 31 375601
	Co doped MoS ₂	220 mV	Newly formed high valence state Co species	Exp.	Unstable	Adv. Mater. 2018, 30(29), 1801450
	Fe doped CoS ₂	302 mV	N/A	Exp.	Maintains the catalytic activity for at least 20 h	Chem. Commun., 2019, 55, 2469-2472
	FeNiS ₂	310 mV in 0.1 M KOH solution	Newly formed NiOOH species	Exp.	Unstable	Nano Energy 27 (2016) 526–534
	FePS ₃	288 mV in 0.1 M KOH	Newly formed	Exp.	Unstable	Small Methods 2019, 1900632

SUPPORTING INFORMATION

		solution	FeOOH species			
WS ₂ /CNT heterostructure	430 mV in 0.1 M KOH solution	W-bonded C atoms at the WS ₂ –CNT interface	Exp.	Stable	Adv. Energy Mater. 2017, 7, 1602217	
GeS, and GeSe	>=970mV	N/A	Exp.	Unstable	Phys. Chem. Chem. Phys., 2016, 18, 1699–1711	
SnS, and SnS ₂	>1000mV in 50 mM phosphate buffered saline	N/A	Exp.	Unstable	J. Phys. Chem. C 2016, 120, 24098–24111	
InS, InSe and InTe	>1000mV in 1.0 M KOH solution	N/A	Exp.	Unstable	ChemCatChem 2019, 11, 2634 – 2642	
Pt ₅ Se ₄	350 mV	Pt sites in the basal plane	Theory	1, 2, 4	ACS Appl. Mater. Interfaces 2020, 12, 12, 13896–13903	
MN ₂ (M= V, Co, W, Re, Rh, Pd, Ir)	>=270 mV	Ir sites in the basal plane of IrN ₂	Theory	1,2,3	Journal of Colloid and Interface Science (2021), doi: https://doi.org/10.1016/j.jcis.2021.05.028	
²⁰⁶ MS ₂ contain ² H, ¹ T, and ¹ T' phase	>=300 mV	Te sites in the basal plane of TaTe ₂	Theory	1, 2, 3	J. Phys. Chem. Lett. 2022, 13, 58–65	
MN ₄ C ₁₂ H ₄ (M=Cr, Mn, Fe, Co, Ni, Cu, Ru, Rh, Ir, Pt, Pd, and Ag)	>=460 mV	Ni sites in the basal plane of NiN ₄ C ₁₂ H ₄	Theory	1,3	Journal of Catalysis 370 (2019) 378–384	
MC ₆ N ₆ H ₆ (M= V, Cr, Mn, Fe, Co, Ni, Cu, Ru, Rh, Pd)	>=320 mV	Rh sites in the basal plane of RhN ₆ C ₆ H ₆	Theory	N/A	Journal of Catalysis 352 (2017) 579–585	
MC ₂ (M= Ti, V, Nb, Ta, and Mo)	>=450mV	C sites in the basal plane of MoC ₂	Theory	1, 2	Adv. Funct. Mater. 2020, 30, 2000570	
Metal atom doped Ga ₂ FeS ₄	>=480 mV	Au atom doped Ga ₂ FeS ₄	Theory	1	J. Mater. Chem. A, 2021, 9, 18594–18603	

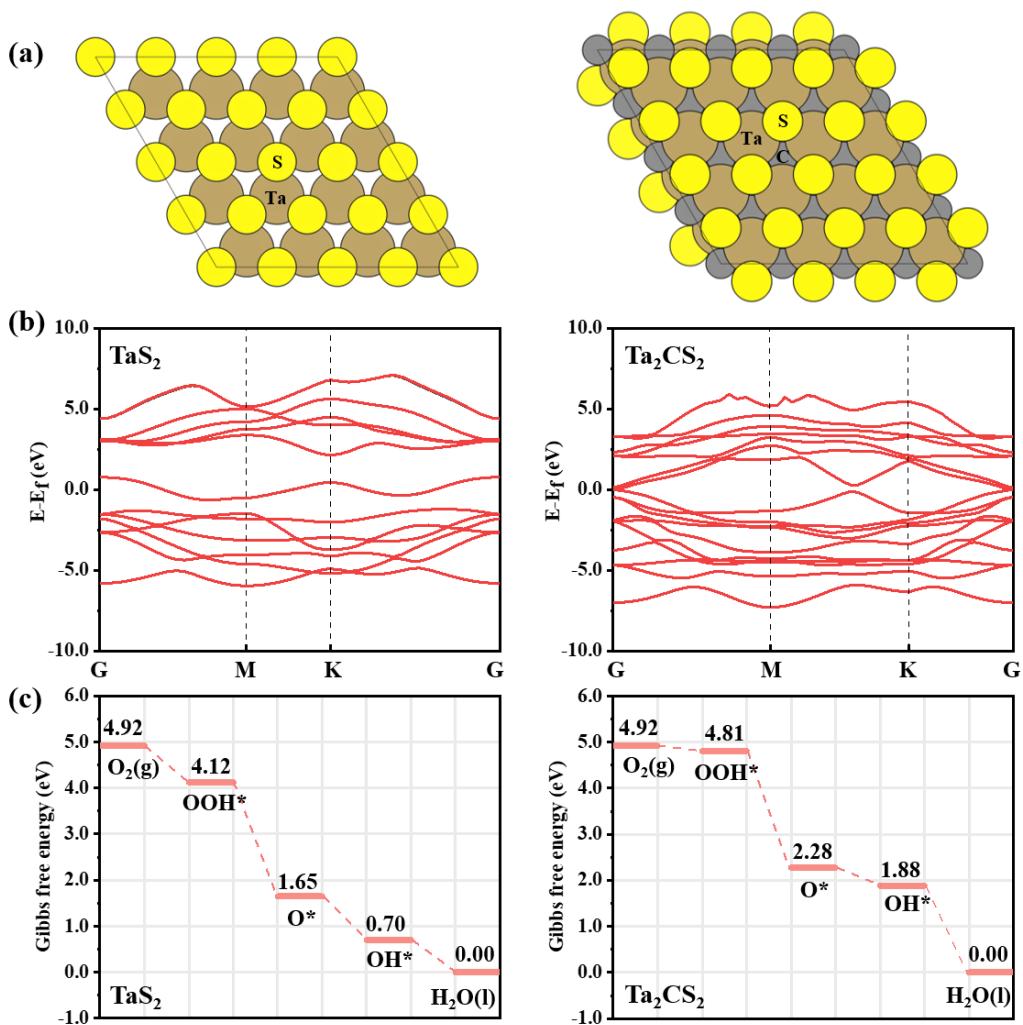


Fig. S1. Top view of structure (a), band structure (b), and reaction pathway along the oxygen reduction reaction for the TaS_2 and Ta_2CS_2 .

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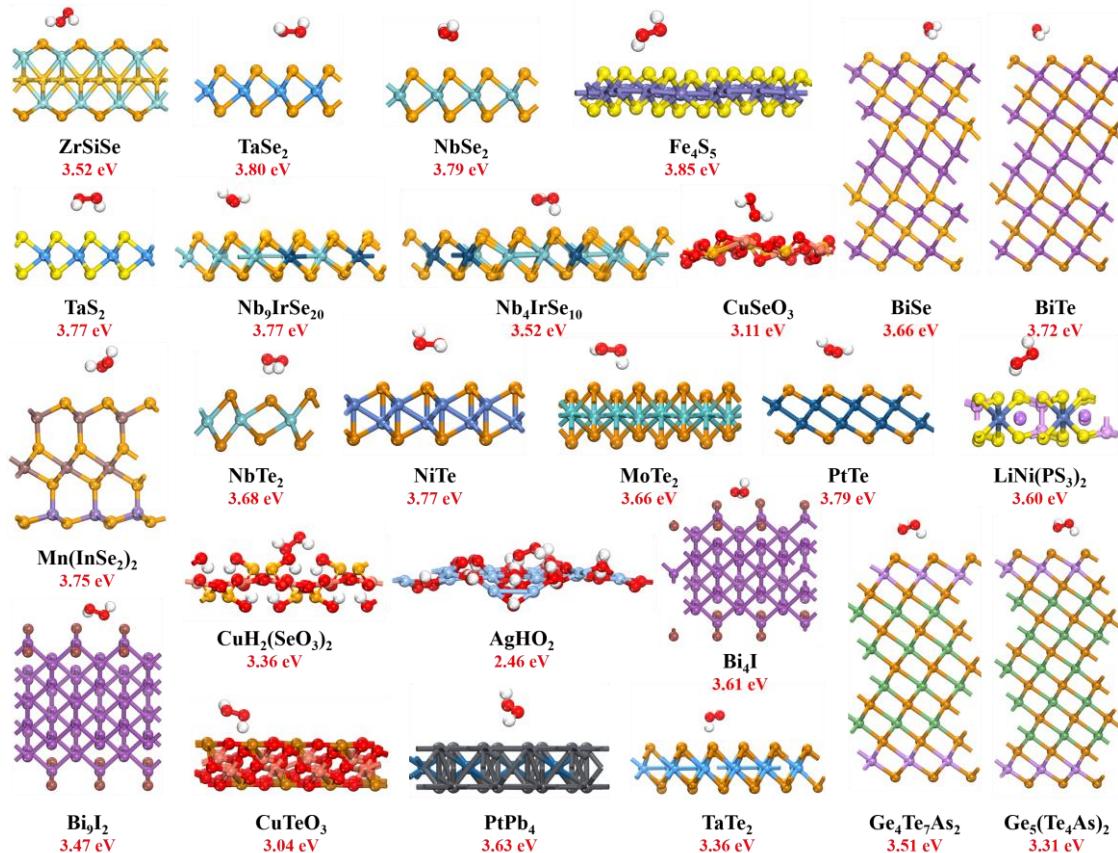


Fig. S2. Side view of adsorption configuration and the corresponding adsorption free energy of H_2O_2 (use the H_2O and H_2 as the energy references) at the active site of 25 2D materials that is predicted for the four-electron oxygen electrocatalysis.

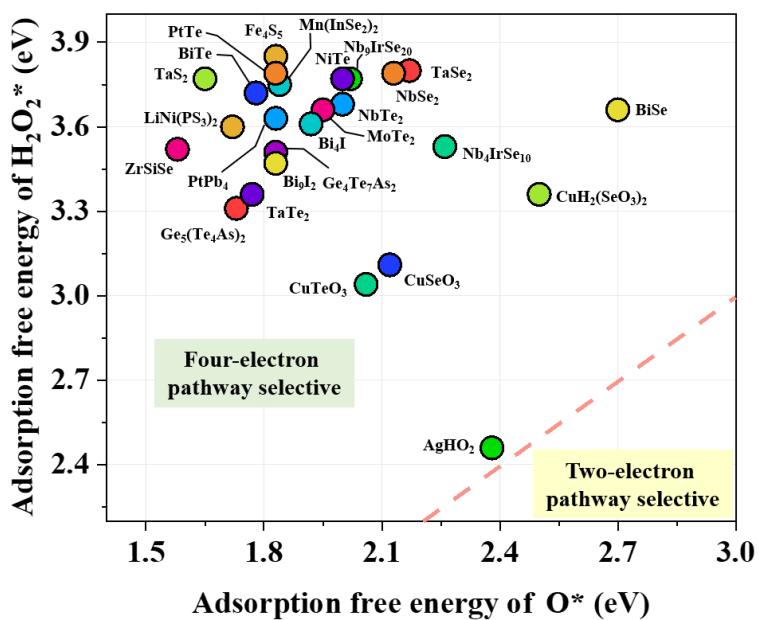


Fig. S3. Adsorption analysis for the O^* and H_2O_2^* on 25 four-electron pathway preferable materials that were identified using the free energy of O^* as the descriptor.

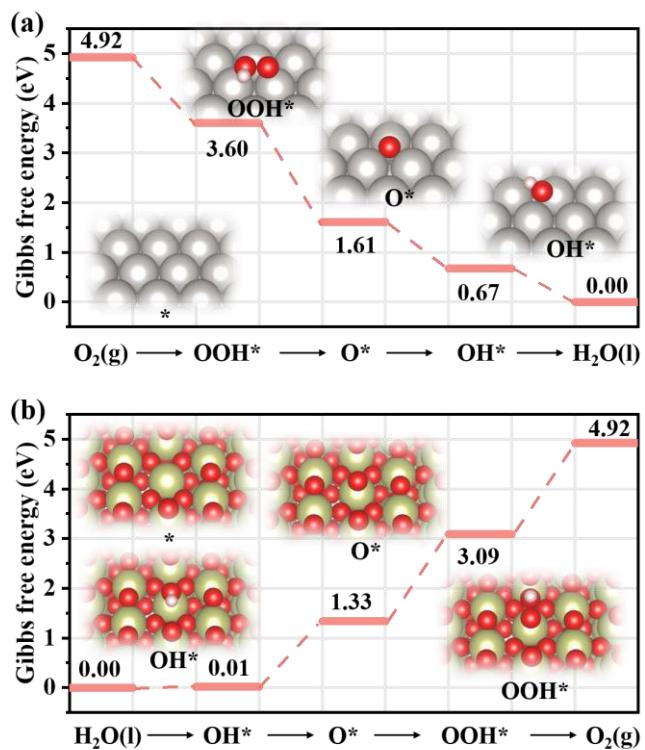


Fig. S4. Computed free energy profile of ORR on the Pt(111) (a), and of OER on the IrO₂(110) (b). The solvation contribution of -0.3, 0.0, -0.3 eV were included in the free energy computations for the OOH*, O*, OH*, respectively, to ensure all the computations are under the same computation level, and to be comparable as the activity benchmark. Note that the corrected adsorption free energies are of well agreement with the previous work.²⁸ For example, the computed free energy value of 3.088 eV for OOH* adsorption on the IrO₂(110) is very close to the reported value of 3.1 eV. No clear solvation correction was found for the O* adsorption, which also agrees well with our correction strategy. The slight difference might be raised by the dipole effect on the polar surfaces of IrO₂(110) due to the inclusion of explicit water molecules in their study.

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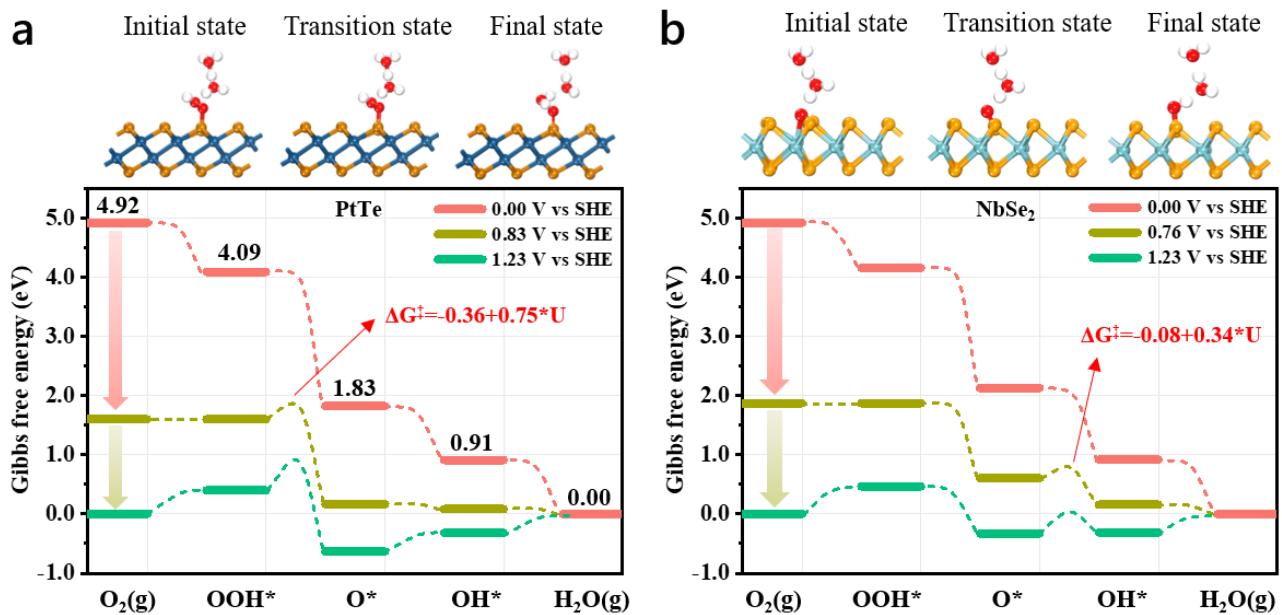


Fig. S5. Kinetic simulation of ORR on the PtTe and NbSe₂ surfaces at three different potential (zero potential, theoretical limiting potential, and equilibrium potential). The key reaction intermediates along the rate limiting step obtained from the climbing image nudged elastic band (CI-NEB) method are also shown.

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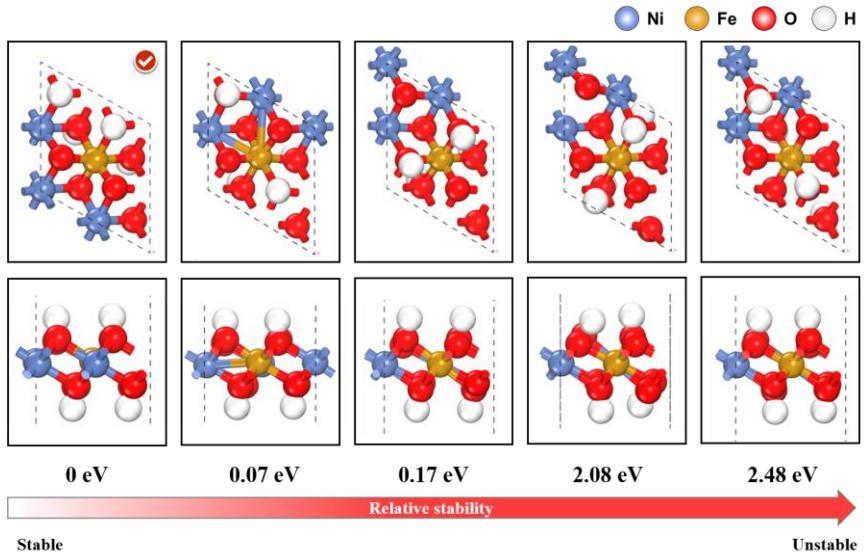


Fig. S6. Relative stability analysis on the possible configuration of $\text{Ni}_{0.75}\text{Fe}_{0.25}\text{OOH}$.

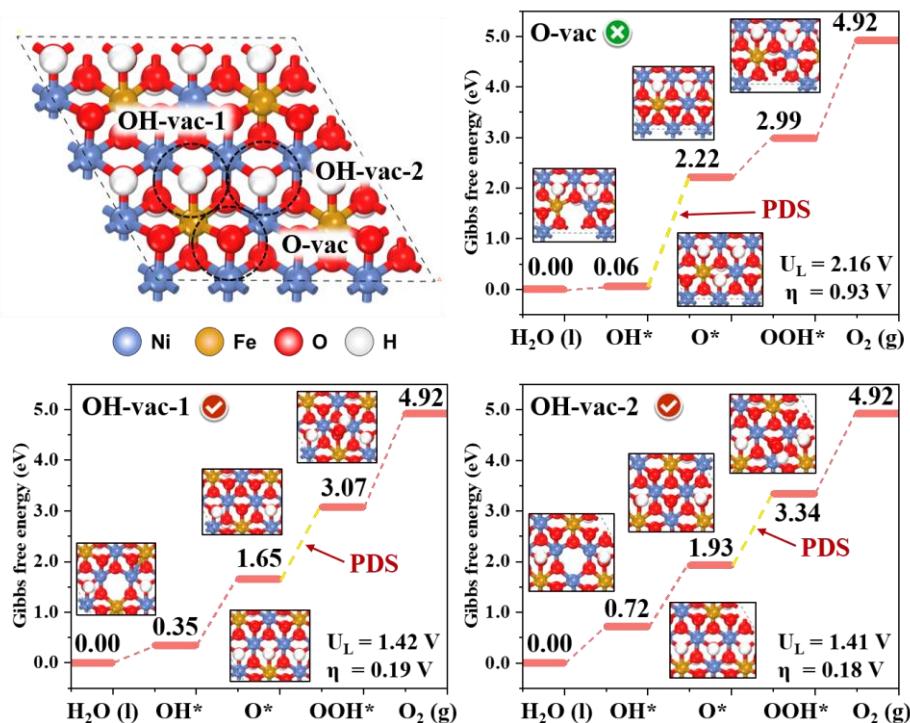


Fig. S7. Free energy diagrams for the OER on three different sites of $\text{Ni}_{0.75}\text{Fe}_{0.25}\text{OOH}$, including OH and O vacancies. The potential limiting step (PDS) was highlighted by yellow line. Note that the self-interaction error in GGA method could strongly affect the adsorption on the transitional oxides, as conventional DFT is not canceled out in redox reactions where the electrons are transferred between significantly different environments. To address this issue, DFT+U computations was carried out, where the U values for the Ni and Fe were set as 6.2 and 5.3 eV, respectively, following the strategy in the Materials Project database.

SUPPORTING INFORMATION

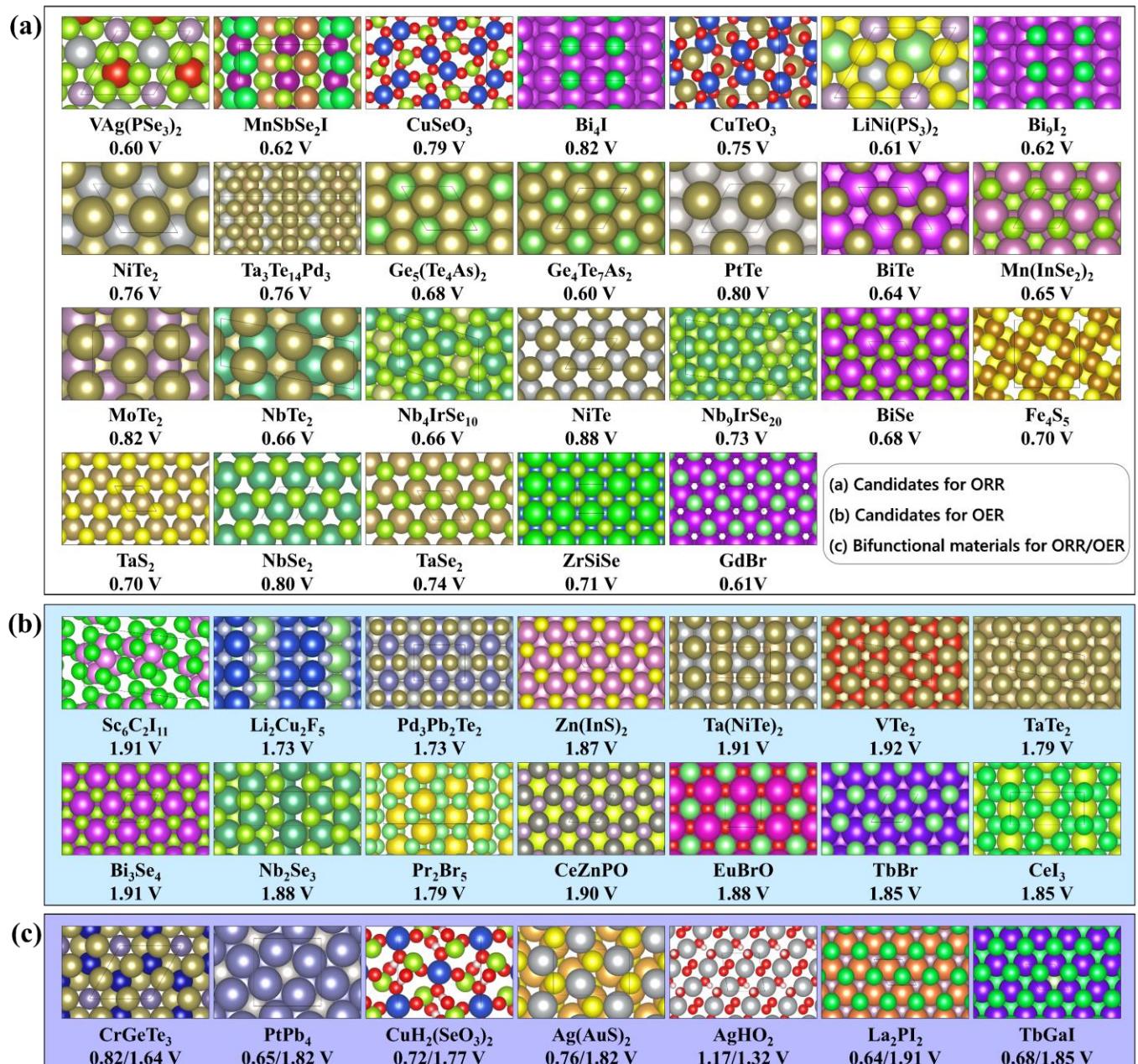


Fig. S8. (a) 25 basal plane active materials for the oxygen reduction reaction. (b) 13 candidates for the oxygen evolution reaction. (c) nine compounds with bifunctional capability for both oxygen reduction and oxygen evolution reactions.

	VAg(PSe₃)₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.45	0.08	0.37
ΔH	\	0.08	0.03	0.05
ΔTS	\	0.16	0.06	0.08
ΔG	\	3.92	1.34	0.60
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.60

Fig. S9. Optimized structures and computed thermodynamic data (include zero-point energy (ΔZPE), enthalpy (ΔH), entropy (ΔTS), and Gibbs free energy (ΔG)) of oxygen-containing species on the **VAg(PSe₃)₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	MnSbSe₂I	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.07	0.35
ΔH	\	0.09	0.03	0.05
ΔTS	\	0.18	0.05	0.08
ΔG	\	4.06	1.25	0.63
PDS	$O^* \rightarrow OH^*$	U_L(ORR)		0.62

Fig. S10. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **MnSbSe₂I** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	CuSeO_3	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.42	0.08	0.36
ΔH	\	0.11	0.03	0.05
ΔTS	\	0.24	0.05	0.09
ΔG	\	4.13	2.12	1.13
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$\text{U}_L(\text{ORR})$		0.79

Fig. S11. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the CuSeO_3 surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	Bi₄I	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.32
ΔH	\	0.10	0.03	0.06
ΔTS	\	0.21	0.06	0.12
ΔG	\	3.95	1.92	0.82
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.82

Fig. S12. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Bi₄I** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	CuTeO₃	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.07	0.34
ΔH	\	0.10	0.04	0.06
ΔTS	\	0.21	0.07	0.11
ΔG	\	4.17	2.06	0.94
PDS	$O^* \rightarrow OH^*$	U_L(ORR)		0.75

Fig. S13. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **CuTeO₃** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	Bi_9I_2	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.32
ΔH	\	0.08	0.03	0.07
ΔTS	\	0.14	0.06	0.13
ΔG	\	3.79	1.83	0.62
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.62

Fig. S14. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the Bi_9I_2 surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	NiTe₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.33
ΔH	\	0.10	0.03	0.06
ΔTS	\	0.21	0.06	0.12
ΔG	\	4.01	1.60	0.76
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.76

Fig. S15. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **NiTe₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	LiNi(PS₃)₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.08	0.37
ΔH	\	0.09	0.03	0.04
ΔTS	\	0.18	0.05	0.08
ΔG	\	4.31	1.72	0.99
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.61

Fig. S16. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **LiNi(PS₃)₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{Ta}_3\text{Te}_{14}\text{Pd}_3$	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.33
ΔH	\	0.10	0.04	0.07
ΔTS	\	0.21	0.06	0.14
ΔG	\	4.16	1.81	0.85
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$\text{U}_\text{L}(\text{ORR})$		0.76

Fig. S17. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Ta}_3\text{Te}_{14}\text{Pd}_3$ surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	TePt	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.33
ΔH	\	0.10	0.04	0.04
ΔTS	\	0.22	0.09	0.08
ΔG	\	4.02	1.83	0.80
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.80

Fig. S18. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **PtTe** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{Ge}_5(\text{Te}_4\text{As})_2$	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.41	0.05	0.32
ΔH	\	0.09	0.04	0.06
ΔTS	\	0.17	0.09	0.12
ΔG	\	4.24	1.73	1.04
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$\text{U}_L(\text{ORR})$		0.68

Fig. S19. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Ge}_5(\text{Te}_4\text{As})_2$ surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	MoTe₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.34
ΔH	\	0.10	0.04	0.06
ΔTS	\	0.19	0.08	0.11
ΔG	\	4.08	1.95	0.82
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.82

Fig. S20. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **MoTe₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	Ge₄Te₇As₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.41	0.05	0.32
ΔH	\	0.11	0.04	0.06
ΔTS	\	0.24	0.09	0.12
ΔG	\	4.32	1.83	1.17
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.60

Fig. S21. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Ge₄Te₇As₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	NiTe	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.33
ΔH	\	0.10	0.03	0.07
ΔTS	\	0.22	0.06	0.15
ΔG	\	4.09	2.00	0.88
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.83

Fig. S22. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **NiTe** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	BiTe	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.34
ΔH	\	0.10	0.04	0.06
ΔTS	\	0.20	0.08	0.11
ΔG	\	4.28	1.78	1.09
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.64

Fig. S23. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **BiTe** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	NbTe₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.33
ΔH	\	0.07	0.04	0.07
ΔTS	\	0.14	0.08	0.14
ΔG	\	3.95	2.00	0.66
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.66

Fig. S24. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **NbTe₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	Mn(InSe₂)₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.06	0.33
ΔH	\	0.08	0.04	0.07
ΔTS	\	0.17	0.09	0.14
ΔG	\	4.27	1.84	1.12
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.65

Fig. S25. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Mn(InSe₂)₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{Nb}_4\text{IrSe}_{10}$	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.44	0.06	0.33
ΔH	\	0.09	0.04	0.06
ΔTS	\	0.18	0.07	0.13
ΔG	\	4.26	2.26	1.43
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$U_L(\text{ORR})$		0.66

Fig. S26. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Nb}_4\text{IrSe}_{10}$ surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	TaS₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.44	0.08	0.35
ΔH	\	0.09	0.03	0.06
ΔTS	\	0.18	0.06	0.13
ΔG	\	4.12	1.65	0.70
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.70

Fig. S27. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TaS₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	BiSe	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.05	0.34
ΔH	\	0.10	0.04	0.06
ΔTS	\	0.20	0.10	0.11
ΔG	\	3.96	2.70	0.68
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$	U_L(ORR)		0.68

Fig. S28. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **BiSe** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	Fe₄S₅	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.08	0.34
ΔH	\	0.10	0.02	0.06
ΔTS	\	0.20	0.03	0.12
ΔG	\	3.93	1.83	0.70
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.70

Fig. S29. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Fe₄S₅** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	NbSe₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.44	0.07	0.34
ΔH	\	0.09	0.03	0.06
ΔTS	\	0.20	0.05	0.13
ΔG	\	4.12	2.13	0.83
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.80

Fig. S30. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **NbSe₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	TaSe₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.44	0.07	0.34
ΔH	\	0.09	0.03	0.04
ΔTS	\	0.20	0.05	0.08
ΔG	\	4.18	2.17	0.90
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.74

Fig. S31. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TaSe₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	ZrSiSe	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.42	0.07	0.32
ΔH	\	0.09	0.03	0.04
ΔTS	\	0.18	0.04	0.07
ΔG	\	4.12	1.58	0.71
PDS	$OH^* \rightarrow H_2O$	U_L(ORR)		0.71

Fig. S32. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **ZrSiSe** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	GdBr	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.33
ΔH	\	0.08	0.05	0.06
ΔTS	\	0.17	0.12	0.11
ΔG	\	4.19	1.91	0.61
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		$U_L(\text{ORR})$	0.61

Fig. S33. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **GdBr** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	CrGeTe₃	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.34
ΔH	\	0.09	0.04	0.06
ΔTS	\	0.19	0.08	0.11
ΔG	\	4.10	2.45	0.86
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.82

Fig. S34. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **CrGeTe₃** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	PtPb ₄	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.41	0.02	0.30
ΔH	\	0.11	0.06	0.03
ΔTS	\	0.22	0.14	0.04
ΔG	\	3.65	1.83	0.65
PDS	$\text{OH}^* \rightarrow \text{H}_2\text{O}$		U_L(ORR)	0.65

Fig. S35. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **PtPb₄** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{CuH}_2(\text{SeO}_3)_2$	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.42	0.08	0.35
ΔH	\	0.10	0.03	0.05
ΔTS	\	0.21	0.05	0.08
ΔG	\	4.20	2.50	1.77
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$\text{U}_L(\text{ORR})$		0.72

Fig. S36. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{CuH}_2(\text{SeO}_3)_2$ surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{Ag}(\text{AuS})_2$	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.36
ΔH	\	0.10	0.03	0.05
ΔTS	\	0.19	0.05	0.08
ΔG	\	4.16	2.34	1.01
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$U_L(\text{ORR})$		0.76

Fig. S37. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Ag}(\text{AuS})_2$ surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{Nb}_9\text{IrSe}_{20}$	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.44	0.06	0.35
ΔH	\	0.09	0.04	0.06
ΔTS	\	0.20	0.07	0.06
ΔG	\	4.19	2.27	0.93
PDS	$\text{O}_2 \rightarrow \text{OOH}^*$	$\text{U}_L(\text{ORR})$		0.73

Fig. S38. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Nb}_9\text{IrSe}_{20}$ surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	AgHO_2	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.42	0.08	0.34
ΔH	\	0.10	0.03	0.06
ΔTS	\	0.21	0.04	0.11
ΔG	\	3.70	2.38	1.21
PDS	$\text{O}^* \rightarrow \text{OH}^*$	$\text{U}_L(\text{ORR})$		1.17

Fig. S39. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the AgHO_2 surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	La₂PI₂	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.33
ΔH	\	0.08	0.04	0.06
ΔTS	\	0.16	0.07	0.10
ΔG	\	4.28	2.37	0.87
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.64

Fig. S40. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **La₂PI₂** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	TbGal	OOH*	O*	OH*
Top view				
Side view				
ΔZPE	\	0.43	0.06	0.31
ΔH	\	0.09	0.04	0.07
ΔTS	\	0.17	0.08	0.14
ΔG	\	4.24	2.71	0.85
PDS	$O_2 \rightarrow OOH^*$	U_L(ORR)		0.68

Fig. S41. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TbGal** surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	CeI_3	OOH^*	O^*	OH^*
Top view				
Side view				
ΔZPE	\	0.44	0.04	0.33
ΔH	\	0.09	0.03	0.06
ΔTS	\	0.18	0.03	0.11
ΔG	\	3.29	1.44	0.79
PDS	$\text{O}^* \rightarrow \text{OH}^*$	$\text{U}_L(\text{ORR})$		0.65

Fig. S42. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the CeI_3 surface. The corresponding U_L value for **ORR** is also shown.

SUPPORTING INFORMATION

	$\text{Sc}_6\text{C}_2\text{I}_{11}$	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.33	0.06	0.44
ΔH	\	0.06	0.04	0.10
ΔTS	\	0.12	0.10	0.21
ΔG	\	-0.44	1.18	3.01
PDS	$\text{OOH}^* \rightarrow \text{O}_2$	$\text{U}_L(\text{OER})$		1.91

Fig. S43. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Sc}_6\text{C}_2\text{I}_{11}$ surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	Li₂Cu₂F₅	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.37	0.07	0.44
ΔH	\	0.04	0.03	0.09
ΔTS	\	0.07	0.05	0.18
ΔG	\	0.53	2.38	4.11
PDS	$O^* \rightarrow OOH^*$	U_L(OER)		1.73

Fig. S44. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Li₂Cu₂F₅** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	$\text{Te}_2\text{Pd}_3\text{Pb}_2$	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.33	0.05	0.41
ΔH	\	0.06	0.04	0.11
ΔTS	\	0.10	0.07	0.24
ΔG	\	0.50	1.97	3.70
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\mathbf{U}_{\text{L}}(\text{OER})$		1.73

Fig. S45. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Pd}_3\text{Pb}_2\text{Te}_2$ surface. The corresponding U_{L} value for **OER** is also shown.

SUPPORTING INFORMATION

	Zn(InS₂)₂	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.41	0.07	0.42
ΔH	\	0.03	0.03	0.10
ΔTS	\	0.05	0.05	0.21
ΔG	\	1.10	2.54	4.41
PDS	$O^* \rightarrow OOH^*$	U_L(OER)		1.87

Fig. S46. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Zn(InS₂)₂** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	Ta(NiTe) ₂	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.32	0.05	0.41
ΔH	\	0.07	0.04	0.08
ΔTS	\	0.14	0.07	0.17
ΔG	\	1.46	2.71	4.62
PDS	O*→OOH*	U_L(OER)		1.91

Fig. S47. Optimized structures and computed thermodynamic data (include ΔZPE, ΔH, ΔTS, and ΔG) of oxygen-containing species on the Ta(NiTe)₂ surface. The corresponding U_L value for OER is also shown.

SUPPORTING INFORMATION

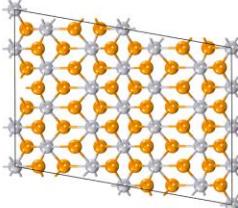
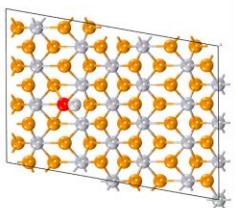
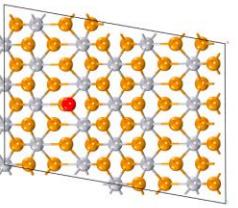
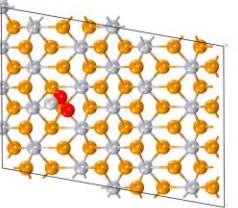
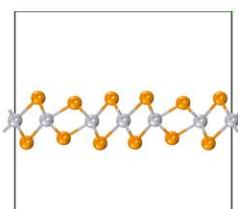
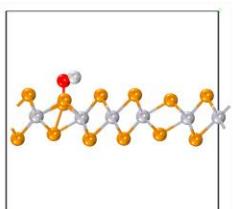
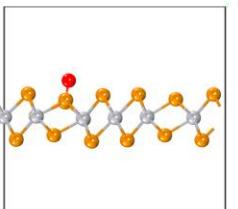
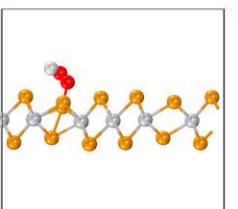
	VTe₂	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.33	0.06	0.43
ΔH	\	0.07	0.04	0.10
ΔTS	\	0.13	0.08	0.21
ΔG	\	0.57	1.93	3.85
PDS	$O^* \rightarrow OOH^*$	U_L(OER)		1.92

Fig. S48. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TaS₂** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	Bi_3Se_4	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.34	0.06	0.43
ΔH	\	0.06	0.04	0.10
ΔTS	\	0.12	0.09	0.20
ΔG	\	0.32	1.70	3.61
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\text{U}_L(\text{OER})$		1.91

Fig. S49. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the Bi_3Se_4 surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	TaTe₂	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.34	0.06	0.43
ΔH	\	0.06	0.04	0.10
ΔTS	\	0.13	0.09	0.22
ΔG	\	0.29	1.77	3.55
PDS	$O^* \rightarrow OOH^*$	U_L(OER)		1.79

Fig. S50. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TaTe₂** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	Nb₂Se₃	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.33	0.06	0.42
ΔH	\	0.07	0.04	0.10
ΔTS	\	0.13	0.07	0.23
ΔG	\	1.45	2.71	4.59
PDS	$O^* \rightarrow OOH^*$		U_L(OER)	1.88

Fig. S51. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **Nb₂Se₃** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	Pr_2Br_5	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.32	0.05	0.43
ΔH	\	0.07	0.02	0.10
ΔTS	\	0.13	0.04	0.19
ΔG	\	0.22	1.87	3.66
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\text{U}_L(\text{OER})$		1.79

Fig. S52. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the Pr_2Br_5 surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	CeZnPO	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.35	0.06	0.44
ΔH	\	0.05	0.04	0.09
ΔTS	\	0.09	0.07	0.18
ΔG	\	0.04	1.22	3.12
PDS	$O^* \rightarrow OOH^*$	$U_L(OER)$		1.90

Fig. S53. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **CeZnPO** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	EuBrO	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.32	0.07	0.44
ΔH	\	0.06	0.03	0.08
ΔTS	\	0.12	0.05	0.15
ΔG	\	1.88	1.92	3.74
PDS	$H_2O^* \rightarrow OH^*$	U_L(OER)		1.88

Fig. S54. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **EuBrO** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	TbBr	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.33	0.06	0.43
ΔH	\	0.07	0.04	0.10
ΔTS	\	0.12	0.10	0.20
ΔG	\	0.56	2.18	4.03
PDS	$O^* \rightarrow OOH^*$		$U_L(OER)$	1.85

Fig. S55. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TbBr** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	CrGeTe_3	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.34	0.06	0.43
ΔH	\	0.06	0.04	0.09
ΔTS	\	0.11	0.08	0.19
ΔG	\	0.86	2.45	4.10
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\text{U}_L(\text{OER})$		1.64

Fig. S56. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the CrGeTe_3 surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	PtPb₄	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.30	0.02	0.41
ΔH	\	0.03	0.06	0.11
ΔTS	\	0.04	0.14	0.22
ΔG	\	0.65	1.83	3.65
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	U_L(OER)		1.82

Fig. S57. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **PtPb₄** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	CuH₂(SeO₃)₂	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.35	0.08	0.42
ΔH	\	0.05	0.03	0.10
ΔTS	\	0.08	0.05	0.21
ΔG	\	1.77	2.50	4.20
PDS	$H_2O \rightarrow OH^*$	U_L(OER)		1.77

Fig. S58. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **CuH₂(SeO₃)₂** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	$\text{Ag}(\text{AuS})_2$	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.36	0.06	0.43
ΔH	\	0.05	0.03	0.10
ΔTS	\	0.08	0.05	0.19
ΔG	\	1.01	2.34	4.16
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\text{U}_L(\text{OER})$		1.82

Fig. S59. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Ag}(\text{AuS})_2$ surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	$\text{Nb}_9\text{IrSe}_{20}$	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.35	0.06	0.44
ΔH	\	0.06	0.04	0.09
ΔTS	\	0.06	0.07	0.20
ΔG	\	0.93	2.27	4.19
PDS	$\text{OOH}^* \rightarrow \text{O}^*$	$\text{U}_L(\text{OER})$		1.91

Fig. S60. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the $\text{Nb}_9\text{IrSe}_{20}$ surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	AgHO_2	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.34	0.08	0.42
ΔH	\	0.06	0.03	0.10
ΔTS	\	0.11	0.04	0.21
ΔG	\	1.21	2.38	3.70
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\text{U}_L(\text{OER})$		1.32

Fig. S61. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the AgHO_2 surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	La₂PI₂	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.33	0.06	0.43
ΔH	\	0.06	0.04	0.08
ΔTS	\	0.10	0.07	0.16
ΔG	\	0.87	2.37	4.28
PDS	$O^* \rightarrow OOH^*$	U_L(OER)		1.91

Fig. S62. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **La₂PI₂** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	TbGal	OH*	O*	OOH*
Top view				
Side view				
ΔZPE	\	0.31	0.06	0.43
ΔH	\	0.07	0.04	0.09
ΔTS	\	0.14	0.08	0.17
ΔG	\	0.85	2.71	4.24
PDS	$\text{OH}^* \rightarrow \text{O}^*$	U_L(OER)		1.85

Fig. S63. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the **TbGal** surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

	CeI_3	OH^*	O^*	OOH^*
Top view				
Side view				
ΔZPE	\	0.33	0.04	0.44
ΔH	\	0.06	0.03	0.09
ΔTS	\	0.11	0.03	0.18
ΔG	\	0.79	1.44	3.29
PDS	$\text{O}^* \rightarrow \text{OOH}^*$	$\text{U}_L(\text{OER})$		1.85

Fig. S64. Optimized structures and computed thermodynamic data (include ΔZPE , ΔH , ΔTS , and ΔG) of oxygen-containing species on the CeI_3 surface. The corresponding U_L value for **OER** is also shown.

SUPPORTING INFORMATION

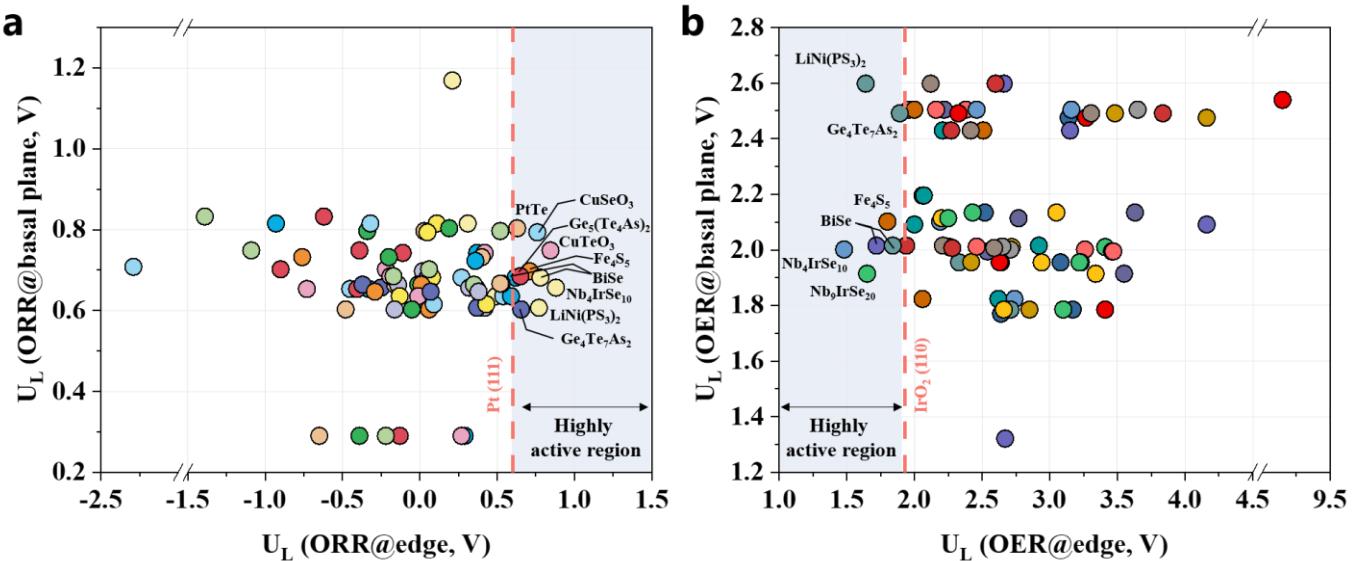


Fig. S65. Theoretical limiting potential (U_L) of ORR (a) and OER(b) on 77 edge surfaces in comparison with the potential on the basal planes.

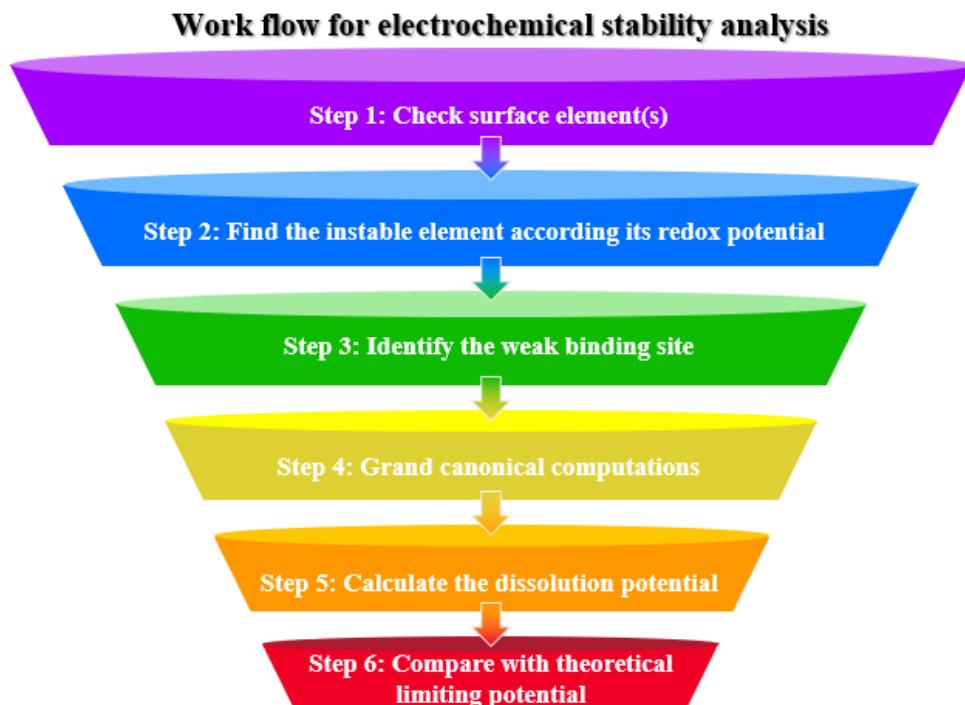


Fig. S66. Work flow for electrochemical stability analysis.

SUPPORTING INFORMATION

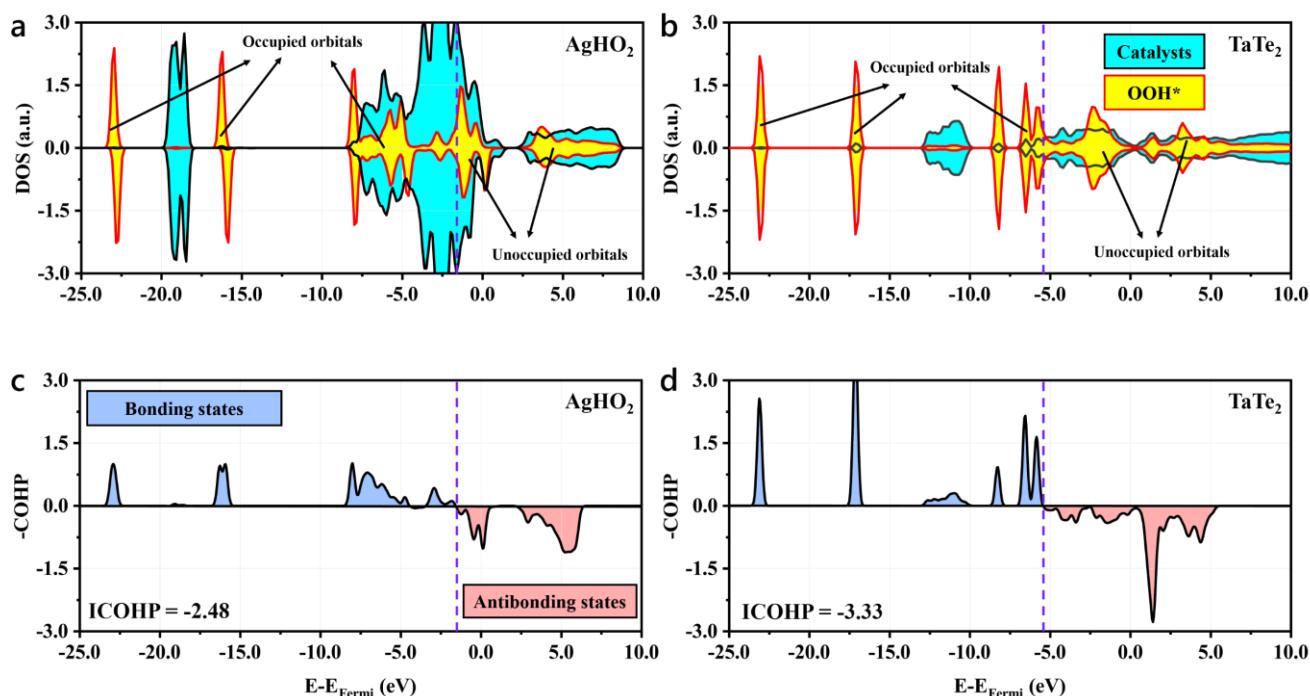


Fig. S67. Density of states (DOS) and the crystal orbital Hamilton populations (COHP) of the OOH^* adsorbed on the active sites of AgHO_2 (a and c), and TaTe_2 (b and d). The results indicate that both of the two catalysts can strongly interact with the OOH^* via band hybridization. Upon adsorption, OOH^* can form the fully occupied orbitals below the Fermi level and partial occupied molecular orbitals around the Fermi level. By comparison with the AgHO_2 , TaTe_2 can downshift the molecular orbitals of OOH^* toward a lower energy level, which results in a stronger binding. The bonding states or the occupied orbitals between the OOH^* and TaTe_2 are all distributed below the -5.97 eV, much lower than that in the AgHO_2 (-2.19 eV). Specifically, through integrating the COHP up to the Fermi level, the different band hybridization can be further unveiled. In principle, a more negative value of integrated-COHP (ICOHP) generally implies a stronger binding. The calculated ICOHP value on the TaTe_2 (-3.33 eV) is more negative than that of -2.48 eV on the AgHO_2 , which is consistent with the trend of adsorption free energy calculations (3.55 eV for the TaTe_2 vs 3.70 eV for the AgHO_2). Notably, the ideal situation for the oxygen electrocatalysis is that the Gibbs free energy changes in each elementary step are the same at zero potential so that potential barriers of each step can be zero when the electrode potential reaches the equilibrium potential. Thus, the optimal $\Delta G(\text{OOH}^*)$ value is estimated at 3.69 eV ($4.92 - 1.23 = 3.69$). Since the AgHO_2 has a nearly ideal $\Delta G(\text{OOH}^*)$ of 3.69 eV, the AgHO_2 is predicted to have a better performance for the OER than the TaTe_2 .

SUPPORTING INFORMATION

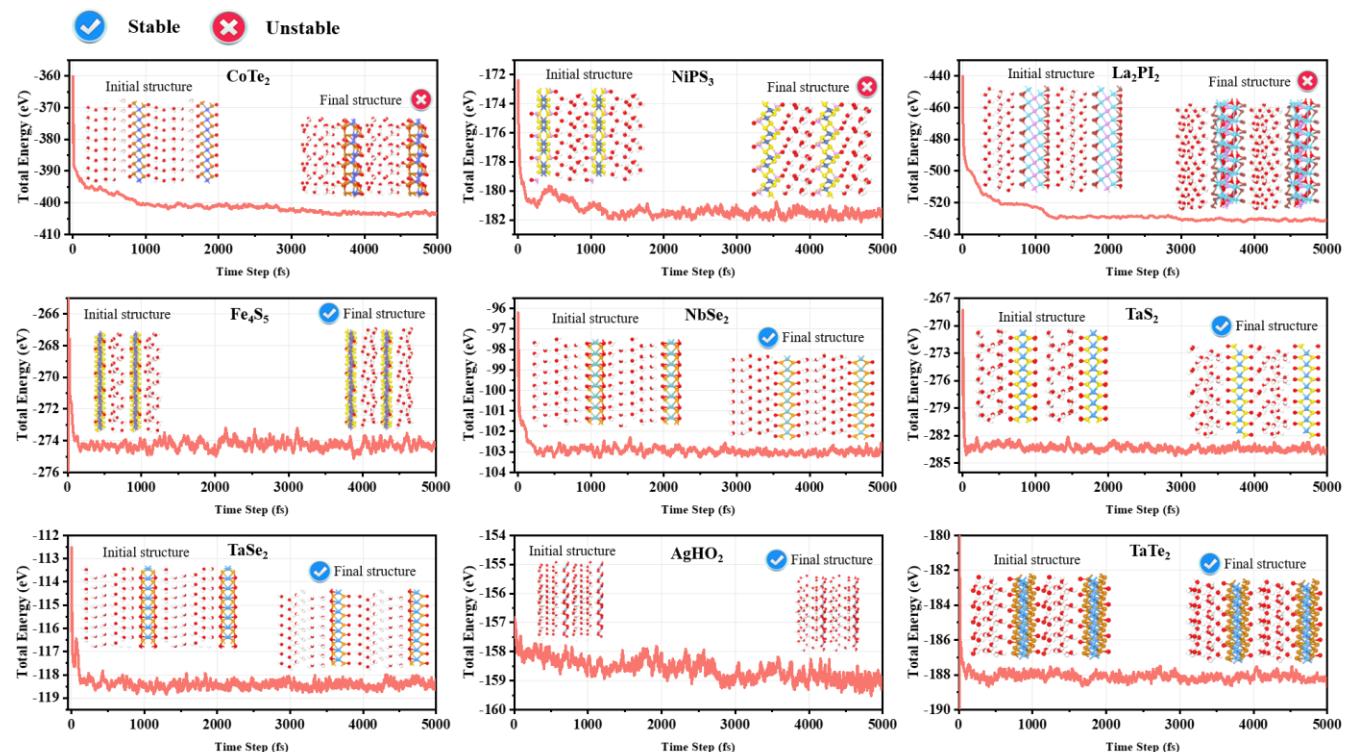


Fig. S68. Energy profiles along 5 ps AIMD simulation for the two benchmark materials of CoTe₂ and NiPS₃, and nine typical compounds which screened from dissolution potential analysis. A canonical ensemble was simulated using the algorithm of Nosé. The temperature was set at 300K.

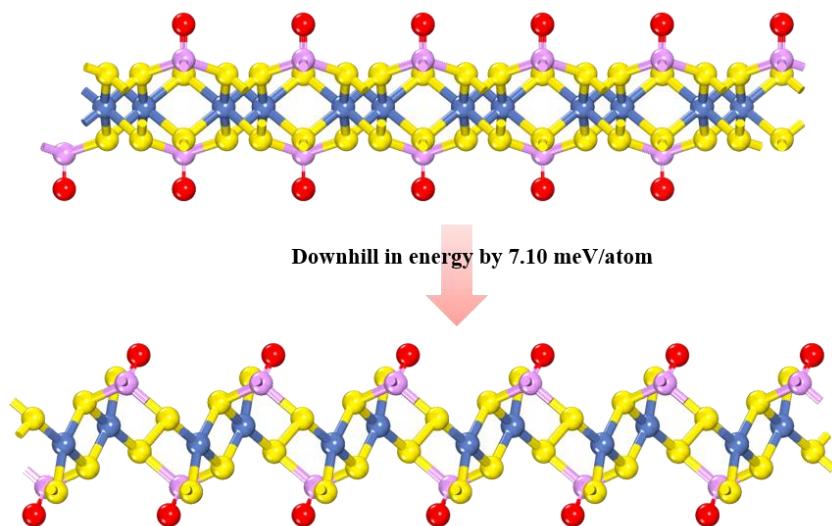


Fig. S69. Oxygen adsorption induced structure change for the NiPS₃ during the MD simulation.

SUPPORTING INFORMATION

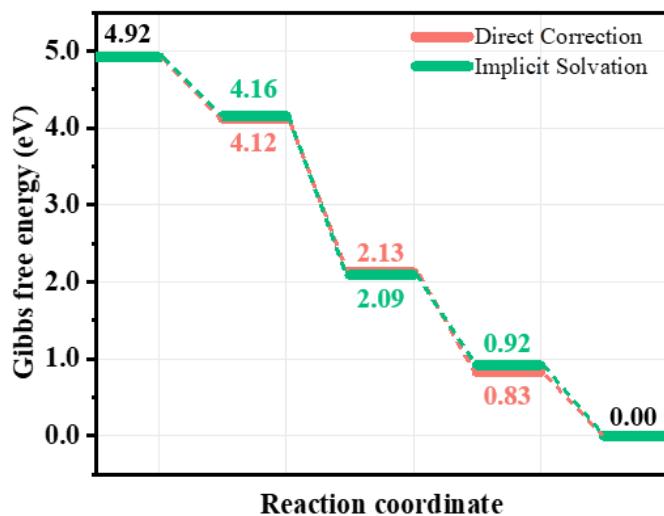


Fig. S70. Comparison of energy profiles of ORR on the NbSe₂ obtained from the direct correction and implicit solvation model.

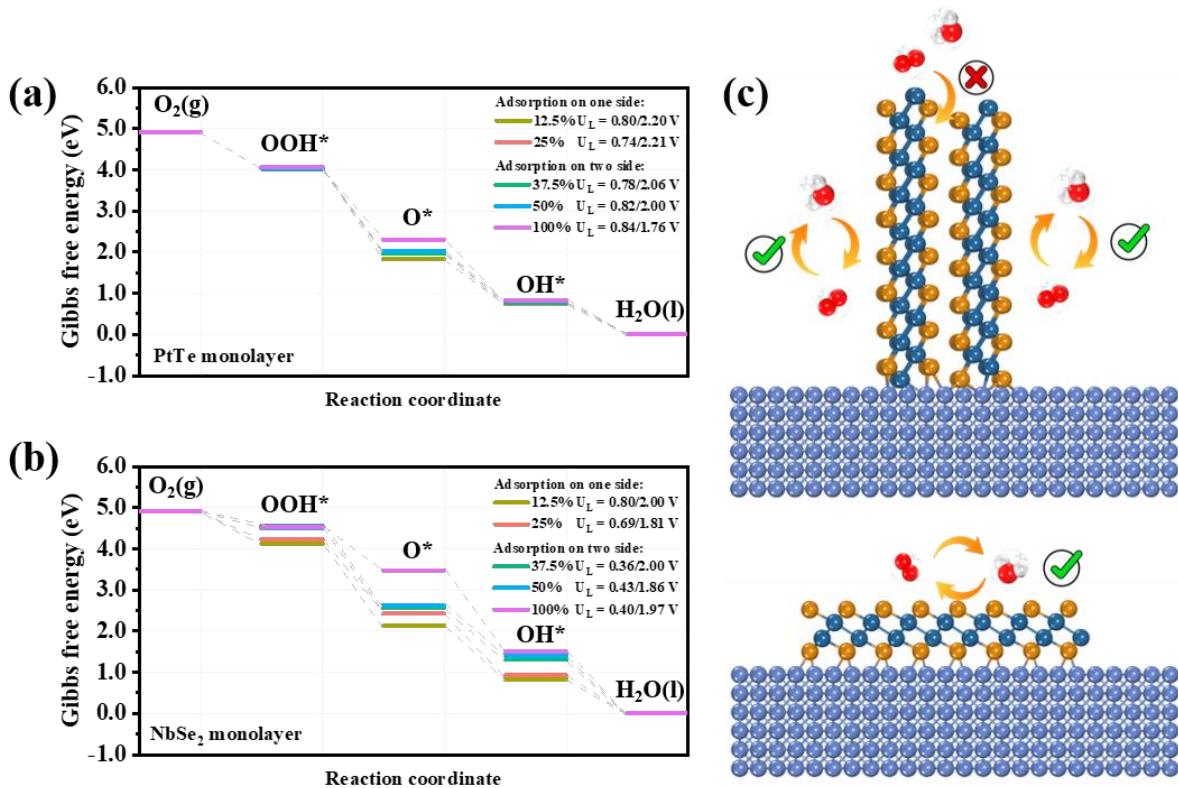


Fig. S71. Reaction pathway and theoretical limiting potential (U_L) of ORR/OER on PtTe (a) and NbSe₂ monolayers (b) at different coverage conditions. (c) Schematic illustration of the contact models of 2D materials on catalytic substrates.

SUPPORTING INFORMATION

References

1. J. P. Perdew, K. Burke and M. Ernzerhof, *Phys. Rev. Lett.*, 1996, **77**, 3865.
2. P. E. Blochl, *Phys. Rev. B*, 1994, **50**, 17953-17979.
3. V. Wang, N. Xu, J.-C. Liu, G. Tang and W.-T. Geng, *Comput. Phys. Commun.*, 2021, **267**, 108033.
4. S. Grimme, *J. Comput. Chem.*, 2006, **27**, 1787-1799.
5. G. K. H. Madsen and D. J. Singh, *Comput. Phys. Commun.*, 2006, **175**, 67-71.
6. T. Stauber, N. M. R. Peres and F. Guinea, *Physical Review B*, 2007, **76**, 205423.
7. J. K. Nørskov, J. Rossmeisl, A. Logadottir, L. Lindqvist, J. R. Kitchin, T. Bligaard and H. Jónsson, *J. Phys. Chem. B*, 2004, **108**, 17886-17892.
8. J. D. Goodpaster, A. T. Bell and M. Head-Gordon, *J. Phys. Chem. Lett.*, 2016, **7**, 1471-1477.
9. H. Xiao, T. Cheng, W. A. Goddard and R. Sundararaman, *J. Am. Chem. Soc.*, 2016, **138**, 483-486.
10. X. Guo, S. Lin, J. Gu, S. Zhang, Z. Chen and S. Huang, *ACS Catal.*, 2019, **9**, 11042-11054.
11. H. Xu, D. Cheng, D. Cao and X. C. Zeng, *Nat. Catal.*, 2018, **1**, 339-348.
12. F. Calle-Vallejo, J. I. Martinez and J. Rossmeisl, *Phys Chem Chem Phys*, 2011, **13**, 15639-15643.
13. K. Mathew, R. Sundararaman, K. Letchworth-Weaver, T. A. Arias and R. G. Hennig, *J. Chem. Phys.*, 2014, **140**, 084106.
14. R. Sundararaman, K. Letchworth-Weaver, K. A. Schwarz, D. Gunceler, Y. Ozhabes and T. A. Arias, *SoftwareX*, 2017, **6**, 278-284.
15. K. F. Garrity, J. W. Bennett, K. M. Rabe and D. Vanderbilt, *Comput. Mater. Sci.*, 2014, **81**, 446-452.
16. R. Sundararaman and W. A. Goddard, *J. Chem. Phys.*, 2015, **142**, 064107.
17. R. Sundararaman, W. A. Goddard and T. A. Arias, *J. Chem. Phys.*, 2017, **146**, 114104.
18. Z. Duan and G. Henkelman, *ACS Catalysis*, 2021, **11**, 14439-14447.
19. C. Seitz Linsey, F. Dickens Colin, K. Nishio, Y. Hikita, J. Montoya, A. Doyle, C. Kirk, A. Vojvodic, Y. Hwang Harold, K. Norskov Jens and F. Jaramillo Thomas, *Science*, 2016, **353**, 1011-1014.
20. Z. Wang, X. Guo, J. Montoya and J. K. Nørskov, *npj Comput. Mater.*, 2020, **6**, 160.
21. H. Xiao, T. Cheng and W. A. Goddard, *J. Am. Chem. Soc.*, 2017, **139**, 130-136.
22. J. C. Liu, H. Xiao and J. Li, *J. Am. Chem. Soc.*, 2020, **142**, 3375-3383.
23. G. Henkelman, B. P. Uberuaga and H. Jónsson, *J. Chem. Phys.*, 2000, **113**, 9901-9904.
24. A. M. Patel, S. Vijay, G. Kastlunger, J. K. Nørskov and K. Chan, *J. Phys. Chem. Lett.*, 2021, **12**, 5193-5200.
25. L. Bornstein, *Subvolume A, Pure Substances (Springer*, 1999), 1999.

SUPPORTING INFORMATION

26. D. C. Harris, *Quantitative chemical analysis*, Macmillan, 2010.
27. D. R. Lide, *CRC handbook of chemistry and physics*, CRC press, 2004.
27. M. O. Almeida, M. J. Kolb, M. R. V. Lanza, F. Illas and F. Calle-Vallejo, *ChemElectroChem*, 2022, **9**, e202200210.
28. J. A. Gauthier, C. F. Dickens, L. D. Chen, A. D. Doyle and J. K. Nørskov, *J. Phys. Chem. C* 2017, **121**, 11455–11463.
29. D. Y. Kuo, J. K. Kawasaki, J. N. Nelson, J. Kloppenburg, G. Hautier, K. M. Shen, D. G. Schlom and J. Suntivich, *J. Am. Chem. Soc.*, 2017, **139**, 3473-3479.